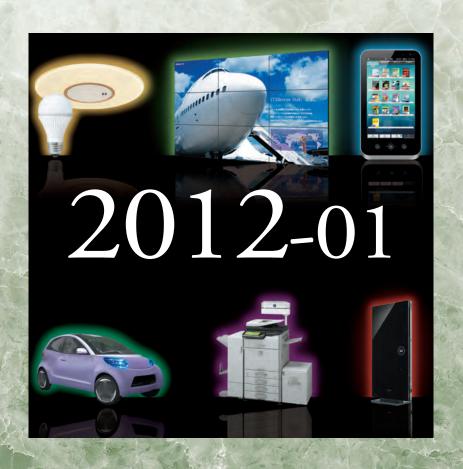


For Your Creative Products ELECTRONIC COMPONENTS



http://sharp-world.com/products/device/

CONTENTS

Sharp Efforts Towards a Green Society		LSI REG PACKA
Developing Devices with High Environmental Performance		CCD (Chin Siza Dagleage)
Raising the Level of Environmental Performance in Factories	э	CSP (Chip Size Package)
TET		SiP (System in Package)
TFT LCD	6	SOF (System On Film)
LCD Madulas		Package Lineup
LCD Modules	6	
1.01		
LSI CMOS IMAGE SENSORS/CCDs	8	
	_	*******
CMOS Camera Modules Road Map		
CMOS Camera Modules		
Road Map for High-resolution CCDs for Digital Cameras		
High-resolution CCDs		
1/3-type CCDs		
1/3.8-type CCD		
1/4-type CCDs	. 11	OPTO OPTOELED
CCD Peripheral ICs/LSIs	. 12	OI TOLLLO
		Photocoupler Lineup
LSI Analog LSIs FOR LCDs/ANALOG ICS	17	Photocouplers
LOIS FOR LCDS/ANALOGICS	17	Phototransistor Output T
For Notebook PCs, PC Monitors and LCD TVs	. 17	OPIC Output
For Mobile Devices	. 18	Phototriac Coupler Lineup
Power Supply ICs for TFT-LCDs	. 18	Phototriac Couplers
		Solid State Relay Lineup
S CYCTEM I CIC	40	Solid State Relays
LSI SYSTEM LSIS	19	Solid State Relays DIP type
System LSIs		
	. 19	DIP type
System LSIs Graphic Display Module with LCDs	. 19 19	DIP type
System LSIs Graphic Display Module with LCDs One-chip Graphic Controller	. 19 19 20	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm< td=""></transm<>
System LSIs	. 19 19 20	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm o<="" phototransistor="" single="" td=""></transm>
System LSIs	. 19 19 20 . 21	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm darlington="" o="" phototransister<="" phototransistor="" single="" td=""></transm>
System LSIs	. 19 19 20	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm darlington="" o="" opic="" phototransistor="" single="" td="" type<=""></transm>
System LSIs	. 19 19 20 . 21	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect<="" darlington="" o="" opic="" photointerrupters="" phototransisto="" phototransistor="" single="" td="" type=""></transm>
System LSIs	. 19 19 20 . 21	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect="" darlington="" o="" o<="" opic="" photointerrupters="" phototransistor="" single="" td="" type=""></transm>
System LSIs	. 19 19 20 . 21	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect="" darlington="" o="" opic="" output<="" photointerrupters="" phototransistor="" single="" td="" type=""></transm>
System LSIs	. 19 19 20 . 21 22 . 22	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect="" darlington="" o="" opic="" output<="" photointerrupters="" phototransistor="" single="" td="" type=""></transm>
System LSIs	. 19 19 20 . 21 22 . 22 . 22	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect="" darlington="" for="" o="" opic="" output="" photointerrupters="" phototransistor="" single="" spec="" td="" transmissive="" type="" type<=""></transm>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect="" darlington="" for="" o="" opic="" output="" photointerrupters="" phototransisto="" phototransistor="" reflective="" single="" spec="" td="" transmissive="" type="" type<=""></transm>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26	DIP type SIP type Photointerrupter Lineup Photointerrupters <transm <reflect="" darlington="" for="" o="" opic="" output="" photointerrupters="" phototransistor="" proximity="" reflective="" sensor<="" single="" spec="" td="" transmissive="" type=""></transm>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" darlington="" for="" interesting="" of="" opic="" output="" photointerrupters="" phototransistor="" proximity="" proximity<="" reflective="" sensor="" single="" spector="" td="" transmissive="" type="" with=""></transmand>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" darlington="" for="" international="" of="" opic="" output="" photointerrupters="" phototransistor="" proximity="" reflective="" s<="" sensor="" since="" single="" spector="" td="" transmissive="" type="" with=""></transmand>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28 . 30	DIP type SIP type Photointerrupter Lineup Photointerrupters < Transmand Single Phototransistor Of Darlington Phototransistor Of Darlington Phototransistor Of OPIC Type Photointerrupters < Reflect Single Phototransistor Of OPIC Output Photointerrupters for Spector Transmissive Type Reflective Type Proximity Sensor with Interest Ambient Light Sensors OPIC Light Detectors
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28 . 30 . 30	DIP type
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 26 . 27 . 28 . 30 . 30 . 30	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" ambient="" darlington="" detectors="" for="" interest="" light="" lineup="" of="" opic="" output="" photointerrupters="" phototransistor="" phototransistors<="" proximity="" reflective="" sensor="" sensors="" single="" spector="" td="" transmissive="" type="" with=""></transmand>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28 . 30 . 30 . 30	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" darlington="" for="" integrating="" of="" opic="" output="" photointerrupters="" phototransistor="" proximity="" reflective="" sen<="" sensor="" single="" spector="" td="" transmissive="" type="" with=""></transmand>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28 . 30 . 30 . 30 . 30 . 31	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" ambient="" darlington="" detectors="" for="" interest="" light="" lineup="" of="" opic="" output="" photodiodes<="" photointerrupters="" phototransistor="" phototransistors="" pin="" proximity="" reflective="" sensor="" sensors="" single="" spector="" td="" transmissive="" type="" with=""></transmand>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28 . 30 . 30 . 30 . 30 . 31	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" ambient="" darlington="" detectors="" diode="" emitting="" for="" infrared="" interest="" light="" lineup="" lir<="" of="" opic="" output="" photodiodes="" photointerrupters="" phototransistor="" phototransistors="" pin="" proximity="" reflective="" sensor="" sensors="" single="" spector="" td="" transmissive="" type="" with=""></transmand>
System LSIs	. 19 19 20 . 21 22 . 22 . 22 . 25 . 26 . 26 . 27 . 28 . 30 . 30 . 30 . 30 . 31	DIP type SIP type Photointerrupter Lineup Photointerrupters <transmand <reflect="" ambient="" darlington="" detectors="" for="" interest="" light="" lineup="" of="" opic="" output="" photodiodes<="" photointerrupters="" phototransistor="" phototransistors="" pin="" proximity="" reflective="" sensor="" sensors="" single="" spector="" td="" transmissive="" type="" with=""></transmand>

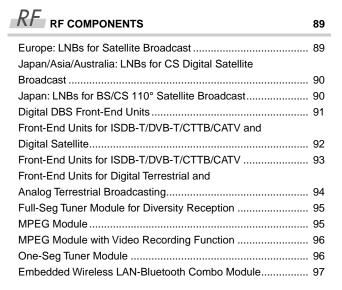
LSI REG PACKAGES	32
CSP (Chip Size Package)	32
SiP (System in Package)	33
SOF (System On Film)	35
Package Lineup	36

OPTOELECTRONICS	43
Photocoupler Lineup	43
Phototransistor Output Type	44
OPIC Output	48
Phototriac Coupler Lineup	50
Phototriac Couplers	51
Solid State Relay Lineup	53
Solid State Relays	
DIP type	54
SIP type	55
Photointerrupter Lineup	57
Photointerrupters < Transmissive type>	58
Single Phototransistor Output	58
Darlington Phototransistor Output	60
OPIC Type	60
Photointerrupters <reflective type=""></reflective>	62
Single Phototransistor Output	62
OPIC Output	63
Photointerrupters for Specific Applications	64
Transmissive Type	64
Reflective Type	64
Proximity Sensor	65
Proximity Sensor with Integrated Ambient Light Sensor	66
Ambient Light Sensors	67
OPIC Light Detectors	68
Phototransistor Lineup	70
Phototransistors	71
PIN Photodiodes	72
Infrared Emitting Diode Lineup	73
Infrared Emitting Diodes	73
Optical-Electric Sensor Lineup	
Distance Measuring Sensors	75
Wide Angle Sensors	77
Paper Size Sensors	77
High-Precision Displacement Sensor	77

INDEX 107 NOTICE...... 113

Color Toner Concentration (Deposition Amount) Sensors		IR DEVICES	98
Fiber Optics Lineup for Audio Equipment		Infrared Data Communication Device Lineup	98
Fiber Optic Transmitters		Infrared Data Communication Devices	
Fiber Optic Receivers	80	IR Detecting Unit for Remote Control Lineup	
		(Classified by Form)	. 101
LED LEDS	81	IR Detecting Units for Remote Control	. 102
High-Luminosity Surface Mount LEDs		3 ///	
Surface Mount LEDs	-		
High-Luminosity White Surface Mount LEDs			
High-Luminosity Surface Mount LEDs (RGB 3-color)			
ZENIGATA LEDs for Lighting		202	
Surface Mount LEDs for Lighting		PCB PRINTED CIRCUIT BOARDS	103
Surface Mount LEDs for Lighting (RGB 3-color)			
LEDs for LCD Backlight	86	Advanced Flex Printed Circuit Boards	
		Flexible Printed Circuit Boards	. 105
LASER DIODES	87	UNIT PICKUPS	106
Laser Diodes	87	DVD Pickup for Automotive Use	. 106

ID





Sharp Efforts Towards a Green Society

Based on its fiscal 2010 corporate vision of becoming an "Eco-Positive Company," the entire Sharp Group is working as one towards realizing a green society.

Basic Environmental Philosophy

Creating an Environmentally Conscious Company with Sincerity and Creativity

The Sharp Group Charter of Corporate Behavior

Contribution to Conservation of the Global Environment

The Sharp Group will make efforts to further contribute to global environmental conservation by strengthening our development of proprietary technologies for protecting the global environment, and by carrying out business activities in an environmentally conscious manner.

The Sharp Code of Conduct

Contribution to Conservation of the Global Environment

1. To Conserve the Environment:

- ① We will comply with all applicable environmental laws, regulations, and regional agreements, and make voluntary efforts to practice effective use and saving of resources and energy, in the recognition that global environmental conservation is an essential facet of corporate and individual pursuits.
- ② We will work aggressively to reduce greenhouse gas emissions in all business activities, in order to contribute to the prevention of global warming.
- ③ To deal with environmental issues on a global scale, we will promote the sharing and practical application of energy-saving actions and environmental conservation technologies among the Sharp Group companies in each country and work to contribute to reducing environmental load.
- We recognize that maintaining an eco-system where diverse living organisms coexist brings about a rich environment in which both corporations and individuals can operate and live. To that end, we will work aggressively to conserve biodiversity and for its sustainable use.
- ⑤ In order to promote communication with local residents and other stakeholders, we will engage in acquiring environmental information at an international level, and providing internal reports thereof.

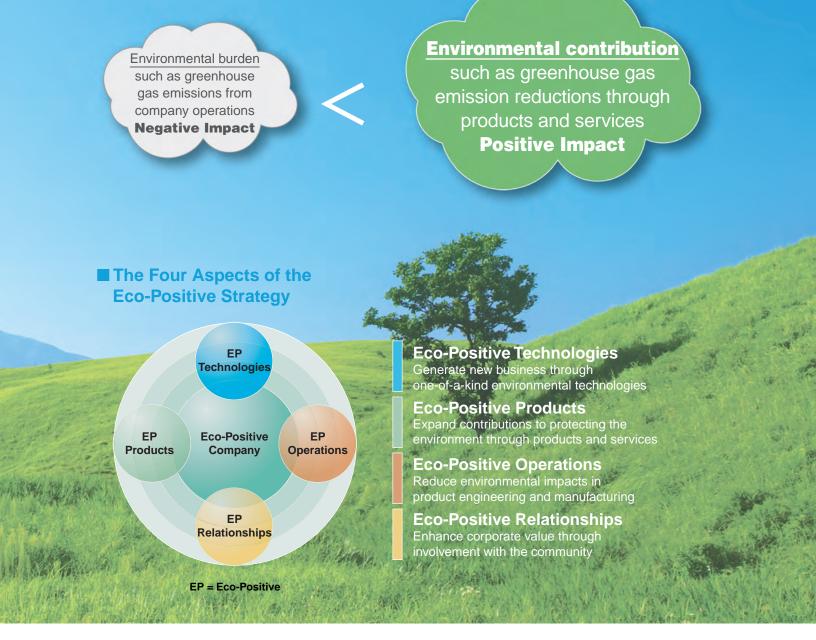
- 2. To Develop Environmentally Conscious Products and Services, and Conduct Our Business Operations in an Environmentally Conscious Manner:
- We understand the importance of internal company systems and related details in maintaining third-party certification of our ISO environmental management systems, and we will observe relevant internal company rules.
- ② We will positively engage in the minimization of resource use, reduction in the size and weight of products, use of recycled materials, and the development of products and services that contribute to energy-saving, energy-creating and long life of products.
- ③ We will work to compile information related to harmful substances that might damage the environment or human health, and will not, as a matter of principle, make use of these harmful substances in our products, services and business activities.
- We will ensure proper use and control of chemical substances in our business activities, including research, development, and manufacturing, at levels meeting or exceeding those stipulated by laws and regulations.
- ⑤ We will, as a matter of policy, design recycling-conscious products with structures that are detachable and decomposable and will use recyclable materials wherever possible.
- ⑥ As to the resources needed for business activities (equipments, raw materials, subsidiary materials, tools, etc.), to the extent possible, we will work to conduct our business in such a way as to select and purchase such resources that have the least adverse effect on the global environment, the local residents and employees.
- (7) We realize that waste material is a valuable resource, and we will actively take part in maximizing the 3Rs (reduce, reuse, recycle) and minimizing the amount of final waste disposal.

^{*} For more information: http://sharp-world.com/corporate/eco/csr_report/index.html

Corporate Vision: Eco-Positive Company

Sharp aims to be an "Eco-Positive Company," a company that works with all stakeholders in creating solutions that have significantly more positive impact on the environment than negative impact caused by company operations.

To this end, Sharp will use the four aspects of its Eco-Positive Strategy to carry out advanced environmental efforts including spreading the use of solar power, improving the environmental performance of its products and devices, making plants more environmentally conscious, and developing one-of-a-kind environmental technologies.



Developing Devices with High Environmental Performance

Developing Green Devices and Super Green Devices

Sharp calls its environmentally conscious devices Green Devices (GD). To define guidelines for development and design based on seven concepts, Sharp established the GD Guidelines, which it began applying at all device design departments in fiscal 2004. The device development process starts with the planning stage, in which Sharp uses the GD Standard Sheet, which was formulated based on the GD Guidelines, to set specific objectives. In the trial manufacture and mass production stages, Sharp determines how well the actual device has met these objectives, with those achieving the standards being certified as GD. In fiscal 2005, Sharp began certifying devices from among GD with the highest possible levels of environmental performance as Super Green Devices (SGD). GD and SGD have been accounting for an increasing share of Sharp's net sales with each year.

Green Device Concepts

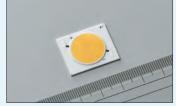
Energy Efficiency	Devices with superior energy efficiency and that consume less energy Reduce power consumption during operation and in standby mode.				
Resource Conservation	Devices designed to conserve resources Reduce device weight or volume.				
Recyclability	Devices designed for recycling Use standard plastic and/or design devices that are easy to disassemble.				
Safe Use and Disposal Devices that can be used and disposed of safely Control usage of chemical substances contained in parts and materials.					
Long Life	Devices that make products last longer Extend the life of the product with exchangeable parts and consumables (target: LCD devices).				
Packaging	Devices that use packaging with enhanced environmental consciousness Reduce packaging.				
Information Disclosure	Devices that give environmental information Provide information on chemical substances in devices.				

Super Green Devices Example

High-Output, High-Color-Rendering*1 LED Lighting Devices

Industry-leading 91 Im/W luminous efficacy*2 in the 25W-class achieved

GW5DMC30M04 is a high-output, high-color-rendering 25W-class LED lighting device that boasts an industry's highest luminous efficacy of 91 lm/W for light sources such as store spotlights. These 25W-class devices have achieved incredibly low energy consumption through the adoption of LED chips and phosphor, which both have excellent high-temperature properties. They provide a high 2 370-lm luminous flux and the industry's highest luminous efficacy of 91 lm/W. In addition, it achieved a high color rendering index (Ra)*3 of 83 by faithfully reproducing the colors of objects. Furthermore, the LED emitting area has been made circular to make designing lighting instruments easy.



GW5DMC30M04

■ Main Features

- Industry-leading luminous efficacy of 91 Im/W achieved within the 25W-class
- Faithfully reproduces natural colors, with its high color rendering index (Ra) of 83
- *1 Color rendering describes how colors are perceived depending on differences in the illuminating light source. The closer to natural light, the higher the color rendering capability.
- *2 The brightness per watt. As of February 9, 2011, for LED lighting devices with an input power of 25 W, a color temperature of 3,000 K, and a color rendering index (Ra) 83 (based on Sharp survey).
- *3 A numerical value expressing the level of color distortion compared to a reference light source. The closer the value to 100, the lower the color distortion.

Raising the Level of Environmental Performance in Factories

Making More Factories Super Green Factories

Sharp defines factories with a high level of environmental consciousness as Green Factories (GF). The basic policies and operational know-how for achieving GF status have been formulated in line with 10 concepts in the GF Guidelines, which Sharp has been applying at all production bases in Japan since fiscal 1999 and overseas since fiscal 2001.

With construction of the Kameyama Plant, in fiscal 2003 Sharp established assessment criteria for Super Green Factories (SGF)—factories with exceptionally high levels of environmental performance—and launched efforts to award in-house certification. The Kameyama Plant was the first plant to achieve this certification. Sharp started GF certification in fiscal 2004 and overseas as well, and Sharp has achieved its mid-term objective of having all Sharp plants in Japan and overseas certified for GF status and all 10 Sharp Corporation plants in Japan certified for SGF status by fiscal 2007.

In fiscal 2008, Sharp stepped up its SGF efforts with the start of the SGF II initiative at plants certified for SGF status.

Green Factory Concepts

Greenhouse gases	Minimize emission of greenhouse gases
Energy	Minimize energy consumption
Waste	Minimize discharge of waste
Resources	Minimize resource consumption
Chemical substances	Minimize risk of environmental pollution and accidents caused by chemical substances
Atmosphere, water, soil	Minimize environmental burden on the atmosphere, water, and soil
Harmony with nature	Endeavor to preserve nature both on and off site
Harmony with the community	Encourage harmony with the local community
Environmental consciousness	Foster high environmental awareness among employees
Information disclosure	Disclose information on the environment

Development of GREEN FRONT SAKAI

In order to become a company that contributes to the environment, Sharp has been developing its business on the two pillars of energy-saving LCDs and energy-creating solar cells. In order to further these efforts, Sharp commenced operations at a new LCD panel plant in October 2009, followed by a new solar cell plant in March 2010, in Sakai, Osaka prefecture. We hope to propel our business forward by having companies in other fields with advanced technology join us, to help us achieve the goal of creating a "green society" suitable to today's environmentally conscious mindset.





Overview of GREEN FRONT SAKAI

Location: 1-banchi, Takumi-cho, Sakai-ku,

Sakai-shi, Osaka Site area: 1.27 million m²

(approx. 28 times the size of Tokyo Dome)

LCD Panel Plant

Start of operations: October 2009 Mother glass size: 2,880 mm x 3,130 mm

(10th generation)

Mother glass input capacity: 72,000 substrates per month

Solar Cell Plants

■ Thin-film solar cell plant

Start of operations: March 2010
Production capacity: 160 MW per year
(first production development)

Glass substrate size: 1,000 mm x 1,400 mm
■ Single-crystal solar cell plant

Start of operations: March 2011
Production capacity: 200 MW per year (first production development)

* The above information is current as of June 2011.



LCD MODULES

☆New product **★**Under development



■ LCD Modules

<For industrial appliances>

<foi appliances="" illustrial=""></foi>																				
Display size (cm) ["]	Model No.	Dot format H × V (dot)	Pixel pitch H×V (mm)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Power con- sumption (W) (TYP.)	Outline dimensions*1 W × H × D (mm) (TYP.)	Weight (g) (MAX.)	Remarks									
8.8 [3.5]	LQ035Q3DG03	320 × RGB × 240	0.2205 × 0.2205	70.56 × 52.92	16.77 M	450	CMOS 8-bit RGB	0.8	76.9 × 63.9 × 4.7	TYP. 42	Long-life LED backlight									
	☆LQ043T3DW03				16.77 M	400	CMOS 8-bit RGB	1.2	105.5 × 67.2 × 7.7	85	Advanced Super V, Long-life LED backlight									
12 [4.3]	LQ043T3DG01	480 × RGB × 272	0.198 × 0.198	95.04 × 53.86	260 k	400	CMOS	0.0	105.5 × 67.2 × 5.05	TYP. 65										
	LQ043T3DG02				200 K	480	6-bit RGB	0.6	105.5 × 67.2 × 3.95	TYP. 55										
14	LQ057V3LG11	640 × RGB × 480	0.18 × 0.18	115.2 ×		350	1ch LVDS 6-bit RGB	2.3	144.0 × 104.6 × 12.3	190	Built-in LED backlight driver circuit									
[5.7]	★LQ057Q3DC03	320 × RGB × 240	0.36 × 0.36	86.4	260 k	500	CMOS 6-bit RGB	2.5	144.0 × 104.6 × 12.3	210	Long-life LED backlight, Built-in LED backlight driver circuit									
	LQ070Y3LW01					360	1ch LVDS 8-bit RGB	2.6	170.0 × 110.0 × 9.0	TYP. 175	Advanced Super V, Long-life LED backlight									
	LQ070Y3DG3A					350	CMOC	2.0	163.2 × 104.0 × 3.9	150										
18 [7.0]	LQ070Y3DG3B		0.1905 × 0.1905	152.4 × 91.4	16.19 M	280	CMOS 6-bit + 2-bit FRC	2.0	163.2 × 104.0 × 7.1 (including touch panel)	185	With resistive touch panel									
	LQ070Y3LG4A					350	LVDS 6-bit + 2-bit FRC	2.1	163.2 × 104.0 × 3.9	150										
21	☆LQ084S3LG03	800 × RGB × 600	0.213 × 0.213	170.4 × 127.8	16.77 M	330	1ch LVDS 8-bit RGB	4.1	199.5 × 154.0 × 11.6	320	Long-life LED backlight, Built-in LED backlight driver circuit									
[8.4]	LQ084V3DG02	640 × RGB × 480	0.267 × 0.267	170.88 × 128.16	260 k	400	CMOS 6-bit RGB	4.6	199.5 × 149.5 × 11.6	400	Long-life LED backlight									
26 [10.4]	☆LQ104V1DG81/LG81	640 × RGB × 480	0.33 × 0.33	211.2 × 158.4	260 k	450	CMOS 6-bit RGB/ 1ch LVDS 6-bit RGB	5.6	246.5 × 179.4 × 12.5	TYP. 500	Strong LCD2, Long-life LED backlight, Built-in LED backlight driver circuit									
31	LQ121S1LG81	800 × RGP	800 × PGP	800 × RGP	800 × RGB	800 × RGB	800 × RGB	800 × RGB	800 × RGB	800 × RGB	800 × RGB	0.3075×	246.0×	260 k	450	LVDS		276.0 × 209.0	600	Long-life LED backlight, HV mode*2, Built-in LED backlight driver circuit
[12.1]	☆LQ121S1LG84	× 600	0.3075	184.5	200 K	450	6-bit RGB	5.1	× 9.1	800	Long-life LED backlight, DE mode*3, Built-in LED backlight driver circuit									
38 [15.0]	LQ150X1LG91	1 024 × RGB × 768	0.297 × 0.297	304.1 × 228.1	16.19 M	350	LVDS 8-bit + 2-bit FRC	6.8	326.5 × 253.5 × 9.6	950	Long-life LED backlight, Built-in LED backlight driver circuit									
48	LQ190E1LX51	1 280 × RGB × 1 024	0.294 × 0.294	376.32 × 301.056	16.77 M	1 000	2ch LVDS 8-bit RGB	75	404.2 × 330.0 × 34.0	2 600	Advanced Super V, Built-in LED backlight driver circuit									
[19.0]	★ LQ190E1LW52	^ I U24	0.234	301.030		300	ט-טונ וועם	15.3	404.2 × 330.0 × 15.0	1 850	Advanced Super V, Long-life LED backlight									
59 [23.1]	LQ231U1LW32	1 600 × RGB × 1 200	0.294 × 0.294	470.4 × 352.8	16.77 M	500	LDI 8-bit RGB	65.5	530.0 × 431.5 × 23.9	4 500	Advanced Super V, Built-in LED backlight driver circuit									

All products listed on this page are LED backlight models.

All products listed on this page are LED backlight models.

1 Protrusions such as positioning bosses are not included.

2 Hsync/Vsync mode

3 Data enable mode
(Note) Please note that the specifications are subject to change without prior notice for product improvement.

Notice
In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. For details, please inquire with SHARP. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

★Under development



<For large-size product applications>

Display size (cm) ["]	Model No.	Number of pixels*1	Dot format H×V (dot)	Active area H × V (mm)	Display colors	Lumi- nance (cd/m²) (TYP.)	Interface	Outline dimensions*2 W×H×D (mm) (TYP.)	Backlight	Remarks
80.0 [31.5]	★ LQ315D1LG91	8 294 400	3 840 × RGB × 2 160	697.92 × 392.58	(1.06B) (10-bit)	(450)	(8ch-LVDS)*3 (10-bit digital)	(733 × 428 × 33)*4	Direct-lit LED (built-in driver)	Super-high resolution and low power consumption (MAX. 150 W) achieved by using IGZO*5 LCD Wide viewing angle: L/R 176°/ U/D 176°, Response time [G to G]: 8 ms (Ave.)
152.5	LK601R3LA19	8 294 400	3 840 × RGB × 2 160	1 330.56 × 748.44	1.06B (8-bit + 2-bit FRC)	450	8ch-LVDS* ³ (10-bit digital)	1 380.0 × 790.0 × 106.6	Direct-lit LED	Ultraviolet-induced Multi-domain Vertical Alignment LCD, High color purity (78% of NTSC), Wide viewing angle: L/R 176°/ U/D 176°, High contrast: 4 000:1, High-speed response [G to G]: 6 ms (Ave.)
[60]	★LK600D3LB14	2 073 600	1 920 × RGB × 1 080	1 329.12 × 747.63		2 000	2ch-LVDS* ³ (10-bit digital)	790.0 × 106.6	(built-in driver)	Ultraviolet-induced Multi-domain Vertical Alignment LCD, Wide viewing angle: L/R 176°/ U/D 176°, High contrast: 5 000:1 or higher, High-speed response [G to G]: 6 ms (Ave.)
207.2 [81.6]	LK816D3LA19	2 073 600	1 080 × 1 920 × RGB	1 015.74 × 1 805.76	1.06B (8-bit + 2-bit FRC)	1 200	2ch-LVDS*3 (10-bit digital)	1 094.0 × 1 879.0 × 81.9	Built-in CCFL	Portrait setting, Advanced Super V, Wide viewing angle: L/R 176°/ U/D 176°, High contrast: 2 000:1, High-speed response [G to G]: 6 ms (Ave.)

*1 Pixel means a set of each RGB dot.

*2 Excluding FPC for connection and other protruding parts.

*3 LVDS: Low Voltage Differential Signaling

*4 Excluding the LED driver.

*5 IGZO: an oxide semiconductor consisting of In (Indium), Ga (Gallium), and Zn (Zinc).

(Note) Please note that the specifications are subject to change without prior notice for product improvement.



CMOS CAMERA MODULES ROAD MAP

☆New product



■ CMOS Camera Modules Road Map

Image format	2009	2010	2011	2012
12M (HXGA)				★ RJ63YC100 ★ RJ63YC200 ★ RJ63YC200
8M (QUXGA)			RJ63VC200 1/3.2 type 0.42 cc Built-in auto focus function 8.52 x 8.52 x 5.8	
5M (QSXGA)	RJ64SC100 1/4 type 0.36 cc Built-in auto focus function 8.5 x 8.5 x 5.0	RJ64SC200 1/4 type 0.36 cc Built-in auto focus function 8.5 x 8.5 x 5.0		
3M (QXGA)		RJ64PC800 1/4 type 0.37 cc Built-in auto focus function 8.5 x 8.5 x 5.1		
VGA			RJ6CBA100 1/13 type 0.03 cc 3.71 x 3.35 x 2.3 RJ6CBA200 1/13 type 0.02 cc 3.50 x 3.05 x 2.3	

Model No.

Optical format & volume

Outline dimensions (D x W x H) TYP. (mm)

Module configuration: CMOS image sensor, CDS/AGC/10-bit ADC, timing generator, DSP, lens

: R, G, B primary color mosaic filters Color filter

Operating temperature: -20 to 60°C

					Output		Lens				Power	
Optical format	Image format Optical function		Model No.	al Na Gastiirea		F No.	Config- uration	Horizontal viewing angle (°)	Output signal	Supply voltage*2 (V) TYP.	consump- tion*3 (mW) TYP.	Package*1
	HXGA	OIS*4 function, auto focus function	☆RJ63YC100	HXGA to QVGA 19 fps at HXGA/60 fps at 1 080p 12.5x electronic zoom at QVGA size (MAX.)	4 016 x	F2.5	5 pcs.	. 61	RAW (Mipi)	2.8/1.8/ 1.2 (I/O: 1.8	270 (at 18.6 fps)	
1/3.2 type			☆RJ63YC200	Image inversion function (top and bottom / right and left)	3 016					or 2.8)	(at 10.0 ips)	
	QUXGA		RJ63VC200	QUXGA to SubQCIF 15 fps at QUXGA/60 fps at 720p 10.5x electronic zoom at QVGA size (MAX.) Image inversion function (right and left)	3 280 x 2 464	F2.4	5 pcs.	59	RAW (Mipi)		136 (at 7.5 fps)	FPC type
	QSXGA	Auto focus function	RJ64SC100	QSXGA to SubQCIF 5 fps at QSXGA/30 fps at VGA 8x electronic zoom at QVGA size (MAX.) Image inversion function (right and left)	2 592		4 200	54	UYVY (Parallel)		270 (at 4.5 fps)	
1/4 type			RJ64SC200	QSXGA to SubQCIF 15 fps at QSXGA/30 fps at 720p 8x electronic zoom at QVGA size (MAX.) Image inversion function (right and left)	1 944	F0.0	4 pcs.		UYVY (Mipi)	2.8/1.8 (I/O: 1.8 or 2.8)	283 (at 4.5 fps)	
	QXGA		RJ64PC800	QXGA to SubQCIF 7.5 fps at QXGA/30 fps at XGA 6.4x electronic zoom at QVGA size (MAX.) Image inversion function (right and left)	2 048 x 1 536	F2.8	3 pcs.	54	UYVY (Parallel)		190 (at 7.5 fps)	
1/13	VGA		RJ6CBA200 • VGA to SubQCIF • 30 fps at VGA		640		4		UYVY (Parallel)		77 (at 30 fps)	25WL-CSP
type	VGA	GA —	RJ6CBA100	2x electronic zoom at QVGA size (MAX.) Image inversion function (right and left)	480	x 80	1 pcs.	5. 53	UYVY (Mipi)		76 (at 30 fps)	21WL-CSP

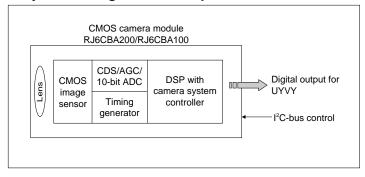
Contact a SHARP sales office regarding FPC type package.

Outline Dimensions

Model No.	Outline dimensions (D x W x H) TYP. (mm)	Package*1		
☆RJ63YC100	11.0 x 11.0 x 5.47			
☆RJ63YC200	8.5 x 8.5 x 5.47			
RJ63VC200	8.52 x 8.52 x 5.8	EDO 1:		
RJ64SC100	8.5 x 8.5 x 5.0	FPC type		
RJ64SC200	0.5 X 0.5 X 5.0			
RJ64PC800	8.5 x 8.5 x 5.1			
RJ6CBA200	3.50 x 3.05 x 2.3	25WL-CSP		
RJ6CBA100	3.71 x 3.35 x 2.3	21WL-CSP		

^{*1} Contact a SHARP sales office regarding FPC type package.

System Configuration Example



^{*2} Additional supply voltage of 3.0 V is necessary for RJ64SC100/200 with a built-in AF driver.

^{*3} Actuator power consumption is *4 OIS: Optical image stabilization Actuator power consumption is not included.

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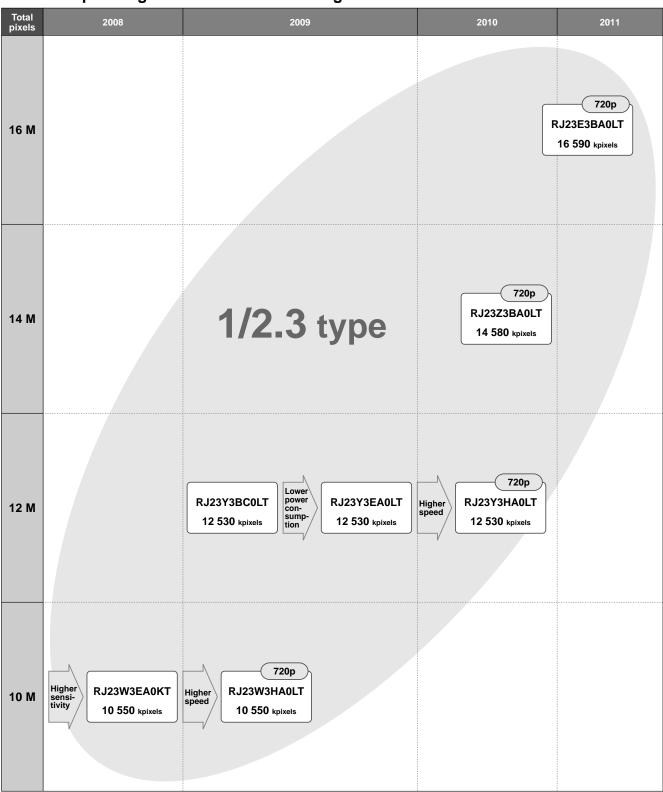
Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.



ROAD MAP FOR HIGH-RESOLUTION CCDs FOR DIGITAL CAMERAS



■ Road Map for High-resolution CCDs for Digital Cameras



HIGH-RESOLUTION CCDs/ 1/3-TYPE CCDs / 1/3.8-TYPE CCD / 1/4-TYPE CCDs

☆New product



■ High-resolution CCDs

Optical	Total	(OIOT TIITOT	Model No.	Movie function	Resolution	Pixel size	Sensitivity	Smear ratio	Package
format	pixels				Image pixels (H x V)	H x V (µm²)	(mV) TYP.	(dB) TYP.	
	10 550 k	O k	RJ23W3EA0KT	VGA 30 fps	3 704 x 2 784	04 x 2 784	68 105	-87	N-LCC040-S433A
			RJ23W3HA0LT	720p 30 fps	3704 X 2 764	1.00 X 1.00	105	-07	
	12 530 k	R,G,B	RJ23Y3BC0LT	VGA 30 fps				-86	
1/2.3 type		30 k primary color	RJ23Y3EA0LT	VGA 30 lps	4 040 x 3 032	1.55 x 1.55	105		N-LCC040-R350
91-5		mosaic filters	RJ23Y3HA0LT	720p 30 fps				-84	N-LCC040-R350
	14 580 k		RJ23Z3BA0LT	720p 30 fps	4 360 x 3 272	1.43 x 1.43	105	-86	
	16 590 k		RJ23E3BA0LT	720p 30 fps	4 648 x 3 488	1.34 x 1.34	105	-86	

■ 1/3-type CCDs

Total pixels	Stan	dord	Model No.	Reso	lution	Pixel size	Sensitivity	Smear ratio	Package
Iulai pixeis	Stari	uaiu	Model No.	Horizontal TV lines	Image pixels (H x V)	H x V (µm²)	(mV) TYP.	(dB) TYP.	rackage
270 k		NTSC	RJ2311DB0PB*1		512 x 492	9.6 x 7.5	3 200	_135	
270 K		RJ2315DB0PB*1		512 X 492	9.0 x 7.5	2 900	-135		
220 %		PAL	RJ2321DB0PB*1	330	F40 v F00	9.6 x 6.34	3 200	405	
320 k		PAL	RJ2325DB0PB*1		512 x 582		2 900	-135	- P-DIP016-0450
410 k	410 k	NTSC	RJ2351CA0PB*1	480	768 x 494	6.4 x 7.5	2 000	-120	
410 K	Color		RJ2355CA0PB*1			0.4 X 7.5	1 800	-130	
470 k	Color	PAL	RJ2361CA0PB*1		752 x 582	6.53 x 6.39	2 000	-120	
470 K		PAL	RJ2365CA0PB*1			6.53 X 6.39	1 800	-130	
500 ls		NTCC	☆RJ2331AA0PB*1		070 404	5.0 x 7.4	2 000	-120	
520 K	520 k	NTSC	☆RJ3331AA0PB*2		976 x 494		1 500	-120	
610 k		DAI	☆RJ2341AA0PB*1	650	976 x 582	5.0 x 6.3	2 000	-120	
		PAL -	☆RJ3341AA0PB*2				1 500	-120	

■ 1/3.8-type CCD

Total pixels	Standard		Model No.	Reso	Pixel size		Smear ratio	Package	
			Model No.	Horizontal TV lines	Image pixels (H x V)	H x V (µm²)	TYP. (mV)	TYP. (dB)	rackaye
290 k	Color	NTSC	RJ2411CA0PB*	330	532 x 512	7.2 x 5.6	1 200	-120	P-DIP014-0400A

^{*} Suitable for intense light exposure.

■ 1/4-type CCDs

Total pivola	Cton	dard	Model No.	Reso	lution	Pixel size	Sensitivity	Smear ratio	Dookogo
Total pixels	Stari	uaru	Wodel No.	Horizontal TV lines	Image pixels (H x V)	H x V (µm²)	TYP. (mV)	TYP. (dB)	Package
270 k			RJ2411EA0PB*			7.2 x 5.6	1 200		
		NTSC	RJ2411EB0PB	330	512 x 492			-130	
			RJ2411FA0PB*				1 800		P-DIP014-0400A
320 k		PAL	RJ2421EB0PB		512 x 582	7.2 x 4.73	1 100	-130	
320 K	Color	FAL	RJ2421FA0PB*		312 X 302	1.2 x 4.13	1 650	-130	
410 k		NTSC	RJ2451CA0PB*		768 x 494	4.9 x 5.6	900	-114	
410 K		NISC	RJ2455CA0PB*	480	700 X 494	4.9 x 5.0	900	-114	
470 k		PAL -	RJ2461CA0PB*	400	750 v 500	E 0 v 4 77	900	111	
			RJ2465CA0PB*		752 x 582	5.0 x 4.77		-114	

^{*} Suitable for intense light exposure.

^{*1} Suitable for intense light exposure.
*2 Progressive scan CCD, suitable for intense light exposure.

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CCD PERIPHERAL ICs/LSIs

☆New product



■ CCD Peripheral ICs/LSIs

Description	Model No.		Features	Package	
V driver	LR366851	Vertical pulse driver for CCDs, 2- 2-level output circuit for electroni	-level output x 2, 3-level output x 4, c shutter	P-SSOP024-0275	
CDS/PGA/ADC	LR36B03A		/ (TYP.)], high-speed S/H circuit, high-gain PGA circuit, al iris control function, 12-bit digital output	P-HQFN036-0606	
V driver +	LR38653	For 270-k/320-k/410-k/ 470-kpixel CCDs	<v driver=""> Vertical pulse driver for CCDs, 2-level output x 2, 3-level output x 2, 2-level output circuit for electronic shutter <cds adc="" pga=""> 25 MHz, high-speed S/H circuit, high-gain PGA circuit, 12-bit ADC <dsp> 10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, lens shading correction function, auto white blemish compensation function, mirror image function, YUV digital output, NTSC/PAL analog output</dsp></cds></v>	P-LFBGA171-0811	
CDS/PGA/ADC + DSP	LR38654	For 270-k/290-k/320-k/410-k/ 470-kpixel CCDs	<v driver=""> Vertical pulse driver for CCDs, 2-level output x 2, 3-level output x 2, 2-level output circuit for electronic shutter <cds adc="" pga=""> 25 MHz, high-speed S/H circuit, high-gain PGA circuit, 12-bit ADC <dsp> 10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, lens shading correction function, auto white blemish compensation function, mirror image function, electronic optical axis adjustment function*1, YUV digital output, NTSC/PAL analog output</dsp></cds></v>	P-LFBGA171-0811	
CDS/PGA/ADC +	LR36B14	For 270-k/320-k/410-k/	<cds adc="" pga=""> High-speed S/H circuit, high-gain PGA circuit, 12-bit ADC <dsp> 75-ohm video amplifier, mechanical iris control function, 10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, LED light control function, gamma transition function, lens shading correction function, auto white blemish compensation function, mirror image function, NTSC/PAL analog output</dsp></cds>	P-HQFN064-0909	
DSP	☆LR36B15	— 470-kpixel CCDs	<cds adc="" pga=""> High-speed S/H circuit, high-gain PGA circuit, 12-bit ADC <dsp> 75-ohm video amplifier, mechanical iris control function, 10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, lens shading correction function, auto white blemish compensation function, mirror image function, NTSC/PAL analog output</dsp></cds>		
	LR38627		10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, lens shading correction function, auto white blemish compensation function, mirror image function, YUV digital output, NTSC/PAL analog output	P-TQFP128-1414	
DSP	LR38690A	For 270-k/320-k/410-k/ 470-kpixel CCDs	10-bit DAC, synchronous signal generation circuit, CCD drive timing generator, AE control function, AWB control function, lens shading correction function, auto white blemish compensation function, mirror image function, mechanical iris control function, privacy masking function, Day/Night control function, color rolling suppression function, high resolution function, NTSC/PAL analog output, Y/C analog output, UYVY digital output (ITU-R BT656 compatible)*2	P-LQFP100-1414	
Power supply IC for CCDs and peripheral	IR3M59U	For 270-k/320-kpixel CCDs	Input voltage range: 4.5 to 16 V, PWM control + charge pump system, output voltage: three outputs (15 V/12 V, –8 V/–5 V, 3.3 V), power sequencing circuit, overcurrent protection circuit	- P-VOEN032-0505	
ICs/LSIs	IR3M63U	For 270-k/290-k/320-k/410-k/ 470-kpixel CCDs	Input voltage range: 4.5 to 10 V, PWM control + charge pump system, output voltage: four outputs (15 V, –8 V, 3.3 V, 1.8 V), power sequencing circuit, overcurrent protection circuit	P-VQFN032-0505	

^{*1} Support for only 290-kpixel CCD. *2 Support for only 410-k/470-kpixel CCDs.

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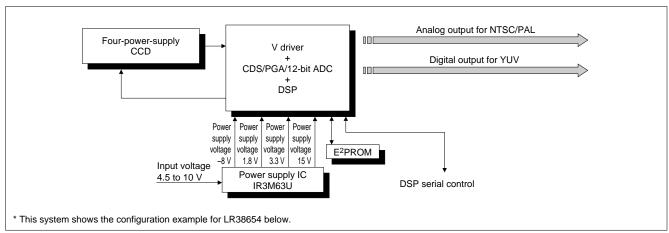
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System Configuration Examples

<Color Security Camera System with Two-chip Configuration [Low Power Consumption Type]>



Four-power-supply CCDs and peripheral IC/LSIs

	CCD		V driver + CDS/PGA/ADC + DSP	Power supply IC		
	070 lmissala	RJ2311DB0PB				
	270 kpixels	RJ2315DB0PB				
	320 kpixels	RJ2321DB0PB		_		
1/2 tupo	320 kpixeis	RJ2325DB0PB	LR38653/LR38654			
1/3 type	410 knivolo	RJ2351CA0PB	LR38003/LR38004			
	410 kpixels	RJ2355CA0PB				
	470 knivolo	RJ2361CA0PB				
	470 kpixels	RJ2365CA0PB				
1/3.8 type	290 kpixels	RJ2411CA0PB	LR38654			
		RJ2411EA0PB				
	270 kpixels	RJ2411EB0PB		IR3M63U		
		RJ2411FA0PB		IKSIVIOSO		
	220 knjivolo	RJ2421EB0PB				
1/4 type	320 kpixels	RJ2421FA0PB	LR38653/LR38654			
	440 knivolo	RJ2451CA0PB				
	410 kpixels	RJ2455CA0PB				
	470 knivolo	RJ2461CA0PB				
	470 kpixels	RJ2465CA0PB				

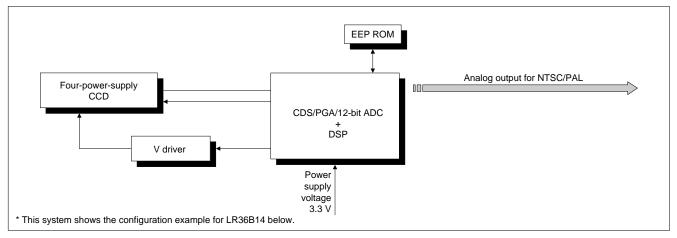


CCD PERIPHERAL ICs/LSIs

☆New product



<Color Security Camera System with Three-chip Configuration>

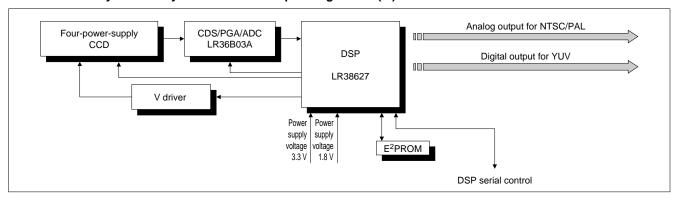


Four-power-supply CCDs and peripheral ICs/LSIs

	CCD		CDS/PGA/ADC + DSP
	270 knivala	RJ2311DB0PB	
	270 kpixels	RJ2315DB0PB	
	220 knivolo	RJ2321DB0PB	
4/2 to ma	320 kpixels	RJ2325DB0PB	
1/3 type	440 looksala	RJ2351CA0PB	
	410 kpixels	RJ2355CA0PB	
	470 kmissala	RJ2361CA0PB	
	470 kpixels	RJ2365CA0PB	
		RJ2411EA0PB	LR36B14/☆LR36B15
	270 kpixels	RJ2411EB0PB	
		RJ2411FA0PB	
	000 looks to a	RJ2421EB0PB	
1/4 type	320 kpixels	RJ2421FA0PB	
	440 lunivala	RJ2451CA0PB	
	410 kpixels	RJ2455CA0PB	
	470 kmissala	RJ2461CA0PB	
	470 kpixels	RJ2465CA0PB	



<Color Security Camera System with Four-chip Configuration (I)>



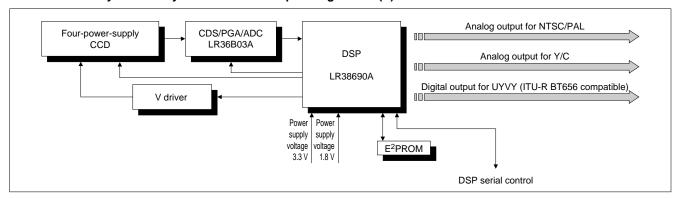
Four-power-supply CCDs and peripheral ICs/LSIs

	CCD		CDS/PGA/ADC	DSP		
	270 knivolo	RJ2311DB0PB				
	270 kpixels	RJ2315DB0PB				
	220 lenistala	RJ2321DB0PB				
1/2 tupo	320 kpixels	RJ2325DB0PB				
1/3 type	440 knivolo	RJ2351CA0PB				
	410 kpixels	RJ2355CA0PB				
	470 lunivala	RJ2361CA0PB				
	470 kpixels	RJ2365CA0PB				
		RJ2411EA0PB	LR36B03A	LR38627		
	270 kpixels	RJ2411EB0PB				
		RJ2411FA0PB				
	220 knivolo	RJ2421EB0PB				
1/4 type	320 kpixels	RJ2421FA0PB				
	440 limitada	RJ2451CA0PB				
	410 kpixels	RJ2455CA0PB				
	470 liningle	RJ2461CA0PB				
	470 kpixels	RJ2465CA0PB				

CCD PERIPHERAL ICs/LSIs



<Color Security Camera System with Four-chip Configuration (II)>



Four-power-supply CCDs and peripheral ICs/LSIs

	CCD		CDS/PGA/ADC	DSP		
	270 knivala	RJ2311DB0PB				
	270 kpixels	RJ2315DB0PB				
	220 knivala	RJ2321DB0PB				
1/2 h m a	320 kpixels	RJ2325DB0PB				
1/3 type	440 knivolo	RJ2351CA0PB				
	410 kpixels	RJ2355CA0PB				
	470 lunivala	RJ2361CA0PB				
	470 kpixels	RJ2365CA0PB				
		RJ2411EA0PB	LR36B03A	LR38690A		
	270 kpixels	RJ2411EB0PB				
		RJ2411FA0PB				
	220 lunivala	RJ2421EB0PB				
1/4 type	320 kpixels	RJ2421FA0PB				
	440 looksala	RJ2451CA0PB				
	410 kpixels	RJ2455CA0PB				
	470 looks le	RJ2461CA0PB				
	470 kpixels	RJ2465CA0PB				



FOR NOTEBOOK PCs, PC MONITORS AND LCD TVs



■ For Notebook PCs, PC Monitors and LCD TVs

TFT-LCD Drivers

Drive f	function	Model No.	Gray scale	No. of LCD drive outputs	Display voltage (V) MAX.	Clock frequency (MHz) MAX.	Supply voltage (V)	Description	Package
		LH16DD		630/642/		250			
Source	Dot	LH16DK	256 levels	684/720	40.5	380	2.7 to 3.6	Low EMI*1 driver using mini-LVDS interface,	
driver	inversion drive	LH16DH		804/840/ 912/960	16.5	330	2.7 10 3.6	R-DAC system	SOF
		LH16DE	1 024 levels	630/642/ 684/720		250			
Gate	driver	LH163Y —		202/242/ 258/262/ 272	20 to 45	20 to 45 200		Output signal masking function, enables construction of module without printed circuit board	

^{*1} EMI: Electro-Magnetic Interference

●TFT-LCD Controller

Model No.	Image	Input	Output interface	Functions	Clock	Su	oply voltage	(V)	Package
	size	interface		Functions	frequency (MHz) MAX.	Core	Digital	Analog	rackage
LR388H3	1 366 x 768 1 920 x 1 080	LVDS 4ch 8/10 bits	mini-LVDS 4ch 8/10 bits	Improves response speed of LCD image by original Quick Shoot technology (with a built-in frame memory) Register control by external EEPROM (SPI) and I ² C I/F Control gamma correction IC (SPI)	170	0.9 to 1.1	3.0 to 3.6	2.3 to 2.7	TFBGA421-1919

●LED Backlight Controller

Model No	LED	Video input	Video output	LED output	Functions	Frame rate	Su	pply voltage	Package	
Model No.	type	interface	interface	interface	Fullcuons	(fps)	Core	LVDS	Ю	rackage
LR388H0	White LEDs	LVDS 2ch 8/10 bits	LVDS 2ch 8/10 bits	SPI	LED backlight controller using area active technology (MAX. 32 x 16 areas) Support for 1 920 x 1 080 / 1 366 x 768 LCD panel Support for wide variety of backlight systems (Direct-type, edge-type, even/odd numbered area division, etc.) Register control by external EEPROM (SPI) and I²C I/F	48/50/60	1.1 to 1.3	2.3 to 2.7/ 3.0 to 3.6	3.0 to 3.6	TFBGA164-1212



FOR MOBILE DEVICES / **POWER SUPPLY ICs FOR TFT-LCDs**



■ For Mobile Devices

TFT-LCD Controllers

Model No.	LCD interface	Display colors	Display RAM	Function	CPU	Supply vo	oltage (V)	Dookogo
wodei no.	(pixel) MAX.	MAX.	capacity (bit)	Function	interface	Core	Host I/F	- Package
LR388J4	600 x 1 024		44 M (Flexibly meets the requirement depending on the panel size)	Built-in 2D-3D image conversion function MDDI*1 1.1/1.2 type2-compliant MIPI*2-compliant Built-in IrSimple™ and IrDA communications functions Main/sub LCD controller Graphic processing Built-in SDHC interface Built-in HDMI 1 080p/24 Hz, 1 080i/60 Hz output interface	MDDI*1 for MSM series/ 80-family (8/16/18-bit			P-WFBGA385-0909
LR388G9		16 770 k colors	32 M (Flexibly meets the requirement depending on the panel size)	• MDDI*¹ 1.1/1.2 type2-compliant • MIPI*²-compliant • Built-in IrSimple™ and IrDA communications functions • Main/sub LCD controller • Graphic processing • Built-in SDHC interface • Built-in HDMI 1 080p/24 Hz, 1 080i/60 Hz output interface	+ '	1.08 to 1.32	1.65 to 3.3	P-WFBGA261-0808
LR388D8	480 x 864		16 M (Flexibly meets the requirement depending on the panel size)	MDDI*¹-compliant Built-in IrSimple™ and IrDA communications functions Main/sub LCD controller Graphic processing Built-in SDHC interface	MDDI*1 for MSM series/ 80-family			P-WFBGA205-0808
LR388D1	240 x 400	262 144 colors	240 x 400 x 18	MDDI*¹-compliant Built-in IrSimple™ and IrDA communications functions Main/sub LCD controller Graphic processing	(8/9/16/ 18-bit parallel)	1.65 to 1.95		P-VFBGA144-0808

^{*1} MDDI (Mobile Display Digital Interface): The serial interface standard developed by QUALCOMM

IrSimple™ is a trademark of Infrared Data Association. QUALCOMM and MSM are trademarks of QUALCOMM Incorporated.

■ Power Supply ICs for TFT-LCDs

Model No.	No. of output circuits	Input voltage range (V)	Output voltage (V)	System	Switching frequency (Hz)	Switching transistor	Switching current (mA) [Built-in SW Tr]	Drive capacity (pF) [External SW Tr]	Package
			F. da	Step-up (MAX. 20 V)/ step-down type PWM	70 1.4-	Built-in (for step-up type PWM)	400		D OFD040 0707/
IR3M58M/U	3	4.5 to 28	External setting	Step-down type PWM	70 k to 500 k	External	_	1 000	P-QFP048-0707/ P-VQFN036-0505
				Step-down, inverting type PWM		External	_		

^{*2} MIPI: Mobile Industry Processor Interface

SYSTEM LSIs / **GRAPHIC DISPLAY MODULE WITH LCDs**



■ System LSIs

Model No.	Function	Features	Supply voltage (V)	Package
LR35501	One-chip graphic controller	Built-in video encoder (NTSC/PAL) Composite signal output Analog RGB signal output Capable of moving picture transmission/play, thanks to real-time image compression and extension technology Real images, backgrounds and sprites can be superimposed Built-in sprite graphic processor Built-in color object detector Built-in Bluetooth® HCI controller Built-in sound generator (ADPCM/PSG) Built-in CMOS camera interface (9 MHz) CPU: Z80 compatible, 27 MHz Peripherals (NAND flash I/F, PIO, SIO, UART, ADC, PWM, etc.)	Core: 1.8±0.18 I/O: 3.3±0.3	P-QFP128-1420
LR35503	One-chip graphic controller	Digital LCD interface (6-bit RGB), QVGA (320 x 240) compliant Transmission (120 x 240) compliant Transmission (120 x 240) compliant Transmission (120 x 240) compliant Capable of moving picture transmission (120 x 240) compliant Capable of moving picture transmission (120 x 240) compliant Capable of moving picture transmission (120 x 240) compliant Capable (120 x 240) compliant (120 x 240) complia	Core: 1.8±0.18 I/O: 3.3±0.3	P-LQFP144-2020

Bluetooth is a trademark of Bluetooth SIG, Inc. Z80 is a trademark of ZiLOG, Inc.

■ Graphic Display Module with LCDs

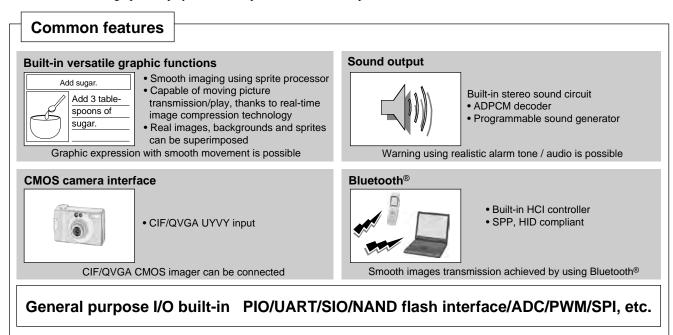
Model No.	Function	Features	Supply voltage (V)	Outline dimensions (W × D) (mm)
LR0G934	3.5" LCD graphic display module (incorporating LR35503)	LED backlight, QVGA (320 x 240), built-in 3.5" color TFT LCD Built-in LR35503 (one-chip graphic controller with built-in 8-bit CPU) Built-in 64-Mbit NOR flash Video input (composite NTSC) Built-in real-time clock (RTC) External interface Video input, digital input/output (shared 2 ch UART), analog input (4 ch ADC), sound output, battery backup terminal (RTC use)	5±0.5	87.4 × 69.2
LR0G938	3.5" LCD graphic display module with touch panel function (incorporating LR35503)	LED backlight, QVGA (320 x 240), built-in 3.5" color TFT LCD Touch panel function Built-in LR35503 (one-chip graphic controller with built-in 8-bit CPU) Built-in 64-Mbit NOR flash Video input (composite NTSC) Built-in real-time clock (RTC) External interface Video input, digital input/output (shared 2 ch UART), analog input (4 ch ADC), sound output, battery backup terminal (RTC use)	5±0.5	87.4 × 69.2

ONE-CHIP GRAPHIC CONTROLLER



■ One-chip Graphic Controller <LR35501/LR35503>

LR35501/LR35503 are the system LSIs which enable smooth graphic display by graphic controller with built-in microcomputers and device control and graphic display with one chip due to the microcomputers and various I/Os.



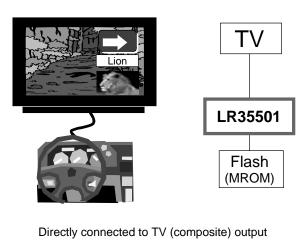
LR35501 features and functions

- Built-in video encoder (NTSC/PAL)
- Built-in analog RGB output
- Built-in composite video output

LR35503 features and functions

- Built-in digital LCD interface (6-bit RGB QVGA [320 x 240])
- Built-in 27 MHz YUV digital video input





Household electrical appliance Recipe guide using moving images TEMP: 200°C TIME: 35 min. Smooth graphics achieved by simple circuits LR35503 LCD (QVGA) Flash (MROM)

Bluetooth is a trademark of Bluetooth SIG, Inc.





■ IrSimple[™] Communications Series <LR388J4/LR388G9/LR388D8/LR388D1>

IrSimpleTM communications is a communications protocol which makes the Ir communication standard employed in mobile terminals such as mobile phones, IrDA protocol, more efficient. Compared with IrDA, since the data transfer time can be significantly reduced to approximately 1/4th to 1/10th, higher volumes of data can be sent and received. In addition, by incorporating a controller for IrSimpleTM communications into mobile equipment or digital home appliances, high-quality image data taken with a digital camera or a mobile phone camera can be readily transferred to a TV or a printer at high speed with a simple operation such as with a remote controller. The image data captured from the camera can be enjoyed on full HD-TV, or by printing the data out.

Features

● LR388J4

(MDDI* 1 /MIPI* 2 -compliant HXGA 3D LCD controller for IrSimple $^{\text{TM}}$)

The 2D-3D image conversion function is incorporated into LR388G9.

The 3D-LCD system in smart phones or tablet-type devices can be achieved with a single chip.

LR388D8

(MDDI*1-compliant WVGA LCD controller for IrSimple™)

The LR388D1 has been made compatible with full-WVGA LCD displays, with internal memory (16 Mbits) that can hold two screens of data (main and sub). High-resolution display and low power consumption have been realized. Furthermore, a built-in SD card interface supports a reduction in the number of chips.

LR388G9

(MDDI*1/MIPI*2-compliant HXGA LCD controller for IrSimple™)

The LR388G9 can display on up to HXGA-sized LCD displays. For incorporating 32-Mbit embedded memory, FHD-sized (1 920 x 1 080) external output is available with HDMI. Also, by adding on MIPI*2 interface, the LR388G9 can be used in wide range of application systems.

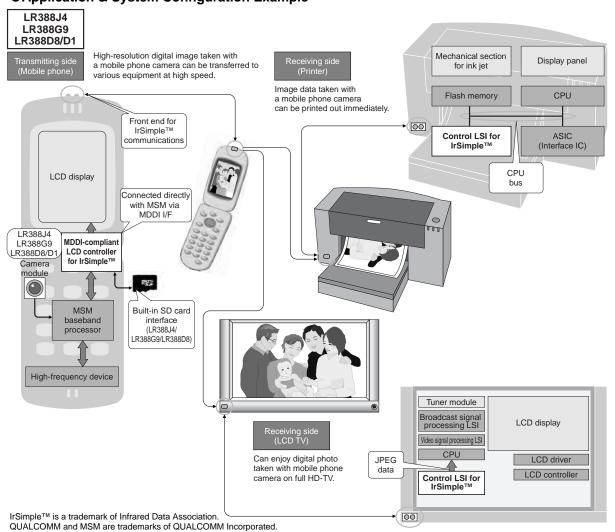
● LR388D1

(MDDI*1-compliant WQVGA LCD controller for IrSimple™)

Thanks to a built-in IrSimple[™] function in the LCD controller, the mounting area of a mobile phone can be decreased; thus it contributes to size reduction in mobile phones. Also, a higher volume of data can be transferred at high speed with 4 fewer signal lines due to the incorporation of an MDDI*¹ interface.

*2 MIPI: Mobile Industry Processor Interface

Application & System Configuration Example



^{*1} MDDI (Mobile Display Digital Interface): The serial interface standard developed by QUALCOMM



LOW POWER-LOSS VOLTAGE REGULATORS / SURFACE MOUNT TYPE LOW POWER-LOSS VOLTAGE REGULATORS



■ Low Power-Loss Voltage Regulators

●TO-220 type $(Ta = 25^{\circ}C)$

		Absolu	ute max	kimum	ratings	Electrica	l characte	eristics		Built-	in func	tions				
Model No.	Features	Output current Io	Input voltage Vin	dissi	wer pation N)		Output voltage precision	Dropout voltage V _I -O*5		rent	control	sipation at OFF state	output	ming	Packa	age
		(A)	(V)	Pd*1	Pd*2	(V) TYP.	(%)	(V)	Overheat protection	Overcurrent protection	ON/OFF	Low dissipation current at OFF s	Variable o	Lead forming available		Package shape type*7
PQxxxRDA1SZH series	ASO protection function,	1	24	1.4	15	3.3, 5, 8, 9, 12	±3	0.5	0	0	0	0				А
PQxxxRDA2SZH series	low dissipation current at OFF state (Iqs: 5 μA (MAX.))	2	20	1.4	15	3.3, 5, 9, 12	±2.5	1.0	0	0	0	0				А
PQ070XF01SZH	Minimum operating input voltage: 2.35 V (4 terminals)	1							0	0			0			Α
PQ070VK01FZH	Minimum operating input	1	10	1.4	15	1.5 to 7	±2*4	0.5	0	0	0	0	0	0		Е
PQ070VK02FZH	voltage: 2.35 V (5 terminals)	2							0	0	0	0	0	0	TO-220	Е
PQ150RWA2SZH	ASO protection function	2	20	1.4	15	3.0 to 15	±2.5*4	1.0	0	0			0			А
PQ30RV11J00H		1		1.5	15				0	0	△*6		0	0		В
PQ30RV21J00H	Variable output voltage	2	35	1.5	18	1.5 to	±2*4	0.5	0	0	△*6		0	0		В
PQ30RV31J00H		3		2	20				0	0	∆*6		0	0		В

At self-cooling

■ Surface Mount Type Low Power-Loss Voltage Regulators

●SOT-89 type $(Ta = 25^{\circ}C)$

												١,	/
		Absolute maximum ratings			Electrica	character	istics		Built-	in fund	ctions		
Model No.	Features	Output current Io (A)	Input voltage Vin (V)	Power dissipa- tion Pd*1 (W)	Output voltage Vo* ² (V) TYP.	Output voltage precision (%)	Dropout voltage V _I -o* ³ (V)	Overheat protection Overheat protection Overcurrent protection ON/OFF control Current at OFF state Variable output voltage	Package				
PQ1LAxx5MSPQ	Compact, high radiation package, ceramic capacitor compatible	0.5	15	0.9	1.2, 1.5, 1.8, 2.5, 3.3, 5.0	±2.0	0.7	0	0	0	0		SOT-89
PQ1LAX95MSPQ	Ceramic capacitor compatible, variable output voltage	0.5	15	0.9	1.5 to 9.0	±2.0*4	0.7	0	0	0	0	0	301-09

When mounted on a board

^{*2} With infinite heat sink attached

^{*3} The xxx in the model No. refer to the output voltage values of the model (e.g. 050 for 5 V, 120 for 12 V, 015 for 1.5 V).

^{*4} Reference voltage precision

^{*5} Current ratings are defined individually.

^{*6 △ :} Available by *7 Refer to page 41 \triangle : Available by adding circuit

^{*2} The xx in the model No. refer to the output voltage values of the model (e.g. 25 for 2.5 V, 50 for 5.0 V).

^{*3} Current ratings are defined individually.
*4 Reference voltage precision

SURFACE MOUNT TYPE LOW POWER-LOSS VOLTAGE REGULATORS



●SC-63 type (1) Output voltage fixed type

 $(Ta = 25^{\circ}C)$

		Abs	olut	e ma	aximum	ratings	Electrica	l charac	teristics		Built-	in fund	ctions				
Model No.	Features	Output current Io (A)		Input voltage	Power dissipation	Output voltage Vo*2	Output voltage preci-	voltage		nt	control	dissipation ent at OFF state	output	package	Pack	age	
		0.5	0.5 1 1.5		Vin (V)	Pd*1 (W)	(V) TYP.	sion (%)	V _{I-O*4} (V)	Overheat protection	Overcurrent protection	ON/OFF (Low dissipation current at OFF	Variable o	Taped pad		Package shape type*5
PQxxxDNA1ZPH series	Ceramic capacitor compatible, ASO protection function, low dissipation current at OFF state (Iqs: 5 µA (MAX.)), solder dip compatible lead shape		0		24	8	3.3, 5, 9, 12	±2.5	0.5	0	0	0	0	_	0		G
PQxxxENA1ZPH series		0	0			8	1.5, 1.8, 2.5, 3.3			0	0	0	0	_	0		G
PQxxxENB1ZPH series	Minimum operating input voltage: 2.35 V, ceramic capacitor compatible, solder dip compatible lead shape		0		10	5	1.2, 1.5, 1.8, 2.5, 3.3	±2.0	0.3	0	0	0	0	-	0	SC-63	G
PQxxxENAHZPH series	solder dip compatible lead shape			0			1.5, 1.8, 2.5, 3.3		0.9	0	0	0	0	_	0		G
PQxxxGN01ZPH series	Minimum operating input voltage: 1.7 V (Dual power supply type),	7 V (Dual power supply type), ramic capacitor compatible,	0		5.5	8	10.12	±30		0	0			-	0		G
PQxxxGN1HZPH series	ceramic capacitor compatible, solder dip compatible lead shape			0	5.5	5.5	1.0, 1.2	mV	_	0	0			-	0		G

With infinite heat sink attached

- The xxx in the model No. refer to the output voltage values of the model (e.g. 033 for 3.3 V, 050 for 5 V, 120 for 12 V).
- The value is defined as ±50 mV in some models.
- *3 The value is defin *4 Current ratings ar *5 Refer to page 41 Current ratings are defined individually.

●SC-63 type (2) Output voltage variable type

(Ta = 25°C)

		Ab	solut	e ma	aximum	ratings	Electrica	al charac	teristics		Built-	in fun	ctions				
Model No.	Features	(A) volt		Input voltage	Power dissipation	Output voltage Vo	Output voltage preci-	voltage		ınt	control	pation OFF state	output	skage	Pack	age	
		0.5	1	1.5	Vin (V)	Pd*1 (W)	(V) TYP.	sion (%)	VI-0*3 (V)	Overheat protection	Overcurrent protection	ON/OFF control	Low dissipation current at OFF s	Variable o voltage	Taped package		Package shape type*4
PQ070XNA1ZPH			0						0.5	0	0	0	0	0	0		G
PQ070XNAHZPH	Minimum operating input voltage: 2.35 V,			0	10	8	1.5 to 7	1	0.9	0	0	0	0	0	0		G
PQ070XNA2ZPH	ceramic capacitor compatible, solder dip compatible lead shape			(2 A)	10			±2.0*2	0.5	0	0	0	0	0	0		G
PQ070XNB1ZPH			0			5	1.2 to 7		0.3	0	0	0	0	0	0		G
PQ035ZN01ZPH	Reference voltage (Vref): 0.6 V, minimum operating input voltage: 1.7 V (Dual power supply type).		0		5.5		0.8 to	±30	-	0	0			0	0		G
PQ035ZN1HZPH	ceramic capacitor compatible, solder dip compatible lead shape			0	3.3		3.5	mV	_	0	0			0	0	SC-63	G
PQ200WNA1ZPH	Minimum operating input voltage: 3.5 V, ASO protection function, low dissipation current at OFF state (lqs: 5 µA (MAX.)), ceramic capacitor compatible, solder dip compatible lead shape		0		- 24	8	3.0 to 20	±2.5*2	0.5	0	0	0	0	0	0		G
PQ200WN3MZPH	Minimum operating input voltage: 5.5 V, low dissipation current at OFF state (lqs: 5 µA (MAX.)), ceramic capacitor compatible, current limit: 800 mA	(0.3)			24	6.8	5.0 to 20	±2.5" ²	0.5	0	0	0	0	0	0		G

With infinite heat sink attached

^{*2} Reference voltage *3 Current ratings ar *4 Refer to page 41

Reference voltage precision Current ratings are defined individually.



SURFACE MOUNT TYPE LOW POWER-LOSS VOLTAGE REGULATORS



●TO-263 type

 $(Ta = 25^{\circ}C)$

		Absolute	e maximui	m ratings	Electri	cal charact	eristics		Built-	in fund	ctions			
Model No.	Features	Output current Io (A)	Input voltage Vin (V)	Power dissipa- tion Pd*1 (W)	Output voltage Vo (V) TYP.	Output voltage precision (%)	Dropout voltage V _{I-O*3} (V)	Overheat protection	Overcurrent protection	ON/OFF control	Low dissipation current at OFF state	Variable output voltage	Taped package	Package
PQ070XHA2ZPH	2 A output (minimum operating input voltage: 2.35 V), ceramic capacitor compatible	2.0	10	35	1.5 to 7	±2.0*2	0.5	0	0	0	0	0	0	TO-263

^{*1} With infinite heat sink attached

●SOP-8 type

(Ta = 25°C)

		Absolu	te maximum	ratings	Electrical charact	eristics	Built-in f	unctions	Je	
Model No.	Features	Output current Io (A)	Input voltage Vin (V)	Power dissipation Pd*1 (W)	Output voltage Vo (V) TYP.	Output voltage precision*2 (mV)	Overheat protection	Overcurrent protection	Taped package	Package
PQ1DX095MZPQ	Built-in sink source function (For DDR II memory)	±0.8	6	0.6	VDD x 1/2 (VDDQ: 1.5 V (MIN.))	±25	0	0	0	SOP-8
PQ1DX125MZPQ	Built-in sink source function (For DDR memory)	±0.8	0	0.6	VDD x 1/2 (VDDQ: 2.3 V (MIN.))	±35	0	0	0	30F-8

When mounted on a board

^{*2} Reference voltage precision
*3 Current ratings are defined individually.

^{*2} Reference voltage precision



SURFACE MOUNT TYPE CHOPPER REGULATORS



■ Surface Mount Type Chopper Regulators (DC-DC Converters)

(Ta = 25°C)

									۷.۰	- 20 0)
			solute im ratings		Electrical	charact	eristics		Pack	age
Model No.	Features	Switching current Isw (A)	Power dissipa- tion Pd*1 (W)	Input voltage range Vin (V)	Output voltage*2 Vo (V)	Output type	Oscillation frequency fo (Hz) TYP.	Output saturation voltage Vsat (V) TYP.		Outline shape type*4
PQ6CU12X2APQ	High switching voltage: 40 V (MAX.) For tuner power supply Variable oscillation frequency Ceramic capacitor compatible	0.25	0.35	3.0 to 5.5	up to 36	Step- up	300 k to 800 k	Ron TYP. 1.7Ω	SOT-23	-6W
PQ1CN38M2ZPH	PWM chopper regulator (high oscillation frequency) Output ON/OFF control function Overcurrent/overheat protection circuits For light load	0.8	8		VREF*3 to 35	Step- down	300 k	0.9		G
PQ1CN41H2ZPH	PWM chopper regulator (high oscillation frequency) Overcurrent/overheat protection circuits		8	4.5 to 40	(step-down type)/ -VREF to -30 (inverting type)	Step- down	300 k	0.9	SC-63	G
PQ1CZ21H2ZPH	PWM chopper regulator Output ON/OFF control function Overcurrent/overheat protection circuits Low dissipation current at OFF state (Standby current < sp>: 1 µA (MAX.))	1.5	8		(into any type)	Step- down	100 k	0.9		F
PQ1CX41H2ZPQ	Bootstrap system for high efficiency (Efficiency 90% (TYP.)) Low voltage output: 0.8 V (MIN.) Ceramic capacitor compatible	1.5	0.8 When mounted on board	4.75 to 27	0.8 to 20	Step- down	400 k	RDSon TYP. 0.45Ω	SOP-8	
PQ1CX53H2MPQ	Bootstrap system for high efficiency (Efficiency 89% (TYP.)) Low voltage output: 0.8 V (MIN.) Ceramic capacitor compatible	3.5	2 When mounted on board	4.75 to 27	0.8 to 16	Step- down	400 k	RDSon TYP. 0.15Ω	USB-8	
PQ1CX61H1ZPQ	Bootstrap system for high efficiency (Efficiency 88% (TYP.)) Low voltage output: 1.0 V (MIN.) Ceramic capacitor compatible	1.5	0.8 When mounted on board	4.75 to 28	1.0 to 18.9	Step- down	900 k	RDSon TYP. 0.55Ω		
PQ1CY1032ZPH	PWM chopper regulator Output ON/OFF control function Overheat protection/overcurrent shutdown circuits High output current type	3.5	35	4.5 to 40	VREF*3 to 35 (step-down type)/ -VREF to -30 (inverting type)	Step- down	150 k	1.4	TO-263	i

^{*1} With infinite heat sink attached or when mour *2 Output variable range (step-down/inversion). *3 VREF nearly equal to 1.26 V *4 Refer to page 41 With infinite heat sink attached or when mounted on a board listed in the specification sheets.



CHOPPER REGULATORS / DC-DC CONVERTER MODULE WITH BUILT-IN COIL

☆New product



■ Chopper Regulators (DC-DC Converters)

●TO-220 type (Ta = 25°C)

			olute n ratings		Electrical o	characte	eristics		Pack	age
Model No.	Features	Switching current Isw (A)	Power dissipa- tion Pd*1 (W)	Input voltage range Vin (V)	Output voltage Vo* ² (V)	Output type	Oscillation frequency fo (kHz) TYP.	Output saturation voltage Vsat (V) TYP.		Outline shape type*5
PQ1CG38M2FZH	PWM chopper regulator (high oscillation frequency) Built-in overcurrent/overheat protection circuits	0.8*3					300	0.95		Е
PQ1CG38M2RZH	For light load Output ON/OFF control function	0.0					000	0.50		D
PQ1CG21H2FZH	PWM chopper regulator Built-in overcurrent/overheat protection circuits						100	1.0		Е
PQ1CG21H2RZH	Output ON/OFF control function	1.5*3					100	1.0		D
PQ1CG41H2FZH	PWM chopper regulator (high oscillation frequency)	1.0	14	40	VREF*4 to 35 (step-down type)/	Step-	300	1.0	TO-220	Е
PQ1CG41H2RZH	Built-in overcurrent/overheat protection circuits Output ON/OFF control function		17	40	-VREF*4 to -30 (inverting type)	down	000	1.0	10 220	D
PQ1CG2032FZH	PWM chopper regulator Built-in overcurrent/overheat protection circuits						70			Е
PQ1CG2032RZH	Output ON/OFF control function	3.5* ³					70	1.4		D
PQ1CG3032FZH	PWM chopper regulator (high oscillation frequency)	J.J v					150	1.4		Е
PQ1CG3032RZH	Built-in overcurrent/overheat protection circuits Output ON/OFF control function						130			D

^{*1} With infinite heat sink attached

■ DC-DC Converter Module with Built-in Coil

(Ta = 25°C)

		Absolute max	kimum ratings		Electri	cal characteri	stics		
Model No.	Features	Output current Io (A)	Operating temperature Topr (°C)	Control system	Input voltage range Vin (V)	Oscillation frequency fo TYP. (MHz)	Output voltage Vo*1 (V)	Standby current Isd (µA) TYP.	Outline dimensions (W x D x H) mm
☆PQ5CM03P	DC-DC converter module with built-in coil for simplified power- supply design High efficiency thanks to synchronous rectification method (efficiency: 81%)	3.0	-10 to +85	PWM system	8.0 to 14	1.0	1.1 to 3.3	20	9.0 x 6.0 x 2.6

^{*1} Output voltage variable range

^{**} Vitth minime near sink attached
** Output voltage variable range
** Peak current
** VREF nearly equal to 1.26 V (TYP.)
*5 Refer to page 41



POWER SUPPLY ICs FOR CCDs/CCD CAMERA MODULES



■ Power Supply ICs for CCDs/CCD Camera Modules

Model No.	No. of output circuits	Input voltage range (V)	Output voltage (V)	System	Switching frequency (Hz)	Switching transistor	Switching current (mA) [Built-in SW Tr]	Drive capacity (pF) [External SW Tr]	Package
			15	Charge pump	200 k		12 (DC)	-	
IR3M63U	4	4.5 to 10	-8	Negative charge pump	200 K	200 k – 2.5 (DC) –		-	P-VQFN032-0505
IKSIVIOSU	4	4.5 to 10	3.3	Step-down type PWM + REG	1 M	Built-in	120 (DC)		
			1.8	Step-down type PWM + REG	I IVI	Duiit-iii	50 (DC)	-	
			15/12	Charge pump	200 k		12/20 (DC)	-	
IR3M59U	3	4.5 to 16	-8/-5	Negative charge pump	arge pump 200 k –	_	2.5/5 (DC)	_	P-VQFN032-0505
			3.3	Step-down type PWM + REG	1 M	Built-in	150 (DC)	-	



☆New product



■ LED Drivers

●Built-in step-up circuit (1)

Model No.	Function	Features	No. of output circuits	Number of LEDs		Constant current circuit	Switching transistor	Input voltage range (V)	Output*3 current (mA) MAX.	Oscillation frequency (Hz) TYP.	Package
PQ6CB11X1CP	- White LED driver	High voltage CMOS output: 30 V (MAX.) Output ON/OFF control function Overvoltage/overcurrent protection circuits Soft start function	1	6 (Series connection)		*1	0	2.7 to 5.5	250*²	1.2 M	USB-6
PQ7L2020BP	for backlight (for small panels)	High voltage CMOS output: 37 V (MAX.) Output ON/OFF control function Overvoltage/overcurrent protection circuits Soft start function Possible to use a low-capacity (0.1 μF) output capacitor	1	9 (Series connection)	PWM	*1	0	2.9 to 5.5	500	1.0 M	USB-6
PQ7L3010QPF	White LED driver for flashlight	Automatic-switching (between 1x/2x) charge pump system Non-external coil Built-in fail-safe function Short-circuit LED protection function/overheat protection function/soft start function	1	1	Charge pump	*1	-	2.6 to 4.4	800	0.9 M	16QFN
IR2E49U/ IR2E49M	White LED driver for backlight	Capable of driving a maximum of 40 LEDs with 8 LEDs (in series) per channel Built-in step-up DC-DC controller Capable of controlling brightness using PWM control Step-up output control according to LED-Vf	5	40	PWM	0	External	6 to 28	150/ ch* ⁴	100 k to 1 M* ⁵	P-VQFN036- 0606/ P-QFP048- 0707
IR2E63Yx	LED driver for backlight and call alert display (auto brightness adjustment)	Capable of driving 9 main-LEDs + 2 sub-LEDs (series) and 6 call alert LEDs (RGB) Auto brightness adjustment and PWM brightness adjustment Power supply for EL panel and LCD controller LDO 4ch Built-in input terminals for ambient light sensor and proximity sensor 2C/SPI interface-compatible	9	15	PWM + charge pump	0	0	3 to 4.2 (for drive)/ 1.62 to 3.2 (for control)	Main 25.6/ch Call alert 12.8/ch	1 M	63WL-CSP* ⁶
☆IR2E68Yx	LED driver for backlight and call alert display (auto brightness adjustment)	Capable of driving 10 main-LEDs + 2 sub-LEDs (series) and 6 call alert LEDs (RGB) Auto brightness adjustment and PWM brightness adjustment Power supply for EL panel and LCD controller LDO 4ch Built-in input terminals for ambient light sensor and proximity sensor PC/SPI interface-compatible	10	16	PWM + charge pump	0	0	3 to 4.2 (for drive)/ 1.62 to 3.2 (for control)	Main 25.6/ch Call alert 12.8/ch	1 M or 500 k	63WL-CSP* ⁽
IR2E56U6	White LED driver for backlight	Capable of driving a maximum of 72 LEDs with 12 LEDs (in series) per channel Built-in step-up DC-DC controller High oscillation frequency (1.5 MHz) makes use of a small coil possible Capable of controlling brightness using PWM control Step-up output control according to LED-Vf Built-in sequential drive mode for output current	6	72	PWM	0	External	5 to 28	25/ch	200 k to 1.5 M	32VQFN
IR2E58U		Capable of driving a maximum of 96 LEDs with 12 LEDs (in series) per channel Built-in step-up DC-DC converter High oscillation frequency (1.5 MHz) makes use of a small coil possible Capable of controlling brightness using PWM control Step-up output control according to LED-Vf	8	96		0	0	4.5 to 28	40/ch	500 k to 1.5 M	24HQFN

^{*1} LED constant current value can be set by external resistors.

^{*1} LED constant current value can so set 2, 2.
*2 Peak switching current
*3 Constant current (MAX.)
*4 Use this IC within the range of power dissipation.
*5 Selectable oscillation frequency range
*6 3.57 mm x 3.57 mm x 0.585 mm (TYP.)



☆New product



●Built-in step-up circuit (2)

Model No.	Function	Features	No. of output circuits	Number of LEDs	Booster method	Constant current circuit	Switching transistor	Input voltage range (V)	Output*1 current (mA) MAX.	Oscillation frequency (Hz) TYP.	Package
IR2E65U	White LED driver	Capable of driving a maximum of 120 LEDs with 12 LEDs (in series) per channel Built-in step-up DC-DC controller High oscillation frequency (1.5 MHz) makes use of a small coil possible Wider range of PWM brightness control possible, from simultaneous total output control to local dimming Step-up output control according to LED-Vf	10	120	PWM	0	External	10 to 28	100/ch	500 k to 1.5 M	52HQFN
☆IR2E67M	for backlight	Built-in 10 ch. constant-current control amplifier (external output transistor) Enables driving LEDs up to external transistor voltage limit Built-in timing controller for lighting Wider range of PWM brightness control possible, from simultaneous total output control to local dimming Step-up output control according to LED-Vf	10	*2	*3	*4	-	4.5 to 5.5	*5	_	80LQFP- 1420

●External power supply for LEDs

Model No.	Function	Features	Supply voltage (V)	Package
IR2D20U	24-dot LED panel driver with constant-current sink outputs	Output current (constant current sink output): 30 mA (MAX.) (setup by external resistor) Gradation function (clock cycle setting or external synchronization) Independent current control for three systems (for RGB LED) LED drive voltage: 15 V Rated output voltage: 20 V (MAX.) fclk: 20 MHz (MAX.)/16.6 MHz (MAX.) (at cascade connection)	4.5 to 5.5	P-HQFN052-0707
IR2D071	16-dot LED panel driver with constant current sink outputs	Output current (constant-current sink output): 60 mA (MAX.) (setup by external resistor) Rated output voltage: 7 V (MAX.) fclk: 20 MHz (MAX.)/16.6 MHz (MAX.) (at cascade connection)	3.0 to 5.5	P-SDIP028-0400

Determined by external transistor voltage limit.

Built-in feedback voltage-generating circuit for external power supply.

Built-in constant-current control amplifier (external output transistor)

^{*1} Constant current (MAX.)
*2 Determined by external transistor
*3 Built-in feedback voltage-genera
*4 Built-in constant-current control a
*5 Determined by external resistor.



AC-DC CONVERSION TYPE ICS FOR LED LIGHTING / AC DIRECT TYPE ICS FOR LED LIGHTING / POWER SUPPLY MODULES FOR LED LIGHTING / POWER AMPLIFIERS FOR WIRELESS LAN

☆New product **★**Under development



■ AC-DC Conversion Type ICs for LED Lighting

		Absolute maximum ratings							
Model No.	Features	Vcc (V)	Topr (°C)	Drive voltage Vcc (V) MIN.	Dissipation current Icc (mA) TYP.	Low level output current loL (mA) MIN.	High level output current IOH (mA) MAX.	Switching frequency Fsw (kHz) TYP.	Package
PQ1DC15C0P	Use of forward type allows high (00%) afficiency rate	22	-30 to +100	20	2	45	45	CO	SOT-23
PQ1DC15F1P	high (90%) efficiency rateNo electrolytic capacitor	23		20	3	15	-15	68	SOP-8

■ AC Direct Type ICs for LED Lighting

		Absolute max	Absolute maximum ratings		Electrical characteristics					
Model No.	Features	VIN1 (V)	Topr (°C)	VS terminal voltage VS (V) TYP.	Dissipation current lcc (mA) TYP.	Low level output current for DG terminal IDG2 (μA) MIN.	High level output current for DG terminal IDG1 (μA) MAX.	Package		
☆IR3M85N4	Compatible with existing dimmers No electrolytic capacitor	395	0 to +85	20	1	40	-50	SOP-14		

■ Power Supply Modules for LED Lighting

		Absolute max	kimum ratings			Electrical ch	aracteristics			
Model No.	Features	VAC (V)	Topr (°C)	Input voltage VAC (V) TYP.	Output voltage Vout (V) TYP.	Output current lout (mA) TYP.	Output power Po (W) TYP.	Efficiency η (%) TYP.	Power factor PF TYP.	Outline dimensions (mm)
★PQ1AS1D01	Step-down type Compatible with existing dimmers High efficiency	110		100	24	31 200		80	0.9	
★PQ1AS1D01A		132	-10 to +80	120	31	200	6.2	82	0.8	23 × 42 × 23.6
★PQ1AS2D01		253		230	62	100		85	0.8	

■ Power Amplifiers for Wireless LAN

Model No.	Application	Supply voltage Vcc (V) TYP.	Control voltage Vbb (V) TYP.	Linear output power*1 (dBm)	Dissipation current (mA) TYP.	Gain (dB) TYP.	Detection circuit	Matching circuit	Package (mm)
IRM068U7	For 2.4 GHz single-band wireless LAN			18	115	27	○*2	Built-in (IN)	HQFN6 pin
QM2A1UA003	(IEEE802.11b/g/n)			20	150	28	0	Built-in (IN)	$(1.5 \times 1.5 \times 0.4 \text{ mm})$
IRM053U7	For 5 GHz single-band wireless LAN		2.8	18	170	30	0	Built-in (IN/OUT)	HQFN10 pin
QM2A1UA004	(IEEE802.11a/n)	3.3		20	225	31	0	Built-in (IN/OUT)	(2 × 2 × 0.4 mm)
IRM065U7				18	130	30	. 0	Built-in	
INIVIOUSU7	For 2.4/5 GHz dual-band wireless LAN			18	160	30		(IN/OUT)	HQFN16 pin
IRM067U6	(IEEE802.11a/b/g/n)		2.9	17	100	28	<u></u>	Built-in	$(3 \times 3 \times 0.4 \text{ mm})$
11/10/07/00			2.9	17	140	30	0 -	(IN/OUT)	

^{*1} At time of OFDM 64QAM modulating wave input.

^{*2} Load fluctuation stabilization and detection output type



FAIL SAFE ICs / **SOLAR MODULES FOR MOBILE DEVICES**

☆New product



■ Fail Safe ICs

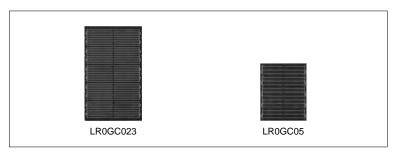
Model No.	Features	Op	perating volta	ige	Dissipation current	Operating temp.	Package
Wiodel No.	reatules	VBAT (V)	VBAC (V)	VIO (V)	(μA) TYP.	(°C)	Гаскауе
IR3T46U6	Malfunction detection Built-in 8-bit ADC Built-in timer circuit Built-in key detection output OR gate	204-45	0.04-0.0	2.6 to 3.0	40	00.42 + 05	P-HQFN024-0404
IR3T48Y6	Small package Built-in 3-STATE buffer Malfunction detection Built-in 8-bit ADC Built-in timer circuit Built-in key detection output OR gate	3.2 to 4.5	3.0 to 3.3	1.6 to 3.0	- 10	−20 to +85	35WL-CSP*

^{* 3.0 (}W) x 3.0 (D) x 0.975 (H) mm (TYP.)

■ Solar Modules for Mobile Devices

Model No.	Features	Maximum output power* Pmax (mW) TYP.	Maximum output voltage* Vpm (V) TYP.	Maximum output current* Ipm (mA) TYP.	Outline dimensions (mm)
☆LR0GC023	Module thickness: 0.8 mm	365	4.9	75	67.5 × 41.0 × 0.8
☆LR0GC05	Module thickness: 1.0 mm	160	4.6	35	41.0 × 33.0 × 1.0

^{*} Measuring conditions: AM 1.5; irradiance: 1 000 W/m² ± 50 mW; module temperature: at 25°C





■ CSP

●CSP (Chip Size Package)

The FBGA (commonly known as CSP) has an area array terminal structure with solder balls on the bottom, to give it a near chip-size footprint. This high-density, compact and low-profile package technology will greatly help in the design of compact mobile equipment, such as mobile phones and digital cameras.



• Compact and lightweight

Ability to create a near-chip size and lighter-weight package in comparison with conventional plastic packages.

High reliability

Comparable high reliability with that of conventional plastic packages.

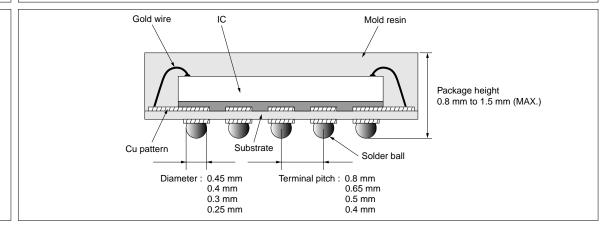
Features

Mountability

Conventional mounting system is available for CSP. SOP and QFP can be mounted together with CSP.

Terminal pitch	0.8 mm	0.65 mm	0.5 mm	0.4 mm
Maximum terminal counts	352 (16 mm x 16 mm)	352 (16 mm x 16 mm)	372 (16 mm x 16 mm)	264 (10 mm x 10 mm)
Nominal dimensions	6	mm x 6 mm to 16 mm x 16 m	m	5 mm x 5 mm to 10 mm x 10 mm

Cross section example



●Wafer-level CSP

The wafer-level CSP (WL-CSP) is a kind of chip-size package which is manufactured by assembling directly onto the finished wafer.

Compact and thinner size

It makes it possible to create an almost IC-size and lighter-weight package.

Mountability

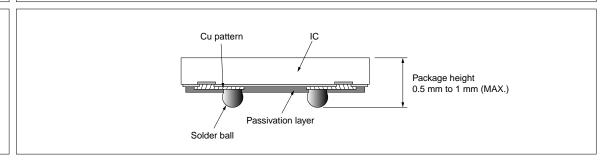
The conventional CSP mounting system can be also used in that of wafer-level CSP, which facilitates chip mounting more than bare-chip mounting does. It can be mounted together with other existing packages and passive components. (The use of underfill is recommended to improve the reliability of assembly.)

Chip size*	4 mm :	4 mm x 4 mm 3		3.5 mm x 3.5 mm		c 3 mm
Pad pitch	0.5 mm	0.4 mm	0.5 mm	0.5 mm 0.4 mm		0.4 mm
Maximum terminal counts	49 (7 x 7)	81 (9 x 9)	36 (6 x 6)	49 (7 x 7)	25 (5 x 5)	36 (6 x 6)

^{*} Rectangular chip form is also available.

Cross section example

Features



32

■ SiP (System in Package)

System in Package is SHARP's original high-density mounting technology that achieves high-density memory capacity and multiple functions by stacking multiple ICs or multiple packages. The System in Package technology means chip-stacked package technology that can achieve up to 5-chip mounting by stacking ICs in a single package. The System in Package technology contributes to higher functionality of applications, such as mobile phones and digital cameras, as well as to reduction in size and weight.

Chip Stacked CSP

Wide variety of lineup

It is possible to provide a wide lineup of stacked CSPs, including 2-chip, 3-chip, 4-chip and 5-chip stacked CSPs, to respond to customer needs.

Compact and thinner size

Encapsulating multiple ICs into an existing plastic package contributes to decreasing the mounting area. In addition, SHARP's wafer thinning technology makes it possible to achieve 1.4 mm (MAX.) package height.

Features

 Multiple functions Multiple ICs of different sizes and functions, such as logic LSIs and memories, can be incorporated in a single package, making possible multiple functions.

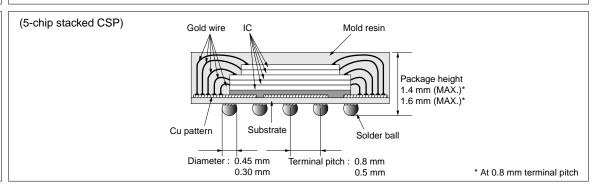
• Same-size IC stacking technology

SHARP's stacking technology enables stacking of multiple same-size ICs, contributing to higher memory density.

(4-chip stacked CSP)

When using a SHARP four-chip stacked CSP, the mounting area and weight of a package can be decreased by half in comparison with using two 2-chip stacked CSPs, or a 3-chip stacked CSP and a conventional CSP.

Cross section example





● Chip Stacked TSOP/QFP*/VQFN/HQFN

• Decreased mounting area

By encapsulating two identical or different types of ICs into a single conventional plastic package, the mounting area of the package can be decreased.

Features

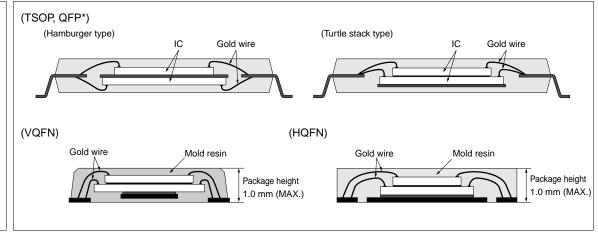
Multiple functions

Thanks to the incorporation of different sizes and functions of multiple ICs, such as logic LSIs and memories, the functionality increases.

• Higher memory density

When incorporating two identical memory ICs into a single package, memory density doubles on the same mounting area.

Cross section example



^{*} Including TQFP and LQFP.

■ SOF

●SOF (System On Film)

SOF is a highly flexible thin film package, created from SHARP's TCP technologies. It can be easily bent, and contributes to thin and compact design of products. Peripheral circuit components can also be mounted.



Features

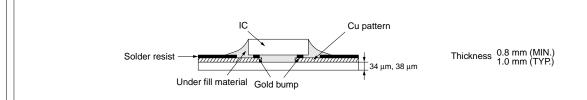
• Highly flexible and thin film package

By using highly flexible and thin film, SOF contributes to creating thin and compact products. It can also achieve finer terminal pitches and multiple outputs easily, and pattern layout on a film under the chip makes it possible to improve the flexibility of the pattern layout.

Multiple chip mounting

Multiple chip mounting with peripheral chip components contribute to the higher functionality of products.

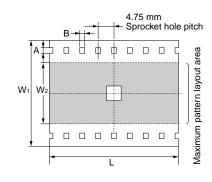
Cross



section	
example	

_								
	Film width : W ₁	35 mm super wide	48 mm super wide	70 mm wide				
	Maximum pattern layout area: W2	28.6 mm	41.6 mm	59.0 mm				
	Maximum device pitch : L		15 sprockets					
	Pattern thickness	8 µm						
	Pattern layer		Electro-deposited Cu					
	Pattern layer finish		Tin (Sn)					
	Minimum pattern pitch	0.025 mm						
	Sprocket hole : A		1.981 mm (wide) /1.42 mm (super wide)					
	Sprocket hole : B		1.981 mm (wide) /1.42 mm (super wide)					

Film specifications



Other components

Bare chips and peripheral chip components can be mounted on the film.



■ Package Lineup

●Surface-mount Type

Package type	Appearance (Package material)	Package code	No. of terminals	Terminal pitch mm	Nominal dimensions mm	Package depth & width (D x W) x (seated height [MAX.]) mm
		P-LFBGA048-0606			6 x 6	6.0 x 6.0 x (1.4)
			P-TFBGA048-0608	48		6 x 8
		P-TFBGA048-0808				
		P-TFBGA056-0808	56	-	8 x 8	8.0 x 8.0 x (1.2)
		P-TFBGA060-0811	60 (48)*			
		P-TFBGA064-0811	64	1		8.0 x 11.0 x (1.2)
		P-TFBGA072-0811		1	8 x 11	, ,
		P-LFBGA072-0811	72 (64)*			8.0 x 11.0 x (1.4) / (1.6)
		P-TFBGA081-0808	81		8 x 8	8.0 x 8.0 x (1.2)
		P-LFBGA085-0811	85	1		
		P-LFBGA087-0811	87	1	8 x 11	8.0 x 11.0 x (1.4) / (1.6)
		P-LFBGA088-0811		1		
		P-LFBGA088-0912	88	0.8	9 x 12	9.0 x 12.0 x (1.4) / (1.6)
		P-LFBGA090-0811	90		8 x 11	8.0 x 11.0 x (1.4) / (1.6)
		P-TFBGA096-1010	96		10 x 10	10.0 x 10.0 x (1.2)
		P-LFBGA107-0912	107		9 x 12	9.0 x 12.0 x (1.4) / (1.6)
		P-TFBGA111-1010	111			
		P-TFBGA112-1010	112		10 x 10	10.0 x 10.0 x (1.2)
FBGA (CSP)		P-LFBGA115-0914	115		9 x 14	9.0 x 14.0 x (1.4) / (1.6)
(CSP)	DW	P-LFBGA116-1010	116	1	10 x 10	10.0 x 10.0 x (1.4) / (1.6)
		P-LFBGA130-1013	130	1	10 x 13	10.0 x 13.0 x (1.4) / (1.6)
		P-TFBGA144-1111	144	1	11 x 11	11.0 x 11.0 x (1.2)
		P-TFBGA160-1212	160	1		12.0 x 12.0 x (1.2)
		P-LFBGA168-1212	168	1	40.40	12.0 x 12.0 x (1.4) / (1.6)
		P-TFBGA180-1212	180	1	12 x 12	
		P-TFBGA184-1212	184	1		12.0 x 12.0 x (1.2)
		P-TFBGA240-1414	240	1	14 x 14	14.0 x 14.0 x (1.2)
		P-LFBGA280-1616	280	1	40.40	10.0 10.0 (1.5)
		P-LFBGA352-1616	352	1	16 x 16	16.0 x 16.0 x (1.5)
		P-TFBGA064-0606	64		6 x 6	6.0 x 6.0 x (1.2)
		P-LFBGA140-0909	140	1	9 x 9	9.0 x 9.0 x (1.4)
		P-LFBGA160-1010	160	1	10 x 10	10.0 x 10.0 x (1.4) / (1.6)
		P-TFBGA180-1313	180	1	13 x 13	13.0 x 13.0 x (1.2)
		P-LFBGA192-1010	192	0.65	10 x 10	10.0 x 10.0 x (1.4) / (1.6)
		P-LFBGA208-1212	208	1	12 x 12	12.0 x 12.0 x (1.4) / (1.6)
		P-LFBGA224-1313	224	1	40. 40	13.0 x 13.0 x (1.4) / (1.6)
	(Plastic)	P-TFBGA260-1313	260	1	13 x 13	13.0 x 13.0 x (1.2)

^{*} Figures in brackets indicate available terminal counts.

●Surface-mount Type (cont'd)

Package type	Appearance (Package material)	Package code	No. of terminals	Terminal pitch mm	Nominal dimensions mm	Package depth & width (D x W) x (seated height [MAX.]) mn
		P-VFBGA057-0505	57			
		P-VFBGA075-0505	75	1	5 x 5	5.0 x 5.0 x (0.9)
		P-TFBGA064-0606	64	1		
		P-TFBGA068-0606	68	1		6.0 x 6.0 x (1.1)
		P-VFBGA081-0606	81	1	6 x 6	6.0 x 6.0 x (0.9)
		P-TFBGA084-0606	84	1		6.0 x 6.0 x (1.1)
		P-VFBGA100-0606		1		6.0 x 6.0 x (0.9)
		P-VFBGA100-0707	100			7.0 x 7.0 x (0.9)
		P-TFBGA100-0707				7.0 x 7.0 x (1.1)
		P-VFBGA108-0707		1		7.0 x 7.0 x (0.9)
		P-TFBGA108-0707	108		7 x 7	7.0 x 7.0 x (1.1)
		P-VFBGA120-0707	400	1		7.0 x 7.0 x (0.9)
		P-TFBGA120-0707	120			
		P-TFBGA132-0707	132	1		7.0 x 7.0 x (1.1)
		P-TFBGA133-0808	133	1	8 x 8	8.0 x 8.0 x (1.1)
	DW O	P-VFBGA144-0808		1		8.0 x 8.0 x (0.9)
		P-LFBGA144-0808	144	0.5		8.0 x 8.0 x (1.3) / (1.5)
		P-LFBGA144-0811		-	8 x 11	8.0 x 11.0 x (1.3)
FBGA (CSP)		P-TFBGA152-0808	152		8 x 8	8.0 x 8.0 x (1.1)
(001)		P-VFBGA171-0811	474		0 44	8.0 x 11.0 x (0.9)
		P-LFBGA171-0811	171		8 x 11	8.0 x 11.0 x (1.3) / (1.5)
		P-VFBGA176-0909	470	1	9 x 9	9.0 x 9.0 x (0.9)
		P-TFBGA176-0909	176			
		P-TFBGA180-0909	180	1		9.0 x 9.0 x (1.1)
		P-TFBGA188-0909	400	1		
		P-VFBGA188-1111	188		11 x 11	11.0 x 11.0 x (0.9)
		P-VFBGA208-1010	000	1		10.0 x 10.0 x (0.9)
		P-TFBGA208-1010	208		40 40	40.0 40.0 (4.4)
		P-TFBGA245-1010	0.45	1	10 x 10	10.0 x 10.0 x (1.1)
		P-LFBGA245-1010	245			10.0 x 10.0 x (1.3)
		P-FBGA424-1414	424	1	14 x 14	14.0 x 14.0 x (1.8)
		P-WFBGA144-0606	144			6.0 x 6.0 x (0.75)
		P-WFBGA121-0606	121]	6 x 6	60 % 60 (0.0)
		P-WFBGA145-0606	145	1		6.0 x 6.0 x (0.8)
		P-TFBGA168-0707	168	0.4	7 x 7	7.0 x 7.0 x (1.0)
		P-TFBGA204-0808	204	1		8.0 x 8.0 x (1.0)
		P-WFBGA205-0808	205	1	8 x 8	0.0 0.0. (0.0)
	(Plastic)	P-WFBGA261-0808	261	1		8.0 x 8.0 x (0.8)



●Surface-mount Type (cont'd)

Package type	Appearance (Package material)	Package code	No. of terminals	Terminal pitch mm	Nominal dimensions mm	Package depth & width (D x W) x (seated height [MAX.]) mn
		P-TFBGAXXX-0606	to 36		6 x 6	6.0 x 6.0 x (1.2)
	-	P-TFBGAXXX-0707	to 49	1	7 x 7	7.0 x 7.0 x (1.2)
		P-TFBGAXXX-0808	to 81	1	8 x 8	8.0 x 8.0 x (1.2)
		P-TFBGAXXX-0909	to 100	1	9 x 9	9.0 x 9.0 x (1.2)
		P-TFBGAXXX-1010	to 121	1	10 x 10	10.0 x 10.0 x (1.2)
		P-TFBGAXXX-1111	to 144	0.8	11 x 11	11.0 x 11.0 x (1.2)
		P-TFBGAXXX-1212	to 196	-	12 x 12	12.0 x 12.0 x (1.2)
	-	P-TFBGAXXX-1313	to 216		13 x 13	13.0 x 13.0 x (1.2)
		P-TFBGAXXX-1414		1	14 x 14	14.0 x 14.0 x (1.2)
	Ī	P-TFBGAXXX-1515	to 240		15 x 15	15.0 x 15.0 x (1.2)
		P-TFBGAXXX-1616	to 352	1	16 x 16	16.0 x 16.0 x (1.2)
		P-TFBGAXXX-0606	to 49		6 x 6	6.0 x 6.0 x (1.2)
		P-TFBGAXXX-0707	to 81	1	7 x 7	7.0 x 7.0 x (1.2)
		P-TFBGAXXX-0808	to 121	1	8 x 8	8.0 x 8.0 x (1.2)
		P-TFBGAXXX-0909	to 144	1	9 x 9	9.0 x 9.0 x (1.2)
		P-TFBGAXXX-1010	to 196	1	10 x 10	10.0 x 10.0 x (1.2)
		P-TFBGAXXX-1111	to 224	0.65	11 x 11	11.0 x 11.0 x (1.2)
		P-TFBGAXXX-1212	to 256		12 x 12	12.0 x 12.0 x (1.2)
	D.W	P-TFBGAXXX-1313	to 272		13 x 13	13.0 x 13.0 x (1.2)
FBGA (CSP)		P-TFBGAXXX-1414	to 304		14 x 14	14.0 x 14.0 x (1.2)
(CSF)		P-TFBGAXXX-1515	to 320		15 x 15	15.0 x 15.0 x (1.2)
		P-TFBGAXXX-1616	to 352		16 x 16	16.0 x 16.0 x (1.2)
		P-TFBGAXXX-0606	to 100		6 x 6	6.0 x 6.0 x (1.1)
		P-TFBGAXXX-0707	to 132	1	7 x 7	7.0 x 7.0 x (1.1)
		P-TFBGAXXX-0808	to 164	1	8 x 8	8.0 x 8.0 x (1.1)
		P-TFBGAXXX-0909	to 192	1	9 x 9	9.0 x 9.0 x (1.1)
		P-TFBGAXXX-1010	to 216	1	10 x 10	10.0 x 10.0 x (1.1)
		P-TFBGAXXX-1111	to 244	0.5	11 x 11	11.0 x 11.0 x (1.1)
		P-TFBGAXXX-1212	to 268	1	12 x 12	12.0 x 12.0 x (1.1)
		P-TFBGAXXX-1313	to 296	1	13 x 13	13.0 x 13.0 x (1.1)
		P-TFBGAXXX-1414	to 320	1	14 x 14	14.0 x 14.0 x (1.1)
		P-TFBGAXXX-1515	to 348	1	15 x 15	15.0 x 15.0 x (1.1)
		P-TFBGAXXX-1616	to 372	1	16 x 16	16.0 x 16.0 x (1.1)
		P-TFBGAXXX-0505	to 100		5 x 5	5.0 x 5.0 x (1.0)
		P-TFBGAXXX-0606	to 144	1	6 x 6	6.0 x 6.0 x (1.0)
		P-TFBGAXXX-0707	to 168	1	7 x 7	7.0 x 7.0 x (1.0)
		P-TFBGAXXX-0808	to 204	0.4	8 x 8	8.0 x 8.0 x (1.0)
		P-TFBGAXXX-0909	to 228]	9 x 9	9.0 x 9.0 x (1.0)
	(Plastic)	P-TFBGAXXX-1010	to 264	1	10 x 10	10.0 x 10.0 x (1.0)
		P-BGA0356-2121	356	1.0	21 x 21	21.0 x 21.0 x (2.2)
PBGA (BGA)		P-BGA0476-3535	476	-	35 x 35	35.0 x 35.0 x (2.63)
. ,	W (Plastic)	P-BGA0528-3535	528	1.27	00 X 00	55.0 x 55.0 x (2.65)

XXX: Terminal counts

BGA is a trademark of Motorola Nippon Ltd.

●Surface-mount Type (cont'd)

Package	Appearance	Package code	No. of	Terminal pitch	Nominal dimensions	Package depth & width	Lead frame	e material
type	(Package material)	Package code	terminals	mm (mil)	mm (mil)	(seated height [MAX.]) mm	Alloy42	Copper alloy
SSOP	W	P-SSOP008-0150	8	0.65	4.5 (150)	3.0 x 3.0 x (1.1)	_	
3301	D (Plastic)	P-SSOP024-0275	24	0.00	7.0 (275)	6.0 x 7.8 x (1.27)	-	
	W	P-TSOP040-1020	40		10 x 20	10.0 x 18.4 x (1.2)		
TSOP		P-TSOP048-1220	48	0.5	12 x 20	12.0 x 18.4 x (1.2)		
	D (Plastic)	P-TSOP056-1420	56		14 x 20	14.0 x 18.4 x (1.2)		
QFP		P-QFP048-0707	48	0.5	7 x 7	7.0 x 7.0 x (1.65)		
QFF	W	P-QFP072-1010	72	0.5	10 x 10	10.0 x 10.0 x (1.8)		-
LQFP		P-LQFP080-1212	80	0.5	12 x 12	12.0 x 12.0 x (1.7)		-
LQFP		P-LQFP100-1414	100	0.5	14 x 14	14.0 x 14.0 x (1.7)]	_
	D (Plastic)	P-TQFP048-0707	48	0.5	7 x 7	7.0 x 7.0 x (1.2)		_
TQFP		P-TQFP100-1414	100		14 x 14	14.0 x 14.0 x (1.2)	1	_
		P-TQFP128-1414	128	0.4	14 X 14	14.0 X 14.0 X (1.2)		-
		P-VQFN020-0404	20		4 x 4	4.2 x 4.2 x (1.0)	_	
		P-VQFN024-0404	24		4 X 4	4.2 x 4.2 x (1.0)	_	
		P-VQFN028-0505	28	0.5	5 x 5	5.2 x 5.2 x (1.0)	-	
VQFN		P-VQFN032-0505	32	0.5	5 X 5	5.2 x 5.2 x (1.0)		
VQFN	W	P-VQFN036-0606	36		6 x 6	6.2 x 6.2 x (1.0)	-	
	34556	P-VQFN048-0707	48]	7 x 7	7.2 x 7.2 x (1.0)	_	
	7127	P-VQFN036-0505	36	0.4	5 x 5	5.2 x 5.2 x (1.0)		
	D	P-VQFN052-0707	52	0.4	7 x 7	7.2 x 7.2 x (1.0)	-	
		P-HQFN020-0404	20			4.0 x 4.0 x (1.0)		
		P-HQFN024-0404	24	0.5	4 x 4	4.0 x 4.0 x (0.85)		
HQFN*		F-HQFN024-0404	24	0.5		4.2 x 4.2 x (1.0)		
		P-HQFN028-0505	28		5 x 5	5.0 x 5.0 x (1.0)	-	
	(Plastic)	P-HQFN052-0707	52	0.4	7 x 7	7.2 x 7.2 x (1.0)		

^{*} HQFN is a higher heat dissipation package of VQFN.

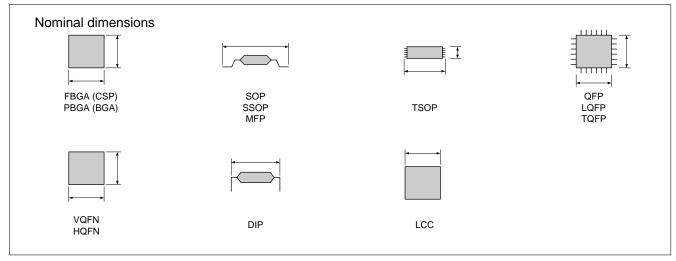
100 mil = 2.54 mm



●For CCDs

Package type	Appearance (Package material)	Package code	No. of terminals	Terminal pitch mm	Nominal dimensions mm (mil)	Package depth & width (D x W) x (seated height [TYP.]) mm
	W	P-DIP014-0400A	14	1.27	10.16 (400)	10.0 x 10.0
DIP		P-DIP016-0450	46	1.27	11.43 (450)	11.4 x 12.2
	(Plastic)	P-DIP016-0500C	16	1.78	12.7 (500)	12.4 x 14.0
	D (Plastic)	P-SOP014-0400A	14	1.27	12 (470)	10.0 x 10.0 x (4.1)
SOP		P-SOP028-0400	28	0.69	10.16 (400)	10.0 x 10.0 x (3.5)
		P-SOP032-0525	32	0.78	13.3 (525)	12.0 x 13.8 x (3.92)
100	W	N-LCC040-R350	40	0.65	8.9	8.3 x 8.9 x (1.52)
LCC	D (Ceramic)	N-LCC040-S433A	40	0.80	11.0	11.0 x 11.0 x (1.62)

100 mil = 2.54 mm



FBGA : fine-pitch ball grid array package QFP : quad flat package

LQFP: low profile quad flat package PBGA : plastic ball grid array package SOP : small outline package TQFP: thin quad flat package

SSOP : shrink small outline package VQFN: very thin quad flat non-leaded package

HQFN: heat sink quad flat non-leaded package MFP : mini flat package **TSOP** : dual inline package : thin small outline package

LCC : leadless chip carrier

Ball Grid Array and BGA are trademarks of Motorola Nippon Ltd.





●Lead-inserting Type Packages [For regulators: PQ series]

Package type	Appearance (Package material)	No. of terminals	Terminal pitch mm	Outline dimensions (Width x Thickness x Height) mm	Lead frame material
TO-220	A (Plastic)	4	2.54	10.2 (MAX.) x 4.5 x 29.1* ²	Cu
TO-220 (Full mold)	B (Plastic)	4	2.54	10.2 (MAX.) x 4.5 x 29.1* ²	Cu
TO-220 (Full mold) [Lead forming type]	C (Plastic)	5	(1.7)*1	10.2 (MAX.) x 4.5 x 24.6* ²	Cu
TO-220 [Lead forming type]	D (Plastic)	5	(1.7)*1	10.2 (MAX.) x 4.5 x 24.6* ²	Cu
TO-220 [Lead forming type]	E (Plastic)	5	(1.7)*1	10.2 (MAX.) x 4.5 x 24.6* ²	Cu

^{*1} The figure in parentheses indicates reference value.

● Surface-mount Type Packages [For regulators/LED drivers: PQ series]

Package type	Appearance (Package material)	No. of terminals	Terminal pitch mm	Outline dimensions (Width x Height x Thickness) mm	Lead frame material
TO-263	(Plastic)	5 (Heat sink not included)	(1.7)* ¹	10.6 (MAX). x 13.7 (MAX.)*2 x 3.5	Cu
SC-63	(Plastic)	5 (Heat sink not included)	(1.27)*1	6.6 (MAX.) x 9.7 (MAX.)* ² x 2.3	Cu
SC-63	(Plastic)	5 (Heat sink included)	(1.27)*1	6.6 (MAX.) x 9.7 (MAX.)*2 x 2.1	Cu
SOP-8	(Plastic)	8	1.27	5 x 6.2*2 x 1.55*2	Cu
SOT-89	(Plastic)	6	1.5	4.5 x 4.3*² x 1.5	Cu

^{*1} The figure in parentheses indicates reference value.

^{*2} Including lead length

^{*2} Including lead length





● Surface-mount Type Packages [For regulators/LED drivers: PQ series] (cont'd)

Package type	Appearance (Package material)	No. of terminals	Terminal pitch mm	Outline dimensions (Width x Height x Thickness) mm	Lead frame material
SOT-23-6	(Plastic)	6	0.95	2.9 x 2.8* ² x 1.3	Cu
SOT-23-6W	(Plastic)	6	0.95	2.9 x 2.8* ² x 1.3	Cu
SOT-23-L	(Plastic)	6	(0.95)*1	(3.4)*1 x 3.3*2 x 1.4 (MAX.)	Cu
SOT-23-5	(Plastic)	5	(0.95)*1	(2.9)* ¹ x 2.8* ² x 1.3 (MAX.)	Cu
USB-6		6	0.5	2.0 x 1.8 x 0.8	Cu (Terminal material)/ Au plating (Terminal finish)
USB-8	The state of the s	9 (Including radiating fin)	1.0	5.0 x 4.5 x 0.75 (MAX.)	Cu

^{*1} The figure in parentheses indicates reference value.
*2 Including lead length

In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc. Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.





■ Photocoupler Lineup

<Phototransistor output type>

Package type	Output type	Features		Model No. (series)	Page
Mini-flat 4-pin Compact, SMT type	Single phototransistor	General purpose, High collector-emitter voltage, etc.		PC35x series/PC451J00000F	44
			Low input current	PC367NJ0000F	44
•		AC input response		PC354NJ0000F	44
		High sensitivity,	Low input current	PC364NJ0000F	44
	Darlington phototransistor	High collector-emitter voltage		PC355NJ0000F/PC452J00000F	44
		-	Low input current	PC365NJ0000F	44
Compact, Half pitch (lead space), SMT type	Single phototransistor	General purpose, High resistance to noise, etc.		PC3Hx series	45
			Reinforced insulation	PC3HU7xYIP0B	45
***			Low input current	PC3H71xNIP0F	45
		AC input response		PC3H3J00000F/PC3H4J00000F	45
			Low input current	PC3H41xNIP0F	45
	Darlington phototransistor	High sensitivity		PC3H5J00000F	45
			Low input current	PC3H510NIP0F	45
DIP type (4-pin)	Single phototransistor	Reinforced insulation		PC123XNNSZ0F	46
(4-pin, DIP type)		General purpose,	Low input current	PC1231xNSZ0X	46
_		High collector-emitter voltage, etc.		PC817XNNSZ0F/PC851XNNSZ0F	46
			Low input current	PC8171xNSZ0X	46
//	Darlington phototransistor	High sensitivity, High collector-emitter voltage		PC815XNNSZ0F/PC852XNNSZ0F/ PC853XNNSZ0F	46
			Low input current	PC81510NSZ0X	46
DIP type (6-pin)	Single phototransistor	General purpose, High collector-emitter voltage, etc.		PC7xxV0NSZXF	47
	Darlington phototransistor	High sensitivity, High collector-emitter voltage, etc.		PC7x5V0NSZXF	47

<OPIC output type>

Package type Output type		Features	Model No. (series)	Page
Compact, SMT type	Digital output	General purpose, High response speed, 2ch, etc.	PC400J00000F/PC456L0NIP0F/ PC410S0NIP0F/PC410L0NIP0F/ PC4D10SNIP0F	48
	Analog/Digital output	High CMR	PC457S0NIP0F/PC457L0NIP0F	48
DIP type, SMT type	Digital output	General purpose	PC900V0NSZXF	49
	Built-in base amplifier	For inverter control, Built-in short-circuit protection circuit	PC925LxNSZ0F/PC942J00000F/ PC928J00000F/PC929J00000F	49





■ Photocouplers

♦Phototransistor Output Type <Compact, SMT type>

O: Approved $(Ta = 25^{\circ}C)$ Approved Absolute maximum ratings Electro-optical characteristics by safety Isolation Current transfer ratio Response time Output type Collector Internal standards*2 voltage Forward emitter Model No. connection **Features** Package current (AC) voltage VCF diagram VCE lc Viso (%) (µs) TYP. UL VCEO (mA) (V) (mA) (Ω) (V) (mA) (rms) MIŃ. (V) (kV) O* PC357NJ0000F 5 5 2 2 General purpose 50 3.75 80 50 4 100 General purpose, PC352NJ0000F \bigcirc 50 3.75 80 90 5 5 4 2 100 2 Single phototransistor output high resistance to noise*1 High collector-emitter PC451J00000F O* 50 3.75 350 40 5 5 4 2 100 2 voltage Low input current, PC367NJ0000F 0 10 3.75 80 100 0.5 5 4 2 100 2 high resistance to noise*1 0* PC354NJ0000F 2 2 AC input response Mini-flat ±50 3.75 80 20 ±1 5 4 100 4-pin Low input current, PC364NJ0000F 2 2 AC input response, \bigcirc ±10 3.75 70 50 ±0.5 5 4 100 high resistance to noise*1 PC355NJ0000F O* 50 3.75 600 2 100 2 High sensitivity 35 1 2 60 Darlington photo-transistor output High sensitivity, PC365NJ0000F \bigcirc 10 3.75 35 600 0.5 2 60 2 100 2 low input current

PC452J00000F

High collector-emitter

A VDE approved type is optionally available.



0*

50

3.75

350

1 000

1 2 100 20 100 2

^{*1} CMR: MIN.10 kV/µs

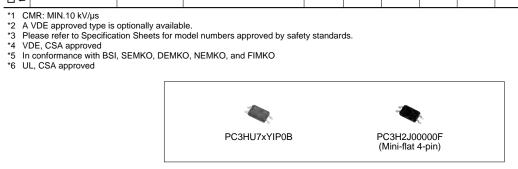
Please refer to Specification Sheets for model numbers approved by safety standards.





♦Phototransistor Output Type

<0	Compact, half	pitch (lead	space) SMT type>		- O: Appr	oved							(T	ā = 25	5°C)
: type		Internal		Approved by safety standards*3		Forward		n ratings Collector- emitter	_	Electro ent trai ratio				stics se time	e e
Output type	Model No.	connection diagram	Features	UL	Package	current IF (mA)	Viso (rms) (kV)	voltage VCEO (V)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)		VCE (V)
	PC3HU7xYIP0B		Reinforced insulation (internal insulation distance: MIN. 0.4 mm), low-profile package	○*4 , 5	Low- profile mini-flat 4-pin	50	3.75	80	50	5	5	4	2	100	2
ansistor output	PC3H2J00000F		High resistance to noise*1	0		50	2.5	80	20	1	5	4	2	100	2
	PC3H7J00000F		Standard	○*6		50	2.5	80	20	1	5	4	2	100	2
	PC3H71xNIP0F		High resistance to noise*1, low input current	0	Mini-flat	10	2.5	80	100	0.5	5	4	2	100	2
Single pł	PC3H3J00000F		AC input response, high resistance to noise*1	0	4-pin	±50	2.5	80	20	±1	5	4	2	100	2
	PC3H4J00000F	\frac{1}{2}	AC input response	<u></u> *2, 6		±50	2.5	80	20	±1	5	4	2	100	2
	PC3H41xNIP0F		AC input response, high resistance to noise*1, low input current	0		±10	2.5	80	50	±0.5	5	4	2	100	2
Darlington photo- transistor output	PC3H5J00000F		High sensitivity	0	Mini-flat	50	2.5	35	600	1	2	60	2	100	2
	PC3H510NIP0F	<u> </u>	High sensitivity, low input current	4-pin	10	2.5	35	600	0.5	2	60	2	100	2	









♦Phototransistor Output Type <DIP type (4-pin)>

- ○: Approved

(Ta = 25°C)

-				Aŗ	prove	d by		Absolu	te maximu	m ratings	Electro-	optical ch	aracter	istics
type		Internal		safet	y stan	dards*8		Forward	Isolation		Current tra	nsfer ratio	Respons	se time
Output type	Model No.	connection diagram	Features	UL	VDE *2	Others *3	Package	current IF (mA)	voltage (AC) Viso (rms) (kV)	emitter voltage VCEO (V)	CTR (%) MIN.	IF (mA)	tr (µs) TYP.	RL (Ω)
Ħ	PC123XNNSZ0F*1, *5, *6, *7		High isolation voltage, reinforced insulation	0	0	0		50	5.0	70	50	5	4	100
Single phototransistor output	PC1231xNSZ0X*1	*	High isolation voltage, reinforced insulation, low input current, high resistance to noise*4	0	0	0		10	5.0	70	50	0.5	4	100
ototransis	PC817XNNSZ0F*5, *6, *7		High isolation voltage	0	1	○*9		50	5.0	80	50	5	4	100
ingle pho	PC8171xNSZ0X*5, *6		High isolation voltage, low input current, high resistance to noise*4	0	ı	_		10	5.0	80	100	0.5	4	100
0)	PC851XNNSZ0F*5, *6	₩	High isolation voltage, high collector-emitter voltage	0	1	_	4-pin DIP	50	5.0	350	40	5	4	100
r output	PC815XNNSZ0F*5, *6		High isolation voltage, high sensitivity	0	ı	ı	5"	50	5.0	35	600	1	60	100
Darlington phototransistor output	PC81510NSZ0X		High isolation voltage, high sensitivity, low input current	0	ı	_		10	5.0	35	600	0.5	60	100
ngton pho	PC852XNNSZ0F*5, *6		High isolation voltage, high collector-emitter voltage	0	0	_		50	5.0	350	1 000	1	100	100
Darlii	PC853XNNSZ0F*5, *6	Д	High isolation voltage, high collector-emitter voltage	0	0	_		50	5.0	350	1 000	1	100	100

- *1 Wide lead spacing type is also available. Creepage distance: 6.4 mm or more, wide lead spacing type: 8 mm or more.

 *2 Optionally available.

 *3 BSI, SEMKO, DEMKO, NEMKO, FIMKO, CSA

 *4 CMR: 10 kV/µs MIN.

 *5 Lead forming type is also available for surface mounting.

 *6 Taped package of lead forming type for surface mounting is also available.

 *7 Wide lead spacing type is also available. Compatible with wide lead spacing type lead-forming models for surface-mount use. Also compatible with taped packages for wide lead spacing type lead-forming models for surface-mount use.

 *8 Please refer to Specification Sheets for model numbers approved by safety standards.

 *9 UII CSA approved
- *9 UL, CSA approved







♦Phototransistor Output Type <DIP type (6-pin)>

· ○: Approved, △: Under application

 $(Ta = 25^{\circ}C)$

Output type					oved		Absolu	te maximun	n ratings	Electro	-optical o	haracte	ristics
ut type	Model No.	Internal connection	Features		afety ards* ²	Package	Forward current	Isolation voltage	Collector- emitter	Current ra		Resp tin	
Outpr	Woder No.	diagram	i dataros	UL	VDE*1	Tackage	IF (mA)	(AC) Viso (rms) (kV)	voltage VCEO (V)	CTR (%) MIN.	IF (mA)	tr (µs) TYP.	RL (Ω)
or output	PC714V0NSZXF		High isolation voltage	0	0		50	5.0	80	50	5	4	100
le photot	PC724V0NSZXF		High isolation voltage, large input current	0	_		150	5.0	35	20	100	4	100
-	PC713V0NSZXF	₩ N	High isolation voltage, with base terminal	0	0		50	5.0	80	50	5	4	100
Darlington phototransistor output	PC715V0NSZXF	<u> </u>	High isolation voltage, high sensitivity	0	0	6-pin DIP	50	5.0	35	600	1	60	100
Darlington photo	PC725V0NSZXF		High isolation voltage, high sensitivity, high collector-emitter voltage, high power	0	0		50	5.0	300	1 000	1	100	100

 ^{*1} Optionally available.
 *2 Please refer to Specification Sheets for model numbers approved by safety standards.









♦ OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

<Compact, SMT type> (1-1) O: Approved $(Ta = 25^{\circ}C)$ Absolute maximum Approved by Electro-optical characteristics*1 ratings safety standards*2 Internal Isolation Low level output voltage Threshold input current Forward Model No. connection **Features** Package voltage (AC) current Vol **I**FLH **IFHL** diagram IOL VDE*3 (V) MAX UL (mA) (mA) /iso (rms) (°C) (mA) (mA) (Ω) (mA) ŇΑΧ. ŇΑΧ. (kV) Digital output, PC400J00000F 0 50 3.75 0.4 0 to +7016 4 2.0 280 normal-off operation Built-in preamplifier, high speed transmission Mini-flat PC456L0NIP0F 0 0 25 3.75 0.6 -40 to +85 2.4 10 5.0 20 k (2 Mb/s), 5-pin for flow soldering High speed (10 Mb/s), High CMR (10 kV/µs), PC410L0NIP0F 0 0 20 3.75 13 5 350 0.6 -40 to +85 5.0 For flow soldering High speed (10 Mb/s), high CMR (10 kV/µs), SOP PC410S0NIP0F 0 for flow soldering, \bigcirc 20 3.75 5 5.0 350 0.6 -40 to +85 13 8-pin Solder heat resistance: 270°C High speed (10 Mb/s), for flow soldering, SOP *=65< PC4D10SNIP0F Solder heat resistance: \circ 20 3.75 0.6 -40 to +85 13 5 5.0 350 8-pin 270°C 2ch output

A: Rated voltage circuit

- *1 Each item is measured at Vcc=5V. (PC400)
- *2 Please refer to Specification Sheets for model numbers approved by safety standards.
- *3 Optionally available.

<compact,< th=""><th>SMT type</th><th>> (1-2)</th><th></th><th>ГС</th><th>: Approve</th><th>ed</th><th></th><th></th><th></th><th></th><th></th><th></th><th></th><th>(Ta =</th><th>= 25°C)</th></compact,<>	SMT type	> (1-2)		ГС	: Approve	ed								(Ta =	= 25°C)
			sa	ved by fety			maximum ings			Electr	o-optic	al chara	cteristic	cs	
	Internal		stand	ards*1		Forward	Isolation	Cur	rent tra	ansfer i	atio	Pro	pagation	n delay	time
Model No.	connection diagram	Features	UL	VDE*2	Package	current IF (mA)	voltage (AC) Viso (rms) (kV)	CTR (%) MIN.	IF (mA)	Vo (V)	Vcc (V)	tPHL (µs) TYP.	tplh (µs) TYP.	RL (Ω)	IF (mA)
PC457L0NIP0F		High speed (1 Mb/s), high CMR (15 kV/µs), for flow soldering	0	0	Mini-flat 5-pin	25	3.75	19	16	0.4	4.5	0.2	0.4	1 900	16
PC457S0NIP0F		High speed (1 Mb/s), high CMR (15 kV/µs), for flow soldering, Solder heat resistance: 270°C	0	0	SOP 8-pin	25	3.75	19	16	0.4	4.5	0.2	0.3	1 900	16

- Please refer to Specification Sheets for model numbers approved by safety standards.
- *2 Optionally available.







♦ OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

<dip digital="" output="" type,=""></dip>				\Box	: Approve	ed		(Ta = 25°C)						25°C)
			Appro saf				olute n ratings		Electro-	optical	charac	teristics	*1	
Model No.	Internal connection	Features	stand		Package	Forward	Isolation voltage	Lo	w level outp	ut volta	ge		shold in	iput
	diagram		UL	VDE *4		IE.	Viso (rms) (kV)	VOL (V) MAX.	Ta (°C)	IoL (mA)	IF (mA)	IFHL (mA) MAX.	IFLH (mA) MAX.	RL (Ω)
PC900V0NSZXF*2, *3	A S	Digital output, normal-off operation	0	0	6-pin DIP	50	5.0	0.4	0 to +70	16	4	2.0	-	280

- A: Rated voltage circuit
 *1 Each item is measured at Vcc=5V.
- Lead forming type is also available for surface mounting.
- Taped package of lead forming type for surface mounting is also available.
- Optionally available.
- *5 Please refer to Specification Sheets for model numbers approved by safety standards.



♦ OPIC Output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

<DIP type, Gate drive type>

C: Approved

(Ta = 25°C)

71 7												(1α –	- 23 0)
			sat	ved by ety			olute m ratings		Electro	-optical	charact	eristics	
	Internal		stand	ards*3		F	Isolation		Pro	pagation	n delay t	time	
Model No.	connection diagram	Features	UL	VDE *2	Package	Forward current IF (mA)	voltage (AC) Viso (rms) (kV)	tphL (µs) TYP.	tPLH (µs) TYP.	Vcc (V)	IF (mA)	teristics	RL2 (Ω)
PC925LxNSZ0F*1		Built-in drive circuit directly connectable to MOS-FET and IGBT Peak output current: 2.5 A Low dissipation current (Icc = TYP. 2.5 mA) High resistance to noise (CMR: MIN. 15 kV/µs)	0	0	8-pin DIP	25	5.0	MAX. 0.5	MAX. 0.5	15 to 30	7 to 16		-
PC942J00000F	Interface Amplifier	For controlling inverter- controlled air-conditioner	0	0		25	5.0	2.0	2.0	6	5	5	10
PC928J00000F	Interface Amplifier	For driving inverter IGBT, built-in short protection circuit	0	0	14-pin SMT (Half pitch	25	4.0	1.0	1.0	24	10		-
PC929J00000F	Interface Amplifier	For driving inverter IGBT, high speed, built-in short protection circuit	0	0	lead)	20	4.0	0.3	0.3	24	5		-

- Lead forming type is also available for surface mounting. Taped package of lead forming type for surface mounting is also available.





PHOTOTRIAC COUPLER LINEUP



■ Phototriac Coupler Lineup

Package	Applied voltage	ON-state current (rms)		Features	Model No.	Page
Mini-flat (SMD)	AC 200 V lines (VDRM = 600V)	0.05 A	General purpose		S2S3000F*3 / S2S5A00F*3	51
				Built-in zero-cross circuit	S2S4000F*3	52
DIP type	AC 200 V lines (VDRM = 600V)	0.1 A	General purpose		PC3ST11NSZAX* ³	51
(4-pin)				Built-in zero-cross circuit	PC3ST21NSZBX*2	52
			Reinforced isolation	on	PC3SH11YFZAX*3 / PC3SH13YFZAX*3	51
()				Built-in zero-cross circuit	PC3SH21YFZBX*2	52
DIP type	AC 100 V lines (VDRM = 400V)	0.1 A	General purpose		PC2SD11NTZAF*3	51
(6-pin package, 5th-pin cut)	AC 200 V lines (VDRM = 600V)	0.1 A	General purpose		PC3SD12NTZAF*3 / PC3SD12NTZBF*2 / PC3SD11NTZCF*1	51
				Built-in zero-cross circuit	PC3SD21NTZAF*3 / PC3SD21NTZBF*2 / PC3SD21NTZDF / PC3SD21NTZDF / PC3SD23YTZCF*1	52
1 1.			Reinforced isolation	on	PC3SF11YVZAF*3 / PC3SF11YVZBF*2 / PC3SF13YVZBF*2	51
				Built-in zero-cross circuit	PC3SF21YVZAF*3 / PC3SF21YVZBF*2	52
	AC 200 V lines (VDRM = 800V)	0.1 A	General purpose		PC4SD11NTZBF*2 / PC4SD11NTZCF*1	51
				Built-in zero-cross circuit	PC4SD21NTZCF*1 / PC4SD21NTZDF	52
			Reinforced isolation	on T	PC4SF11YVZAF*3 / PC4SF11YVZBF*2	51
				Built-in zero-cross circuit	PC4SF21YVZBF*2 / PC4SF21YVZCF*1	52

Minimum trigger current: *1 IFT \leq 5 mA, *2 IFT \leq 7 mA, *3 IFT \leq 10 mA

7



PHOTOTRIAC COUPLERS



Phototriac			Ap	oproved v standa	- ○: Ap by	piorea	Absolu	te maximum	n ratings	(Ta = 25°C) Electro-optical characteristic
Model No.	Internal connection diagram	Features	UL, CSA	VDE	Others	Package	ON-state current IT (rms) (A)	Repetitive peak OFF-state voltage VDRM (V)	Isolation voltage (AC) Viso (rms) (kV)	Min. trigger current IFT
S2S3000F		200 V lines, compact	0	○*6	-	Mini-flat	0.05	600	3.75	10
S2S5A00F		200 V lines, compact	0	○*6	_	4-pin	0.05	600	3.75	10
PC3ST11NSZAX		200 V lines, compact	0	○*6	-					10
PC3SH11YFZAX		200 V lines, compact, reinforced isolation	0	0	O*2	4-pin DIP	0.1	600	5.0	10
PC3SH13YFZAX		200 V lines, compact, reinforced isolation, high noise resistance	0	0	O*2	DIP				10
PC2SD11NTZAF*7		100 V lines	0	-	-			400		10
PC3SD12NTZAF*8		200 V lines	0	○*6	-			000		10
PC3SD12NTZBF		200 V lines	0	O*6	-			600		7
PC4SD11NTZBF		200 V lines, repetitive peak-OFF-state voltage	0	O*6	-			800	-	7
PC3SD11NTZCF		200 V lines	0	O*6	-			600		5
PC4SD11NTZCF		200 V lines, repetitive peak-OFF-state voltage	0	○*6	-	6-pin DIP* ^{1, 3}	0.1	800	5.0	5
PC3SF11YVZAF		200 V lines, reinforced isolation	0	0	O*2					10
PC3SF11YVZBF		200 V lines, reinforced isolation	0	0	O*2			600		7
PC3SF13YVZBF		200 V lines, reinforced isolation, high noise resistance	0	0	O*2					7
PC4SF11YVZAF		200 V lines, reinforced isolation, repetitive peak-OFF-state voltage	0	0	O*2			000		10
		200 V lines, reinforced isolation.			0.40			800		_

0

0

O*2

For the notes *1 to *9, see next page.

PC4SF11YVZBF

200 V lines, reinforced isolation, repetitive peak-OFF-state voltage



PHOTOTRIAC COUPLERS



■ Phototriac Couplers

(Built-in zero-cross circuit type) O: Approved $(Ta = 25^{\circ}C)$ Approved by safety standards*4 Electro-optical Absolute maximum ratings characteristics Min. trigger Internal Repetitive Isolation current ON-state Package Model No. connection dia-Features peak voltage UL current IFT gram VDE Others OFF-state (AC) (mA) MAX. CSÁ IT (rms) VDRM Viso (rms) VD = 4 V(A) (V) (kV) $RL = 100\Omega$ Mini-flat S2S4000F 200 V lines, compact ○*6 0.05 600 3.75 10*5 4-pin PC3ST21NSZBX 200 V lines, compact 0 ○*6 7 4-pin DIP 600 5.0 0.1 200 V lines, compact, O*2 PC3SH21YFZBX 0 \circ 7 reinforced isolation 200 V lines. PC3SD21NTZAF 0 ○*6 10 low zero-cross voltage: MAX. 20 V 200 V lines. PC3SD21NTZBF 0 O*6 7 low zero-cross voltage: MAX. 20 V 200 V lines. O*6 PC3SD21NTZCF*9 0 5 low zero-cross voltage: MAX. 20 V 600 200 V lines. PC3SD23YTZCF 0 0 high pulse/noise resistance 5 (TYP. 2 kV) 200 V lines, PC3SD21NTZDF ○*6 3 low zero-cross voltage: MAX. 20 V 6-pin DIP*1, 3 200 V lines 0.1 5.0 PC4SD21NTZCF 0 ○*6 5 repetitive peak-OFF-state voltage 800 200 V lines PC4SD21NTZDF 0 ○*6 3 repetitive peak-OFF-state voltage PC3SF21YVZAF 200 V lines, reinforced isolation 0 0 ○*2 10 600 PC3SF21YVZBF 200 V lines, reinforced isolation 0 0 O*2 7 200 V lines, reinforced isolation, PC4SF21YVZBF 0 \circ O*2 7 repetitive peak-OFF-state voltage 800 200 V lines, reinforced isolation, repetitive peak-OFF-state voltage

- Lead forming type for surface mounting is also available.
- In conformance with BSI, SEMKO, DEMKO, and FIMKO
- These are molded pin No. 5.
- Please refer to Specification Sheets for model numbers approved by safety standards.
- VD = 6 V, $RL = 100\Omega$
- Optionally available

PC4SF21YVZCF

- An equivalent model (IFT MAX.: 15 mA) with overseas brand compatibility is also available. (PC1S3021NTZF)
- An equivalent model with overseas brand compatibility is also available. (PC1S3052NTZF)
- An equivalent model with overseas brand compatibility is also available. (PC1S3063NTZF)



S2S3000F (Mini-flat 4-pin)



PC2SD series (PC3SD series, PC4SD series) (6-pin DIP)



0

○*2

C3SF series C4SF series) (6-pin DIP)



PC3ST series (4-pin DIP)



5

PC3SH series (4-pin DIP)



SOLID STATE RELAY LINEUP



■ Solid State Relay Lineup

Package	Applied voltage	ON-state current (rms)	Features	Model No.	Page
DIP 6-pin	AC 100 V lines	0.06 A	General purpose	PR22MA11NTZF	54
	AC 200 V lines	0.15 A	General purpose	PR31MA11NTZF / PR32MA11NTZF	54
DIP 8-pin	AC 100 V lines	0.3/0.6/0.9 A	General purpose	PR23MF11NSZF / PR26MF series / PR29MF series	54
		0.6/0.9 A	Built-in zero-cross circuit	PR26MF21NSZF / PR29MF21NSZF	54
, 41,	AC 200 V lines	0.3/0.6/0.9/1.2 A	General purpose	PR33MF51NSZF / PR36MF series / PR39MF series / PR3BMF51NSKF	54
		0.6/0.9/1.2 A	Built-in zero-cross circuit	PR36MF2 series / PR39MF2 series / PR3BMF21NSZF	54
SIP 4-pin	AC 100 V lines	2/8 A 3 to 16 A	General purpose	\$102T01F*1 / \$108T01F*1 / \$101\$05F / \$102\$01F / \$112\$01F / \$116\$01F	55
		2/8 A 3 to 16 A	Built-in zero-cross circuit	\$102T02F*1 / \$108T02F*1 / \$101\$06F / \$102\$02F / \$116\$02F	55
Low profile		8 A	Built-in snubber circuit	S102S11F	55
Zow promo		3/8 A	Built-in snubber circuit/ zero-cross circuit	S101S16F / S102S12F	55
	AC 200 V lines		General purpose	\$202T01F*1 / \$208T01F*1 / \$202\$01F / \$212\$01F / \$216\$01F	55
11/		2/8 A 3 to 16 A	Built-in zero-cross circuit	\$202T02F*1 / \$208T02F*1 / \$201\$06F / \$202\$02F / \$216\$02F	55/56
		8/8 A	Built-in snubber circuit	S202S15F / S202S11F	56
		8 A	Built-in snubber circuit/ zero-cross circuit	S202S12F	56

^{*1} Low profile







■ Solid State Relays

<DIP type> — ○: Approved $(Ta = 25^{\circ}C)$ Approved by Electrical Absolute maximum ratings safety standards*1 characteristics Min. trigger Internal Repetitive Isolation ON-state current Model No. connection Features Package peak OFF-state voltage current diagram VDE*2 UI CSA (AC) (mA) MAX. IT (rms) voltage /iso (rms) (A) VD = 6 VVDRM (V) (kV) $RL = 100\Omega$ 0 PR31MA11NTZF 200 V lines, compact \bigcirc 0 0.06 10 600 -13 100 V lines, 6-pin PR22MA11NTZF 0 \bigcirc 0 400 5.0 10 150 mA model in a small package DIP 0.15 200 V lines, PR32MA11NTZF \bigcirc \bigcirc 0 600 10 150 mA model in a small package PR23MF11NSZF 0 100 V lines, compact 0 400 10 0.3 PR33MF51NSZF 0 \bigcirc 0 200 V lines, compact 600 10 PR26MF11NSZF 100 V lines, compact \bigcirc \bigcirc 10 0.6 100 V lines, compact, 0 PR26MF12NSZF 0 5 low input current 400 PR29MF11NSZF 100 V lines, compact 0 \bigcirc 10 0.9 100 V lines, compact, 0 PR29MF12NSZF \bigcirc 5 low input current PR36MF51NSZF 0 200 V lines, compact 0 0 10 0.6 200 V lines, compact, PR36MF12NSZF 0 0 0 5 low input current 200 V lines, compact, PR39MF12NSZF 0 \bigcirc 0 600 5 low input current 8-pin DIP 0.9 4.0 PR39MF51NSZF 200 V lines, compact 0 \bigcirc 0 10 PR3BMF51NSKF 200 V lines, compact \bigcirc \bigcirc \bigcirc 1.2 10 100 V lines, compact PR26MF21NSZF 0 \bigcirc 0.6 10 (built-in zero-cross circuit) 400 100 V lines, compact PR29MF21NSZF 0 \circ 0.9 10 (built-in zero-cross circuit) 200 V lines, compact (built-in zero-PR36MF22NSZF 0 \bigcirc \bigcirc 0.6 5 cross circuit), low input current 200 V lines, compact (built-in zero-PR39MF22NSZF 0 0 0 0.9 5 cross circuit), low input current 200 V lines, compact (built-in zero-PR36MF21NSZF 0 0 0 0.6 600 10 cross circuit) 200 V lines, compact (built-in zero-PR39MF21NSZF \bigcirc \bigcirc 0 0.9 10 cross circuit) 200 V lines, compact (built-in zero-PR3BMF21NSZF 0 \bigcirc 0 1.2 10 cross circuit)

^{*2} Optionally available.



Please refer to Specification Sheets for model numbers approved by safety standards.



<SIP type> (1) (Ta = 25°C)

von typor	(')			O. 7	ippioved,	A. Onder	application			(1a =	23 ()
			Appro safety sta	ved by andards*6		Absolut	e maximum	ratings		lectrica racteris	
Model No.	Internal connection diagram	Features	UL	CSA	Package	ON-state current IT (rms) (A)	Repetitive peak OFF-state voltage VDRM(V)	voltage	Min. tr IFT (mA) MAX.	VD (V)	RL (Ω)
S102T01F		100 V lines, low profile	0	0		2			8	12	30
S108T01F		100 V lines, low profile	_	_	Low profile	8*2			8	12	30
S102T02F	Zero-	100 V lines, low profile (built-in zero-cross circuit)	0	0	4-pin SIP	2		3.0	8	12	30
S108T02F	Zero- cross circuit	100 V lines, low profile (built-in zero-cross circuit)	_	_		8*2			8	12	30
S101S05F		100 V lines	0	0		3*3			15	12	30
S102S01F		100 V lines	0	0		8*2			8	12	30
S112S01F		100 V lines	0	0		12*4		4.0	8	12	30
S116S01F		100 V lines	0	0		16* ⁵	400		8	12	30
S101S06F		100 V lines (built-in zero-cross circuit)	0	0		3*3		3.0	15	6	30
S102S02F	Zero-	100 V lines (built-in zero-cross circuit)	0	0	4-pin SIP	8*2			8	6	30
S116S02F	circuit	100 V lines (built-in zero-cross circuit)	0	0		16* ⁵		4.0	8	6	30
S102S11F	***	100 V lines (built-in snubber circuit)	0	0		8*1		1.0	8	12	30
S101S16F		100 V lines (built-in snubber circuit, built-in zero-cross circuit)	0	0		3*3		3.0	15	6	30
S102S12F	Zero- cross circuit	100 V lines (built-in snubber circuit, built-in zero-cross circuit)	0	0		8*1		4.0	8	6	30
S202T01F		200 V lines, low profile	0	0		2			8	12	30
S208T01F		200 V lines, low profile	_	_	Low profile	8*2		2.0	8	12	30
S202T02F		200 V lines, low profile (built-in zero-cross circuit)	0	0	4-pin SIP	2		3.0	8	12	30
S208T02F	Zero- cross circuit	200 V lines, low profile (built-in zero-cross circuit)	_	_		8*2	600		8	12	30
S202S01F		200 V lines	0	0		8*2			8	12	30
S212S01F		200 V lines	_	_	4-pin SIP	12*4		4.0	8	12	30
S216S01F		200 V lines	_	_		16* ⁵			8	12	30

For the notes *1 to *6, see next page.

Notice
In the absence of confirmation by device specification sheets, SHARP takes no responsibility for any defects that may occur in equipment using any SHARP devices shown in catalogs, data books, etc.

Except where specially indicated, models listed on this page comply with the RoHS Directive*. For details, please contact SHARP.

*RoHS Directive: Prohibits use of lead, cadmium, hexavalent chromium, mercury and specific brominated flame retardants

(PBBs and PBDEs), with certain exceptions.

Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.



SOLID STATE RELAYS



<SIP type> (2)

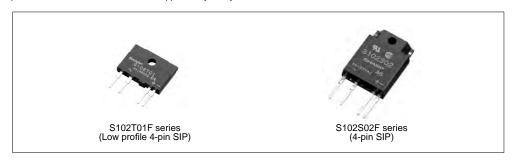
 \bigcirc : Approved, \triangle : Under application

(Ta = 25°C)

				ved by andards*6		Absolu	te maximum	ratings		lectrica racteris	
Model No.	Internal connection diagram	Features	UL	CSA	Package	ON-state current IT (rms) (A)	Repetitive peak OFF-state voltage VDRM(V)	voltage	IFT	VD (V)	RL (Ω)
S201S06F		200 V lines (built-in zero-cross circuit)	0	0		3* ³		3.0	15	6	30
S202S02F	Zero- cross	200 V lines (built-in zero-cross circuit)	0	0		8*2		4.0	8	6	30
S216S02F	circuit	200 V lines (built-in zero-cross circuit)	_	_		16* ⁵		4.0	8	6	30
S202S15F		200 V lines (built-in snubber circuit)	_	_	4-pin SIP	8*2	600	3.0	15	12	30
S202S11F		200 V lines (built-in snubber circuit)	0	0		8*1			8	12	30
S202S12F	Zero-cross circuit	200 V lines (built-in snubber circuit, built-in zero-cross circuit)	0	0		8* ¹		4.0	8	6	30

^{*1} Tc ≦ 88°C

^{*6} Please refer to Specification Sheets for model numbers approved by safety standards.



^{*2} Tc ≦ 80°C

^{*3} Tc ≦ 100°C

^{*4} Tc ≦ 70°C

^{*5} Tc ≦ 60°C





■ Photointerrupter Lineup

<Transmissive type>

Output type	Package type	Outline	Mounting method	Model No. (series)	Page
Single phototransistor	Compact	High resolution	PWB mounting type	GP1S396HCP0F/GP1S09xHCZ0F/ GP1S19xHCZ0F	58
High response speed			Surface-mount type/ Soldering reflow	GP1S396HCPSF/GP1S296HCPSF/ GP1S092HCPIF/GP1S19xHCxSF	58
	Case type	High resolution	PWB mounting type, etc.	GP1S5x series	59
		Horizontal slit, High resolution	PWB mounting type	GP1S59J0000F	59
	With connector	General purpose	Snap-in	GP1S173LCS2F/GP1S74PJ000F/ GP1S273LCS1F	59
Darlington phototransistor	Case type	General purpose	PWB mounting type, etc.	GP1L5x series	60
High sensitivity		Wide gap	PWB mounting type	GP1L57J0000F	60
Digital output	Compact	High voltage	PWB mounting type	GP1A98HCZ0F	60
(OPIC output)			Surface-mount type	GP1A98HCPSF	60
	Case type	High resolution	With screw hole/ PWB mounting type	GP1A5x series	61
		Wide gap	PWB mounting type	GP1A57HRJ00F	61
	With connector	General purpose	Screw mounting type/Snap-in	GP1A173LCS2F/GP1A173LCSVF/ GP1A273LCS1F/GP1A7x series/ GP1A07x series	62

<Reflective type>

Output type	Package type	Outline	Mounting method	Model No. (series)	Page
Single phototransistor	Leadless	Long focal distance	Surface-mount type	GP2S700HCP	62
High response speed	Compact, thin (leadless)	General purpose	Surface-mount type	GP2S60	62
OPIC output	With connector	Light modulation type, Sensitivity adjusted	Screw mounting type/ Compact snap-in/ Inverter light countermeasures	GP2A25 series/GP2A28 series/ GP2A200LCS0F/GP2A230LRS0F/ GP2A231LRSAF/ GP2A240LCS0F/GP2A250LCS0F	63

<Application-specific photointerrupter lineup>

Detection type	Outline (C	utput type etc.)	Mounting method	Model No. (series)	Page
Transmissive type	Case type With encoder function Digital 2 output (phase A/B)	Resolution: 45 LPI Linear scale slit pitch: 0.56 mm	PWB mounting type	GP1A057SGKLF	64
		Resolution: 150 LPI Linear scale slit pitch: 0.17 mm	PWB mounting type/	GP1A057RBKLF	64
		Resolution: 180 LPI Linear scale slit pitch: 0.14 mm	Screw mounting type	GP1A058SCK0F	64
		Resolution: 300 LPI Linear scale slit pitch: 0.0847 mm	PWB mounting type	GP1A054RDKLF	64
	Case type With encoder function Digital 2 output (Multiplying output)	Resolution for reading: 180 LPI Pitch: 0.14 mm Output resolution: 360 LPI	PWB mounting type	GP1A101C2KSF	64
	For amusement use		Screw mounting	GP1A204HCS0	64
Reflective type	Injection For prism system (Singl	e phototransistor)	Screw mounting	GP2S29SVJ00F	64
	For amusement use (Pa	chinko ball sensor)	-	GP2A222HCKA	65



☆New product



■ Photointerrupters

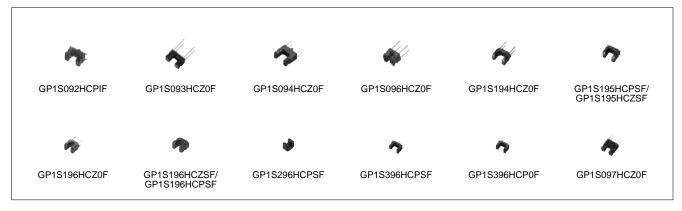
- <Transmissive type>
- **♦**Single phototransistor output

<Compact type>

(Ta = 25°C)

	Internal Detecting and Slit width Current transfer ratio				al char	acterist	ics				
		_	and		Currer	nt transfe	er ratio	F	Respon	se time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (kΩ)	VCE (V)
GP1S092HCPIF		Wide gap, for soldering reflow, surface mount compatible, with positioning boss (4.5 × 2.6 × 2.9 [height] mm)	2.0	0.3	2.0	5	5	50	0.1	1	5
GP1S093HCZ0F		Wide gap (4.5 × 2.6 × 2.9 [height] mm)	2.0	0.3	2.0	5	5	50	0.1	1	5
GP1S094HCZ0F		Wide gap, with positioning pin, (5.5 × 2.6 × 4.8 [height] mm)	3.0	0.3	0.8	5	5	50	0.1	1	5
GP1S096HCZ0F		Narrow gap (3.5 × 2.6 × 2.9 [height] mm)	1.0	0.3	2.0	5	5	50	0.1	1	5
GP1S194HCZ0F		Compact, wide gap, size: 3.6 × 2.0 × 2.7 (height) mm	1.7	0.3	3.0	5	5	50	0.1	1	5
GP1S195HCZSF GP1S195HCPSF		Compact, wide gap, surface mount compatible, size: 3.4 × 2.0 × 2.7 (height) mm	1.5	0.3	3.0	5	5	50	0.1	1	5
GP1S196HCZ0F		Compact, low profile $(3.1 \times 2.0 \times 2.7 \text{ [height] mm})$	1.1	0.3	2.0	5	5	50	0.1	1	5
GP1S196HCZSF GP1S196HCPSF		Surface mount, for soldering reflow, compact, low profile (3.1 × 2.0 × 2.7 [height] mm)	1.1	0.3	2.0	5	5	50	0.1	1	5
GP1S296HCPSF		Surface mount, for soldering reflow, compact, low profile (2.5 × 1.8 × 1.9 [height] mm)	1.0	0.2	3.0	5	5	50	0.1	1	5
☆GP1S396HCP0F		Straight lead type, compact, low profile (2.26 × 1.4 × 1.6 [height] mm)	1.2	0.12	2.0	5	5	50	0.1	1	5
☆GP1S396HCPSF		Surface mount, for soldering reflow, compact, low profile (2.26 × 1.4 × 1.6 [height] mm)	1.2	0.12	2.0	5	5	50	0.1	1	5
GP1S097HCZ0F		High resolution, wide gap, with mounting hole (4.5 × 2.6 × 4.5 [height] mm)	2.0	0.3	2.0	5	5	50	0.1	1	5

^{*} Topr: -25 to +85°C *** GP1SxxxHCZxF: Sleeve package, GP1SxxxHCPxF: Taped package





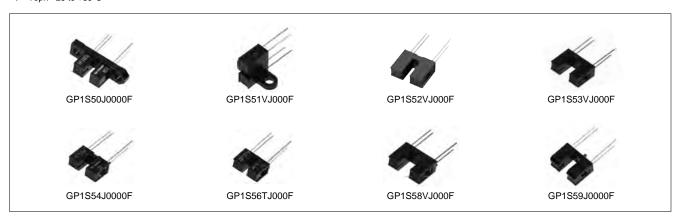


(Ta = 25°C)

<Case type>

			Detecting			Elec	tro-optic	al char	acteris	ics	
	Internal		and	Slit width	Currer	t transf	er ratio	F	espon	se time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (Ω)	VCE (V)
GP1S50J0000F		High resolution, both-side mounting type	3.0	0.5	2.5	20	5	3	2	100	2
GP1S51VJ000F		High resolution, side mounting type	3.0	0.5	2.5	20	5	3	2	100	2
GP1S52VJ000F		High resolution, PWB mounting type	3.0	0.5	2.5	20	5	3	2	100	2
GP1S53VJ000F		High resolution, PWB mounting type	5.0	0.5	2.5	20	5	3	2	100	2
GP1S54J0000F		High resolution, with positioning pin, PWB mounting type	3.0	0.5	2.5	20	5	3	2	100	2
GP1S56TJ000F		High resolution, with positioning pin, PWB mounting type	2.0	0.15	2.0	20	5	38	0.5	1 000	2
GP1S58VJ000F		High resolution, with positioning pin, PWB mounting type	5.0	0.5	2.5	20	5	3	2	100	2
GP1S59J0000F		High resolution, horizontal slit, with positioning pin, PWB mounting type	4.2	0.5	2.5	20	5	3	2	100	2

 [★] Topr: -25 to +85°C



<With connector> (Ta = 2<u>5°C)</u>

			Detecting			Elec	tro-optic	al char	acterist	ics	
	Internal		and	Slit width	Currer	nt transf	er ratio	R	Respon	se time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (Ω)	VCE (V)
GP1S74PJ000F		Snap-in mounting type with connector Applicable to 3 kinds of thickness of mounting boards	5.0	0.5	2.5	20	5	3	2	100	2
GP1S173LCS2F		Snap-in mounting integrated connector type Applicable to 3 kinds of thickness of mounting boards	5.0	0.5	2.5	20	5	3	2	100	2
GP1S273LCS1F		Snap-in mounting integrated connector type Applicable to 3 kinds of thickness of mounting boards Compact (Compatible with 1.5 mm pitch connector)	5.0	0.7	2.5	20	5	3	2	100	2

^{*} Topr: -25 to +85°C, -30 to +95°C (GP1S173LCS2F, GP1S273LCS1F)







 $(Ta = 25^{\circ}C)$

◆Darlington phototransistor output

<Case type> (Ta = 25°C)

	Detecting		Elect	tro-optic	al char	acterist	ics				
	Internal	_	and	Slit width	Currer	nt transfe	er ratio	R	espon	se time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	CTR (%) MIN.	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (Ω)	VCE (V)
GP1L50J0000F▲		High sensitivity, both-side mounting type	3.0	0.5	50	1	2	80	2	100	2
GP1L51J0000F		High sensitivity, side mounting type	3.0	0.5	50	1	2	80	2	100	2
GP1L52VJ000F	* = 5	High sensitivity, PWB mounting type	3.0	0.5	50	1	2	80	2	100	2
GP1L53VJ000F		High sensitivity, PWB mounting type	5.0	0.5	30	1	2	80	2	100	2
GP1L57J0000F		High sensitivity, wide gap, PWB mounting type	10.0	1.8	70	1	2	130	2	100	2

 [★] Topr: -25 to +85°C

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.



♦ OPIC type ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

<Compact type>

			Detecting				Electro	optical cl	naracteris	tics		
	Internal	_	and	Slit width	Thresho	old input o	urrent		Propagati	on dela	y time	
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	IFLH (mA) MAX.	IFHL (mA) MAX.	Vcc (V)	tpLн (µs) TYP.	tPHL (µs) TYP.	IF (mA)	RL (kΩ)	Vcc (V)
GP1A98HCZ0F	Voltage regulator Amplifier	Compact, PWB mounting	3.2	0.5	8	ı	3.3 to 24	2.0	10.0	10	3.9 to 20	3.3 to 24
GP1A98HCPSF		Compact, surface mount	3.2	0.5	8	ı	3.3 to 24	2.0	10.0	10	3.9 to 20	3.3 to 24

[₩] Topr = -25 to +85°C







<Case type>

 $(Ta = 25^{\circ}C)$

			Detecting			l	Electro-	optical ch	aracterist	ics	alas stima				
Ma dal Ma	Internal	Frational	and	Slit width	Thresho	old input o	urrent	F	ropagation	n delay	time				
Model No.	connection diagram	Features	emitting gap (mm)	(mm)	IFLH (mA) MAX.	IFHL (mA) MAX.	Vcc (V)	tplh (µs) TYP.	tPHL (µs) TYP.	IF (mA)	RL (Ω)	Vcc (V)			
GP1A50HRJ00F		Both-side mounting, with screw hole	3.0	0.5	5	_	5	3	5	5	280	5			
GP1A51HRJ00F	Voltage	Side mounting, with screw hole	3.0	0.5	5	_	5	3	5	5	280	5			
GP1A52HRJ00F	regulator Amplifier	PWB mounting type	3.0	0.5	5	_	5	3	5	5	280	5			
GP1A53HRJ00F	(When light is cut off:	PWB mounting type	5.0	0.5	8	_	5	3	5	8	280	5			
GP1A57HRJ00F	low level)	PWB mounting type, with positioning pin	10.0	1.8	7	-	5	3	5	7	280	5			
GP1A58HRJ00F		PWB mounting type, with positioning pin	5.0	0.5	8	_	5	3	5	8	280	5			
GP1A52LRJ00F	Voltage regulator Amplifier (When light is cut off: high level)	PWB mounting type	3.0	0.5	_	5	5	5	3	5	280	5			

Topr = -25 to +85°C











GP1A50HRJ00F

GP1A51HRJ00F

GP1A52LRJ00F (GP1A52HRJ00F)

GP1A53HRJ00F GP1A58HRJ00F with positioning pin

GP1A57HRJ00F



PHOTOINTERRUPTERS (TRANSMISSIVE TYPE)/(REFLECTIVE TYPE)



♦ OPIC type ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

<With 3-pin connector terminal>

(Ta = 25°C)

				Detecting			Elect	ro-optical	characteri	stics	
	Internal			and	Slit width		voltage	Lo	ow level ou	tput volta	ge
Model No.	connection diagram		Features	emitting gap (mm)	(mm)		CC V) MAX.	Vol (V) MAX.	Light cut-off	lo _L (mA)	Vcc (V)
GP1A173LCS2F			Snap-in mounting integrated connector type*1	5.0	0.5	4.5	5.5	0.35	No	4	5
GP1A173LCSVF	-Voltage regulator		Snap-in mounting integrated connector type*1	5.0	0.5	4.5	5.5	0.35	No	4	5
GP1A273LCS1F	regulator	connector	Integrated connector, compatible with 1.5 mm pitch connector, snap-in mounting type*1	5.0	0.7	4.5	5.5	0.35	No	4	5
GP1A73AJ000F		3-pin co	Compact, snap-in mounting type*1	5.0	0.5	4.5	5.5	0.35	No	4	5
GP1A073LCS		with 3-	Compact, snap-in mounting type*1, low voltage operation	5.0	0.5	2.7	5.5	0.35	No	4	3
GP1A75EJ000F	Voltage regulator Amplifier	1	Either-side mounting type Screw mounting type	5.0	0.5	4.5	5.5	0.35	Yes	16	5

Topr: -20 to +75°C, -30 to +95°C (GP1A173LCS2F, GP1A173LCSVF, GP1A273LCS1F)

^{*1} Applicable to 3 kinds of thickness of mounting boards.



■ Photointerrupters

- <Reflective type>
- **♦**Single phototransistor output

<Compact>

(Ta = 25°C)

		Internal				ctro-optica	l charact	eristics		
Model No.	Internal connection	Features	detecting		ent transfei	ratio		Respon	se time	
Wiodel No.	diagram	i datares	distance	011(70)	lF	VCE	tr (µs)	Ic	RL	VCE
			(mm)	MIN.	(mA)	(V)	TYP.	(mA)	$(k\Omega)$	(V)
GP2S700HCP	* 5	$\begin{array}{l} \text{Compact (4 \times 3 \times 2 [height] mm),} \\ \text{long focal distance, surface mounting leadless type} \end{array}$	3	1.5	4	2	20	0.1	1	2
GP2S60	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\	Thin (3.2 \times 1.7 \times 1.1 [height] mm), surface mounting leadless type	0.5	1.0	4	2	20	0.1	1	2

[₩] Topr: -25 to +85°C





PHOTOINTERRUPTERS (REFLECTIVE TYPE)



♦ OPIC output ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.

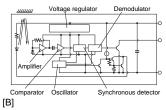
<With 3-pin connector terminal>

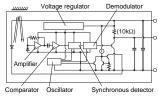
 $(Ta = 25^{\circ}C)$

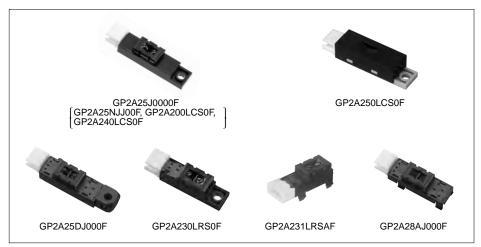
			0-4		Е	Electro-opti	cal charact	teristics	
	Internal	<u> </u>	Optimum detecting	Supply	voltage	Dissipation	n current	Low level or	tput voltage
Model No.	connection diagram	Features	distance (mm)	(\ MIN.	CC /) MAX.	Icc (mA) MAX.	Vcc (V)	Vol (V) MAX.	Vcc (V)
GP2A200LCS0F		Multi types of paper detectable, light modulation type, with connector, sensitivity adjusted	5 to 15	4.75	5.25	30*1	5	0.4	5
GP2A240LCS0F	(Following	Applicable to inverter fluorescent lamp, light modulation type, with connector, sensitivity adjusted	5 to 15	4.75	5.25	30*1	5	0.4	5
GP2A250LCS0F	diagram [A])	Static electricity resistant, applicable to inverter fluorescent lamp, light modulation type, with connector, sensitivity adjusted	2.5 to 12.5	4.75	5.25	30*1	5	0.4	5
GP2A25J0000F		Multi types of paper detectable, light modulation type, with connector, sensitivity adjusted	3 to 7	4.75	5.25	30*1	5	0.4	5
GP2A230LRS0F	(Following	Compact, hook type (GP2A231LRSAF),	3 to 7	4.75	5.25	20*1	5	0.4	5
GP2A231LRSAF	diagram [B])	multi types of paper detectable, light modulation type, with connector	3 10 7	4.75	5.25	20 '	5	0.4	5
GP2A25NJJ00F	/Fall-ordina	Multi types of paper detectable, light modulation type, sensitivity adjusted, improved light-resistance characteristic for inverter lighting, built-in visible light cut filter	3 to 7	4.75	5.25	30*1	5	0.4	5
GP2A25DJ000F	(Following diagram [A])	Multi types of paper detectable, light modulation type, with connector, sensitivity adjusted	3 to 7	4.75	5.25	30*1	5	0.4	5
GP2A28AJ000F		Multi types of paper detectable, light modulation type, with connector, sensitivity adjusted, hook type	3 to 7	4.75	5.25	30*1	5	0.4	5

[Internal connection diagram]

[A]







Topr: -10 to +60°C (GP2A25J0000F, etc.)
-10 to +70°C (GP2A200LCS0F, GP2A240LCS0F, GP2A250LCS0F, GP2A230LRS0F, GP2A231LRSAF)

^{*1} Smoothing value R L = ∞



PIO PHOTOINTERRUPTERS FOR SPECIFIC APPLICATIONS



■ Photointerrupters for Specific Applications

♦Transmissive type

<Case type, with encoder function>

 $(Ta = 25^{\circ}C)$

	Absolute m	aximum ratings			Electro-optical characteristics			
Model No.	Vcc (V)	Topr (°C)	Operating voltage Vcc (V) TYP.	Output signal	Resolution	Response f (kHz) MAX.	frequency IF (mA)	Dissipation current (output side) Icc (mA) MAX.
GP1A057RBKLF	6	-10 to +70	3.3		Linear scale slit pitch 0.17 (mm) (150LPI)	60	20	7
GP1A054RDKLF	6	-10 to +70	3.3	Digital 2 output	Linear scale slit pitch 0.0847 (mm) (300LPI)	40	20	5.5
GP1A057SGKLF	6	-10 to +70	3.3	(Phase A/B)	Linear scale slit pitch 0.56 (mm) (45LPI)	25	20	5.5
GP1A058SCK0F	6	-10 to +70	3.3		Linear scale slit pitch 0.14 (mm) (180LPI)	40	20	5.5
GP1A101C2KSF	6.5	-10 to +70	3.3	Digital 2 output (Multiplying output)	Resolution for reading: 180 LPI (Pitch: 0.14 mm) Output resolution: 360 LPI	120	20	20

^{*} High precision read and low affection of angle error from vibration thanks to the multi-segment PD system. Duty ratio: 50±15%, phase difference: 90±45°







GP1A058SCK0F



GP1A101C2KSF

<For amusement use>

 $(Ta = 25^{\circ}C)$

			Datastina			Ele	ctro-optica	al charact	eristics	
Model No.	Internal connection	Features	Detecting and emitting	Slit width (mm)		g voltage (V)	L	ow level o	output vol	tage
	diagram		gap (mm)	(111111)	MIN.	MAX.	Vol (V) MAX.	Light cut-off	IoL (mA)	Vcc (V)
GP1A204HCS0	Voltage regulator	Connector with lock, screw mounting type, high resistant to noise	4.0	0.5	10.8	24	0.4	Yes	5	10.8 to 24



♦Reflective type

<Case type, phototransistor output>

(Ta = 25°C)

					Electro-o _l	otical char	acteristics		
Model No.	Internal connection	Features	Pea	k photocur	rent		Respon	se time	
Woder No.	diagram	T GUILLIOS	ICP (mA)	IF (mA)	VCE (V)	tr (µs) TYP.	Ic (mA)	RL (kΩ)	VCE (V)
GP2S29SVJ00F	* 5	Long focal distance (with prism system*1), compact, screw mounting type	0.4 to 3.0*1	20	5	38	0.5	1	2

 [★] Topr: -25 to +85°C

^{*1} Space between prism and sensor is 8 mm.





PHOTOINTERRUPTERS FOR SPECIFIC APPLICATIONS / **PROXIMITY SENSOR**



<For amusement use>

(Ta = 25°C)

		Electro-optical characteristics						
Model No.	Features	Supply voltage Vcc (V)	Dissipation current Icc (mA)	Response frequency f (Hz)				
GP2A222HCKA	Employs reflective type, pinball detector, connector with lock In conjunction with an IC, detects beam interruption*1	4.5 to 16.5	MAX. 10	MAX. 500				

^{*1} Used together with interface IC for control (IR3N184)



■ Proximity Sensor

(Ta = 25°C)

		Absolute max	imum ratings	Electro-optical characteristics					
Model No.	Features	Vcc (V)	Topr (°C)	Dissipation current Icc (μΑ) TYP.	Detecting distance Lon (mm) MIN.	Non- detecting distance Loff (mm) MAX.	Maximum acceptable illuminance Ev (lx) MIN.	Peak emission wavelength λp (nm)	
GP2AP002S00F	Compact size $(4.0 \times 2.0 \times 1.25 \text{ t mm})$ Disparities in detecting distance results are greatly reduced using a built-in circuit for reduction of light-detecting sensitivity disparities Built-in LEDs for simple optical design and I ² C output	3.8	-25 to +85	240	25	150	3 000	940	



PROXIMITY SENSOR WITH INTEGRATED AMBIENT LIGHT SENSOR

☆New product



■ Proximity Sensor with Integrated Ambient Light Sensor

(Ta = 25°C)

		Absolut mum r					Electro-op	tical chara	cteristics			
					F	Proximity s	ensor portio	ı	Ambi	ent light se	nsor port	ion
Model No.	Features			Dissipa- tion	Detecting	Non- detecting	Maximum	Peak	Recom- mended	Peak	- '	current
		Vcc (V)	Topr (°C)	current Icc (µA) TYP.	distance Lon (mm) MIN.	distance Loff (mm) MAX.	acceptable illuminance Ev (lx) MIN.	emission wave- length λp (nm)	illuminance range Ev (lx) MIN.	sensitivity wave- length λp (nm)	lo1 (μΑ) TYP.	lo2 (µA) MAX.
GP2AP002A00F	LED and ambient light sensor combined in a single package (5.6 × 2.1 × 1.25 t mm) Disparities in detecting distance results are greatly reduced using a built-in circuit for reduction of light-detecting sensitivity disparities Built-in LEDs for simple optical design Proximity sensor: I ² C output Ambient light sensor: logarithmic current output	3.8	-25 to +85	270	25	150	3 000	940	3 to 55 000	555	30 (at Ev = 1 000 lx)	1 (at Ev = 0 lx)

(Ta = 25°C)

		Absolute maximum ratings		Electro-optical characteristics							
					Proximity se	nsor portion	Ambien	t light sensor	portion		
Model No.	Features	Vcc (V)	Topr (°C)	Dissipation current Icc (µA) TYP.	Detecting distance Lon (mm) MIN.	Peak emission wavelength λp (nm)	Recom- mended illuminance range Ev (Ix)	Output resolution (bit)	ADC conversion time Tint (ms) TYP.		
☆GP2AP020A00F	LED and ambient light sensor combined in a single package (4.0 × 2.0 × 1.25 t mm) Built-in LEDs for simple optical design Illuminance output: digital 16-bit output (Minimum detectable illuminance: 0.02 lx) I ² C output compatible (proximity sensor, ambient light sensor)	3.8	-35 to +85	70	45.5	940	0.2 to 131 072	16	100		



GP2AP002A00F



GP2AP020A00F





■ Ambient Light Sensors

(Ta = 25°C)

			Absolute	maximu	m ratings		Electro-	optical char	acteristics	,	· ·
Model No.	Туре	Package	Vcc (V)	lo (mA)	Topr (°C)	Recommended supply voltage Vcc (V)	Recommended illuminance range Ev (Ix)	Dissipation current Icc (µA) TYP.	Peak sensitivity wavelength λp (nm)	lo ₁	lo2 (µA) TYP.
GA1A2S100SS	Built-in amplification circuit Peak sensitivity characteristic close to human visual sensitivity Output characteristic: Linear current output for illuminance Lead frame (straight) type	Transparent	7.0	5	-40 to +85	2.7 to 3.6	10 to 10 000	500	555	480 (at Ev = 1 000 lx)	48 (at Ev = 100 lx)
GA1A2S100LY	Built-in amplification circuit Peak sensitivity characteristic close to human visual sensitivity Output characteristic: Linear current output for illuminance Lead frame (L bend) type	(3 × 4 mm)	7.0	5	-40 to +85	2.7 to 3.6	10 to 10 000	500	555	480 (at Ev = 1 000 lx)	48 (at Ev = 100 lx)
GA1A1S202WP	Built-in amplification circuit Peak sensitivity characteristic close to human visual sensitivity Output characteristic: Logarithmic current output for illuminance	Compact SMD (2.0 × 1.6 × 0.6 mm) Leadless	7.0	1	-40 to +85	2.3 to 3.2	3 to 55 000	70	555	20 (at Ev = 100 lx)	30 (at Ev = 1 000 lx)
GA1A1S203WP	Built-in amplification circuit Peak sensitivity characteristic close to human visual sensitivity Output characteristic: Logarithmic current output for illuminance Thin type	Compact SMD (2.0 × 1.6 × 0.42 mm) Leadless	7.0	1	-40 to +85	2.3 to 3.2	3 to 55 000	70	555	20 (at Ev = 100 lx)	30 (at Ev = 1 000 lx)
GA1A1S204WP	Built-in amplification circuit Peak sensitivity characteristic close to human visual sensitivity Output characteristic: Logarithmic current output for illuminance Back-mount-available type	Compact SMD (3.3 × 2.0 × 0.6 mm) Back-mount available, leadless	7.0	1	-40 to +85	2.3 to 3.2	3 to 55 000	70	555	20 (at Ev = 100 lx)	30 (at Ev = 1 000 lx)
GA1A1S100WP	Built-in amplification circuit Peak sensitivity characteristic close to human visual sensitivity Output characteristic: Linear current output for illuminance	Compact SMD (2.0 × 1.6 × 0.6 mm) Leadless	7.0	10	-40 to +85	2.7 to 3.6	10 to 5 000	1 460	555	1 420 (at Ev = 1 000 lx)	142 (at Ev = 100 lx)











GA1A2S100LY

GA1A1S202WP (GA1A1S100WP)

GA1A1S203WP

GA1A1S204WP



OPIC LIGHT DETECTORS



■ OPIC Light Detectors ("OPIC" (Optical IC) is a trademark of SHARP Corporation. An OPIC consists of a light-detecting element and signal-processing circuit integrated onto a single chip.)

(Ta = 25°C)

			Absolute maximum ratings					Electro-optical characteristics							
Model No.	Type	Package	Vcc	D	lo	Topr	Evlh	EVHL		tPLH	tPHL				
	1,700	radiago	(V)	(mW)	(mA)	(°C)	(Ix) MAX.	(lx) MAX.	Vcc (V)	(µs) TYP.	(µs) TYP.	Vcc (V)	E∨ (Ix)	RL (Ω)	
IS485E	Built-in schmidt trigger	Transparent	-0.5 to +17	175	50	-25 to +85	_	35	5	5	3	5	50	280	
IS486E	circuit, amplifier and voltage regulator	epoxy resin with condenser (lens)	-0.5 to +17	175	50	-25 to +85	35	_	5	3	5	5	50	280	



<Low-voltage operation>

(Ta = 25°C)

			Absolute maximum ratings			Electro-optical characteristics								
Model No.	Type	Package	ь	lo	Topr	Operating	Evlh	EVHL		tPHL	tPLH			
model ito:	1,500	rackago	(mW)	(mA)	(°C)	supply voltage (V)	(lx) MAX.	(lx) MAX.	Vcc (V)	(µs) TYP.	(µs) TYP.	Vcc (V)	Ev (lx)	RL (Ω)
IS489E	Built-in Schmidt trigger circuit and amplifier	Transparent epoxy resin with condenser (lens)	80	2	-25 to +85	1.4 to 7.0	-	15	3	1.3	8.5	3	125	3 000



<Model employing a light modulation system>

 $(Ta = 25^{\circ}C)$

	. ,		•										(.a _0 0)
			Absol	lute max	kimum r	atings		Electro-	optical ch	aracterist	ics*2		External
Model No.	Туре	Package	Vcc (V)	P (mW)	lo (mA)	Topr (°C)	Vol (V) MAX.	Voh (V) MIN.	tplh (µs) TYP.	tphl (µs) TYP.	Vcc (V)	RL (Ω)	disturbing light illuminance EVDX(Ix) TYP.
IS471FE*1, *3	Built-in pulse driver circuit at the emitter side, synchronous detector circuit, amplifier circuit and demodulator circuit	Visible light cut-off epoxy resin	-0.5 to +16	250	50	-25 to +60	0.35	4.97	400	400	5	280	7 000

- *1 IS471FE is less susceptible to disturbing effects
 *2 Vcc = 5 V
 *3 Straight lead type (IS471FSE) is also available. ${\sf IS471FE} \ is \ less \ susceptible \ to \ disturbing \ effects \ thanks \ to \ the \ light \ modulation \ system$







<For laser beam printers (laser beam origin detection)>

(Ta = 25°C)

				Electro-opt	ical characteris	tics
MadalNa	T	Dealerna	Recommended supply	Voн	Vol	$H \rightarrow L$ delay time variation
Model No.	Туре	Package	voltage Vcc (V)	(V) MIN.	(V) MAX.	Δ tphL (ns) MAX.
GA220T2L2IZ	2-PD, differential type	Transparent epoxy resin 18-pin	4.5 to 5.5	4.9	0.6	±8.5





PHOTOTRANSISTOR LINEUP



■ Phototransistor Lineup

			Half	Mod	el No.
Package	Output type	Features	sensitivity angle	Standard	Visible light cut-off
Epoxy resin with lens	Single phototransistor	General purpose/Narrow acceptance	±13°	PT480E00000F	PT480FE0000F
		Compact, thin	±35°	PT4800E0000F	PT4800FE000F / PT4850FE000F
	Darlington phototransistor	High sensitivity/Narrow acceptance	±13°	PT481E00000F	PT481FE0000F
		High sensitivity/Narrow acceptance/Long lead	±13°		PT483F1E000F
		High sensitivity/Compact, thin	±35°	PT4810E0000F▲	PT4810FJE00F▲
		High sensitivity/Intermediate acceptance	±40°	_	PT491FE0000F
		High sensitivity/Intermediate acceptance/Long lead	±40°	_	PT493FE0000F▲
Surface mounting leadless type	Single phototransistor	Compact (side view/top view mounting possible)	±15°	PT100MC0MP	PT100MF0MP
	Darlington phototransistor	Compact (side view/top view mounting possible)	±15°	_	PT100MF1MP

The model marked with \blacktriangle may not be available in the near future. Contact with SHARP for details before use.



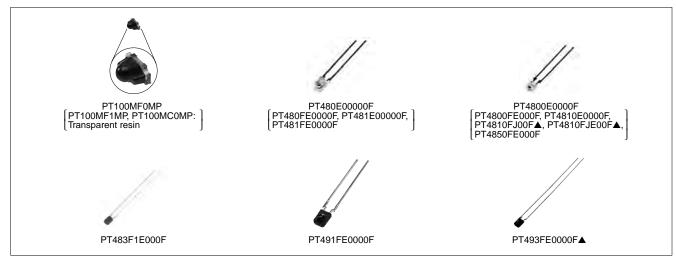


■ Phototransistors

_O			Absolu	ute maxim	num ratings		lc (r	mA)		Iceo(A)		Δθ	λр
Type	Model No.	Package	VCEO (V)	Pc (mW)	Topr (°C)	MIN.	MAX.	VCE (V)	Ee (mW/cm ²)	MAX.	VCE (V)	(°) TYP.	(nm) TYP.
	PT100MC0MP	Surface mounting	35	75	-30 to +85	1.7	5.1	5	1	1×10 ⁻⁷	20	±15	900
	PT100MF0MP*1	leadless type with lens	35	75	-30 to +85	1.15	3.45	5	1	1×10 ⁻⁷	20	±15	910
	PT480E00000F		35	75	-25 to +85	0.4	TYP. 1.7	5	1	1×10 ⁻⁷	20	±13	800
Single	PT480FE0000F*1		35	75	-25 to +85	0.25	TYP. 0.8	5	1	1×10 ⁻⁷	20	±13	860
-	PT4800E0000F	Epoxy resin with lens	35	75	-25 to +85	0.12	TYP. 0.4	5	1	1×10 ⁻⁷	20	±35	800
	PT4800FE000F*1		35	75	-25 to +85	0.08	TYP. 0.25	5	1	1 × 10 ⁻⁷	20	±35	860
	PT4850FE000F*1		35	75	-25 to +85	0.12	0.56	5	1	1 × 10 ⁻⁷	20	±35	860
	PT481E00000F		35	75	-25 to +85	1.5	25	2	0.1	1×10 ⁻⁶	10	±13	800
	PT481FE0000F*1		35	75	-25 to +85	0.9	27	2	0.1	1×10 ⁻⁶	10	±13	860
	PT4810E0000F▲		35	75	-25 to +85	0.45	7.0	2	0.1	1×10 ⁻⁶	10	±35	800
Darlington	PT4810FJE00F*1▲	Epoxy resin with lens	35	75	-25 to +85	0.27	6.0	2	0.1	1×10 ⁻⁶	10	±35	860
Darlir	PT483F1E000F*1		35	75	-25 to +85	1.5	4.0	2	0.1	1×10 ⁻⁶	10	±13	860
	PT491FE0000F*1		35	75	-25 to +85	0.2	0.8	2	Ev, 2 lx	1×10 ⁻⁶	10	±40	860
	PT493FE0000F*1▲		35	75	-25 to +85	0.2	0.8	2	Ev, 2 lx	1×10 ⁻⁶	10	±40	860
	PT100MF1MP*1	Surface mounting leadless type with lens	35	75	-30 to +85	0.2	1.2	5	0.01	1×10 ⁻⁶	10	±15	860

^{*1} Visible light cut-off type

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■ PIN Photodiodes

(Ta = 25°C)

	_	Package	Active	Topr	Isc		ld		tr, tf			λρ
Model No.	Features	(Material)	area (mm²)	(°C)	(μA) MIN.	Ev (lx)	(A) MAX.	VR (V)	(µs) TYP.	VR (V)	RL (kΩ)	(nm) TYP.
PD410PI2E00F		Visible light cut-off epoxy resin with condenser (lens)	3.31	-25 to +85	2.5	100	1 × 10 ⁻⁸	10	0.2	10	1	1 000
PD411PI2E00F	PIN type	Transparent epoxy resin with condenser (lens)	3.31	-25 to +85	5.0	100	1 × 10 ⁻⁸	10	0.2	10	1	960
PD412PI2E00F		Transparent epoxy resin with condenser (lens)	3.31	-25 to +85	3.5	100	1 × 10 ⁻⁸	10	0.25	10	1	800
PD413PI2E00F	PIN type IrDA1.0	Visible light cut-off epoxy resin with condenser (lens)	3.31	-25 to +85	MIN. 4.5 (TYP. 5.4)	100	1 × 10 ⁻⁸	10	0.2	10	1	960
PD100MC0MP	Surface mounting leadless type	Transparent epoxy resin board with lens	_	-30 to +85	0.6	100	1 × 10 ⁻⁸	10	0.01	15	0.18	820
PD100MF0MP	Surface mounting leadless type	Visible light cut-off epoxy resin board with lens	_	-30 to +85	0.4	100	1 × 10 ⁻⁸	10	0.01	15	0.18	850



PD410PI2E00F

[PD411PI2E00F: transparent; PD412PI2E00F: transparent,]
PD413PI2E00F

PD100MC0MP (PD100MF0MP: black)

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INFRARED EMITTING DIODE LINEUP/ INFRARED EMITTING DIODES



■ Infrared Emitting Diode Lineup

Туре	Package	Featu	ıres	Half intensity angle	Model No.
Single-end lead	Epoxy resin with lens	General purpose/Narrow bear	n angle	±13°	GL480E00000F
(Side view type)					
		Compact and thin		±30°	GL4800E0000F
	Flat epoxy resin	Wide beam angle		±90°	GL4100E0000F▲
	Epoxy resin with lens/				
Surface mount type	leadless	Compact/Narrow beam angle		±10°	GL100MN0MP
	(Mountable for Top view/ Side view type)				
	ciae nen type,		High output type	±10°	GL100MN1MP
		Compact/Wide beam angle		±80°	GL100MD1MP1

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.

■ Infrared Emitting Diodes

 $(Ta = 25^{\circ}C)$

												,	
·		Ab	solute	maximu	m ratings	Radia	nt flux Φe	(mW)		VF (V)		Δθ	λр
Model No.	Package, features	IF (mA)	Vr (V)	P (mW)	Topr (°C)	MIN.	TYP.	lF (mA)	TYP.	MAX.	lF (mA)	(°) TYP.	(nm) TYP.
GL480E00000F	Epoxy resin with lens	50	6	75	-25 to +85	0.7	_	20	1.2	1.4	20	±13	950
GL4800E0000F	Epoxy resin with iens	50	6	75	-25 to +85	0.7	1.6	20	1.2	1.4	20	±30	950
GL4100E0000F▲	Side-view flat type, epoxy resin	50	6	75	-25 to +85	1.0	_	20	1.2	1.4	20	±90	950
GL100MN0MP	Surface mounting leadless type, epoxy resin board with lens	50	6	75	-30 to +85	1.0	3.0 (MAX.)	20	1.2	1.4	20	±10	940
GL100MN1MP	Surface mounting leadless type, epoxy resin board with lens, high output type	50	6	75	-30 to +85	2.0	6.0 (MAX.)	20	1.2	1.5	20	±10	940
GL100MD1MP1	Surface mounting leadless type, epoxy resin board with lens, wide beam angle	50	6	75	-30 to +85	-	6.0 (MAX.)	20	-	1.5	20	±80	940

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OPTICAL-ELECTRIC SENSOR LINEUP



■ Distance Measuring Sensor Lineup

Output	Range of distance measuring	Features		Model No.
1-bit digital output according to distance measuring	4 to 30 cm	1-bit digital output (detected distance: 15/13 cm)		GP2D150AJ00F/GP2Y0D413K0F
	10 to 80 cm	1-bit digital output (detected distance: 24 d	GP2Y0D21YK0F	
	20 to 150 cm	1-bit digital output (detected distance: 80 d	cm)	GP2Y0D02YK0F
	Battery drive compatible, compact, 1-bit digital output (detected distance: 5/10 cm)			GP2Y0D805Z0F/GP2Y0D810Z0F
			Wide operating temperature type (-40 to +85°C) (detected distance: 10 cm)	GP2Y0D810Z1F
		Compact, thin 1-bit digital output (detected distance: 10/4)	40 cm)	GP2Y0D310K/GP2Y0D340K
		Battery drive compatible, compact, 1-bit digital output (detected distance: 1.5 Capable of operation at high temperature		GP2Y5D91S00F
Analog voltage output according to distance				
measuring	2 to 15 cm	Analog output		GP2Y0A51SK0F
	4 to 30 cm	Analog output		GP2Y0A41SK0F
	10 to 80 cm	Analog output		GP2Y0A21YK0F
	10 to 150 cm	Compact (22 × 8 × 7.2 [T] mm), Analog output		GP2Y0A60SZ0F/GP2Y0A60SZLF
	20 to 150 cm	Analog output		GP2Y0A02YK0F
	100 to 550 cm	Analog output		GP2Y0A710K0F

■ Wide Angle Sensor Lineup

Output Range of distance measuring		Detection angle of view	Model No.
Voltage output according to distance measuring	4 to 30 cm	25° (When using 5 beams)	GP2Y3A001K0F
	20 to 150 cm	25° (When using 5 beams)	GP2Y3A002K0F
	40 to 300 cm	25° (When using 5 beams)	GP2Y3A003K0F

■ Paper Size Sensor (Using Optical Distance Measuring Method) Lineup

Output	Features	Features				
1-bit output	1-beam (detection height: 60 mm)	Thin type (T: 11.5 mm)	GP2Y2D160K0F			
Analog output relative to measuring distance	1-beam (detection height: 80 mm)	Thin type (T: 11.5 mm)	GP2Y2A180K0F			
	2-beam (detection height: 80 mm)	Thin type (T: 11.5 mm)	GP2Y2A280K0F			

■ High-Precision Displacement Sensor

Output	Range of distance measuring	Features	Model No.
Voltage output according to distance measuring	4.5 to 6.0 mm	Resolution: 50 µm	GP2Y0AH01K0F

■ Dust Sensor Unit Lineup

Output	Features	Model No.
	Pulse analog output, single-shot detection of house dust,	
Analog output	general purpose	GP2Y1010AU0F

■ Color Toner Concentration (Deposition Amount) Sensor Lineup

Output	Features	Model No.		
Analog output	Employs diffuse reflection system + mirror reflection system	GP2TC2J0000F		
	Employs diffuse reflection system + mirror reflection system	GP2Y40010K0F		



DISTANCE MEASURING SENSORS



■ Distance Measuring Sensors (1)

♦Digital output (Ta = 25°C)

	-							,	
		Absolute max	ximum ratings		Electr	ro-optical ch	aracteristi	cs*1	
Model No.	Features	Vcc (V)	Topr (°C)	Detected distance (cm)	Distance measuring range	Voн (V) MIN.	Vol. (V) MAX.	Dissipation Operating (mA)	
GP2Y0D805Z0F	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V)	-0.3 to +7	-10 to +60	5	(cm) _	Vcc -0.6	0.6	MAX. 6.5	" /
GP2Y0D810Z0F	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V)	-0.3 to +7	-10 to +60	10	-	Vcc -0.6	0.6	MAX. 6.5	MAX. 8
GP2Y0D810Z1F	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V)	-0.3 to +7	-40 to +85	10	_	Vcc -0.6	0.6	TYP. 5	MAX. 8
GP2Y5D91S00F	Light detector, infrared LED and signal processing circuit, short distance measuring type, battery drive compatible (operating power supply: 2.7 to 6.2 V), capable of operation at high temperature	-0.3 to +7	-30 to +105	1.5	-	Vcc -0.6	0.6	TYP. 7	_
GP2Y0D310K	Digital voltage output according to the measured distance of GP2Y0D340K	-0.3 to +7	-10 to +60	10	_	Vcc -0.3	0.6	MAX. 35	_
GP2Y0D340K	Compact, thin type (15 x 9.6 x 8.7 mm: sensor part), Light detector, infrared LED and signal processing circuit, digital voltage output according to the measured distance	-0.3 to +7	-10 to +60	40	-	Vcc -0.3	0.6	MAX. 35	_
GP2Y0D21YK0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, digital voltage output	-0.3 to +7	-10 to +60	24	10 to 80	Vcc -0.3	0.6	MAX. 40	_
GP2D150AJ00F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, digital voltage output	-0.3 to +7	-10 to +60	15	4 to 30	Vcc -0.3	0.6	MAX. 50	_
GP2Y0D413K0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, digital voltage output	-0.3 to +7	-10 to +60	13	4 to 30	Vcc -0.3	0.6	_	_
GP2Y0D02YK0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, long distance measuring type (No external control signal required), digital voltage output according to the measured distance	-0.3 to +7	-10 to +60	80	20 to 150	Vcc -0.3	0.6	MAX. 50	_

^{*1} Vcc = 5 V * PSD: Position Sensitive Detector

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DISTANCE MEASURING SENSORS



■ Distance Measuring Sensors (2)

♦Analog output

(Ta = 25°C)

		Absolute max	rimum ratings	E	Electro-optical c	haracteristics*1	
Model No.	Features	Vcc (V)	Topr (°C)	Distance measuring range (cm)	Voh (V) MIN.	Vol (V) MAX.	Dissipation current Operating (mA)
GP2Y0A21YK0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, linear voltage output	-0.3 to +7	-10 to +60	10 to 80	Vo (TYP) (at L = ΔVo (TYF) (at L: 80 cm	MAX. 40	
GP2Y0A41SK0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, short measuring cycle (16.5 ms)	-0.3 to +7	-10 to +60	4 to 30	(at L = ∆Vo (TYP	(a) = 0.4 V 30 cm), (b) = 2.25 V cm → 4 cm)	MAX. 22
GP2Y0A51SK0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, short measuring cycle (16.5 ms)	-0.3 to +7	-10 to +60	2 to 15	Vo (TYP.) = 0.4 V (at L = 15 cm), Δ Vo (TYP.) = 2.25 V (at L = 15 cm → 2 cm)		TYP. 12
2 GP2Y0A60SZ0F/ GP2Y0A60SZLF	Distance measuring sensor united with PSD, infrared LED and signal processing circuit, compact type (22 x 8 x 7.2 mm), long distance measuring type (No external control signal required)	-0.3 to +5.5	-10 to +60	10 to 150	Vo (TYP.) = 0.65 V *3 (at L = 150 cm), Δ Vo (TYP.) = 3.0 V (at L = 150 cm → 20 cm)		MAX. 50
GP2Y0A02YK0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, long distance measuring type (No external control signal required)	-0.3 to +7	-10 to +60	20 to 150	(at L = 1 ΔVo (TYP	() = 0.4 V 150 cm), () = 2.05 V cm → 20 cm)	MAX. 50
GP2Y0A710K0F	Distance measuring sensor united with PSD*, infrared LED and signal processing circuit, long distance measuring type (No external control signal required)	-0.3 to +7	-10 to +60	100 to 550	(at L = 1 ∆Vo (TYF	() = 2.5 V (00 cm), (2) = 0.7 V m → 200 cm)	TYP. 30

Vcc = 5 V

^{*3} When Vcc = 3 V: Vo (TYP.) = 0.35 V (at L = 150 cm); Δ Vo (TYP.) = 1.6 V (at L = 150 cm \rightarrow 20 cm)







GP2Y0D805Z0F GP2Y0D810Z0F, GP2Y0D810Z1F



GP2Y0D340K (GP2Y0D310K)



GP2Y0A60SZ0F



* PSD: Position Sensitive Detector

GP2Y0A60SZLF



GP2Y0A21YK0F [GP2D150AJ00F, GP2Y0D21YK0F, GP2Y0A41SK0F GP2Y0D413K: without mounting hole



GP2Y0A51SK0F



GP2Y0D02YK0F (GP2Y0A02YK0F)



GP2Y0A710K0F

GP2Y0A60SZ0F: Surface mount type

GP2Y0A60SZLF: Board insertion type



WIDE ANGLE SENSORS / PAPER SIZE SENSORS / HIGH-PRECISION DISPLACEMENT SENSOR



■ Wide Angle Sensors

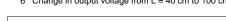
(Ta = 25°C)

L = Reflector - Sensor distance

MadalNa		Absolute max	imum ratings	Electro-optical characteristics					
	Fastures	.,		Distance	Output	Output	Input vol	tage (V)	
Model No.	Features	Vcc (V)	Topr (°C)	measuring range (cm)	terminal voltage (V)	voltage difference (V)	VınH	LEDL	
GP2Y3A001K0F	Distance measuring sensor united with PSD*,	-0.3 to +7	-10 to +60	4 to 30	TYP. 2.85*1	TYP. 1.6*4	MIN. 4.5	MAX. 0.5	
GP2Y3A002K0F	infrared LED and signal processing circuit, distance measuring sensor application product,	-0.3 to +7	-10 to +60	20 to 150	TYP. 2.3*2	TYP. 1.6*5	MIN. 4.5	MAX. 0.5	
GP2Y3A003K0F	wide range (field of view) detection using 5 infrared beams	-0.3 to +7	-10 to +60	40 to 300	TYP. 2.3*3	TYP. 1.2*6	MIN. 4.5	MAX. 0.5	

PSD: Position Sensitive Detector

- L = 4 cm
- L = 20 cm
- *3 L = 40 cm Change in output voltage from L = 40 cm to 100 cm





■ Paper Size Sensors

(Ta = 25°C)

Model No.	Features	Operating temperature	Supply voltage	Paper detection height	LED beam pitch	Approved value of paper position sliding	Paper detection density	Dissipation current
		Topr (°C)	Vcc (V)	H (mm)	Lp (mm)	Δx (mm)	OD	Icc (mA)
GP2Y2D160K0F	Thin type (T: 11.5 mm), using optical distance measuring method (1-beam), digital output (1-bit)	-10 to +65	5 ±0.5	TYP. 60	_	MIN. ±7.5	0.7 or less*1	MAX. 40
GP2Y2A180K0F	Thin type (T: 11.5 mm), analog output using optical distance measuring method (1-beam)	-10 to +65	5 ±0.5	TYP. 80	_	-	_	MAX. 25
GP2Y2A280K0F	Thin type (T: 11.5 mm), analog output using optical distance measuring method (2-beam)	-10 to +65	5 ±0.5	TYP. 80	TYP. 21	_	_	MAX. 50

This table shows the characteristics when configured in the paper size sensor system.

^{*1} Reflectivity: 18% or more, OD = log (1/T), T: Reflectivity



■ High-Precision Displacement Sensor

 $(Ta = 25^{\circ}C)$

Model No.	Features	Topr (°C)	Operating supply voltage (V)	Dissipation current (mA)	Distance measuring range (mm)	Distance characteristic of output
GP2Y0AH01K0F	Resolution: 50 μm	-10 to +60	4.5 to 5.5	TYP. 20	4.5 to 6.0	TYP. 1.70 V Variation in output over range (4.5 to 6.0 mm)



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DUST SENSOR UNIT / COLOR TONER CONCENTRATION SENSORS



■ Dust Sensor Unit

 $(Ta = 25^{\circ}C)$

			Electro-optical characteristics								
Model No.	Features	Topr (°C)	Operating supply voltage (V)	Dissipation current (mA)	Detection sensitivity V/(0.1 mg/m ³)	Output voltage at no dust Voc (V)	Output voltage range Voн (V)				
GP2Y1010AU0F	Built-in infrared emitting diode, photodiode and signal processing circuit, compact, single-shot detection of house dust	-10 to +65	4.5 to 5.5	TYP. 11	TYP. 0.5	TYP. 0.9	MIN. 3.4				



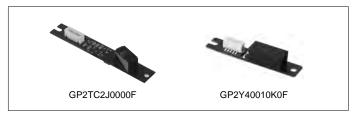
■ Color Toner Concentration (Deposition Amount) Sensors

 $(Ta = 25^{\circ}C)$

		Topr	Electro-optical characteristics				
Model No.	Features	(°C)	Dissipation current*1 (mA)	Output voltage*2 Vo1 (V)	Output voltage*2 V ₀₂ (V)		
GP2TC2J0000F	Employs diffuse reflection system + mirror reflection system, high-precision detection of toner concentration on photo-sensitive drum, 2-line analog output (2-PD)	0 to +60	TYP. 4	TYP. 1.17	TYP. 2.81		
GP2Y40010K0F	Employs diffuse reflection system + mirror reflection system, high-precision detection of toner concentration on transfer belt, 2-line analog output (2-PD)	0 to +60	TYP. 4	TYP. 1.27	MAX. 3.5 TYP. 2.87		

^{*1} Dissipation current with LED current of IFM = 0 mA

^{*2} With reflection object A (Reflectance: 15.6%)



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FIBER OPTICS LINEUP FOR AUDIO EQUIPMENT



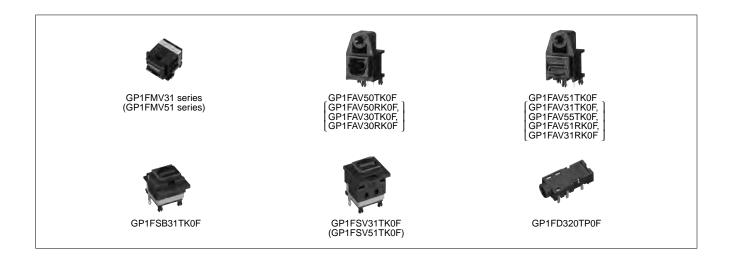
■ Fiber Optics Lineup for Audio Equipment

					High anged signal	Mod	lel No.
Connector type	Туре	Outline	Featu	ıres	High speed signal transmission	Supply voltage 3 to 5 V	Supply voltage 5 V
•	Fiber optic	Without mounting	NACO I O	Horizontal	MAN 40 0 MI /		OD45111/54T/05
Square connector	transmitter	hole	With shutter	mounting type	MAX. 13.2 Mb/s		GP1FMV51TK0F
(EIAJ RC-5720B)					MAX. 15.5 Mb/s	GP1FMV31TK0F	
		With mounting hole	With shutter	Horizontal mounting type	MAX. 13.2 Mb/s		GP1FAV51TK0F*1
					MAX. 15.5 Mb/s	GP1FAV31TK0F	
					MAX. 50 Mb/s		GP1FAV55TK0F
				Vertical mounting type	MAX. 13.2 Mb/s		GP1FSV51TK0F
				371	MAX. 15.5 Mb/s	GP1FSV31TK0F (mounting height: 15 mm) GP1FSB31TK0F (mounting height: 8.5 mm)	
			With protection cap	Horizontal mounting type	MAX. 13.2 Mb/s		GP1FAV50TK0F*1
					MAX. 15.5 Mb/s	GP1FAV30TK0F	
	Fiber optic receiver	Without mounting hole	With shutter	Horizontal mounting type	MAX. 13.2 Mb/s		GP1FMV51RK0F
				0 71	MAX. 15.5 Mb/s	GP1FMV31RK0F	
		With mounting hole	With shutter	Horizontal mounting type	MAX. 13.2 Mb/s		GP1FAV51RK0F
					MAX. 15.5 Mb/s	GP1FAV31RK0F	
			With protection cap	Horizontal mounting type	MAX. 13.2 Mb/s		GP1FAV50RK0F
					MAX. 15.5 Mb/s	GP1FAV30RK0F	

*1 TTL drive compatible

Connector type	Туре	Outline	Features	High speed signal transmission	Model No. Supply voltage 3 V
Optical mini-jack ø3.5 mm	Fiber optic transmitter	Thin type (t: 4.2 mm)	Capable of detection/transmission of optical/electrical signals	MAX. 25 Mb/s	GP1FD320TP0F

(JIS C 6650)





FIBER OPTIC TRANSMITTERS (Square Connector) / FIBER OPTIC TRANSMITTERS (ø3.5 mm Optical Mini-jack) / FIBER OPTIC RECEIVERS (Square Connector)



■ Fiber Optic Transmitters (Square Connector)

(Ta = 25°C)

	Appea	rance		Absolute max	kimum ratings		Electr	o-optic	al characte	eristics	
Model No.	Mounting		Features	Vcc	Topr	Supply	Propa delay	gation time	Dissipation current	width	Transmis- sion speed
	hole	Shutter		(V)	(°C)	voltage (V)	tplh (ns) MAX.	tPHL (ns) MAX.	Icc (mA) MAX.	distortion ∆tw (ns)	T (Mb/s) MAX.
GP1FMV31TK0F	No	Yes	Compact	-0.5 to +7	-20 to +70	2.7 to 5.25	180	180	12	±15	15.5
GP1FMV51TK0F	No	Yes	Compact	-0.5 to +7	-20 to +70	4.75 to 5.25	180	180	13	±15	13.2
GP1FAV30TK0F	Yes	No	Low voltage drive, with protection cap	-0.5 to +7	-20 to +70	2.7 to 5.25	180	180	12	±15	15.5
GP1FAV50TK0F	Yes	No	TTL drive compatible, with protection cap	-0.5 to +7	-20 to +70	4.75 to 5.25 Input voltage: MIN. 2.0 V	180	180	13	±15	13.2
GP1FAV51TK0F	Yes	Yes	TTL drive compatible	-0.5 to +7	-20 to +70	4.75 to 5.25	180	180	13	±15	13.2
GP1FSV51TK0F	No	Yes	Vertical mounting (mounting height: 15 mm)	-0.5 to +7	-20 to +70	4.75 to 5.25	180	180	13	±15	13.2
GP1FAV31TK0F	Yes	Yes	Low voltage drive	-0.5 to +7	-20 to +70	2.7 to 5.25	180	180	12	±15	15.5
GP1FSV31TK0F	No	Yes	Vertical mounting (mounting height: 15 mm)	-0.5 to +7	-20 to +70	2.7 to 5.25	180	180	13	±15	15.5
GP1FAV55TK0F	Yes	Yes	High response speed	-0.5 to +7	-20 to +70	4.75 to 5.25	180	180	13	±15	50
GP1FSB31TK0F	No	Yes	Vertical mounting (mounting height: 8.5 mm)	-0.5 to +7	-20 to +70	2.7 to 5.25	180	180	13	±15	15.5

■ Fiber Optic Transmitters (ø3.5 mm Optical Mini-jack)

 $(Ta = 25^{\circ}C)$

Model No.	Features	Abs	Absolute maximum ratings				Electro-optical characteristics					
		Vcc	Vin	Topr	Supply	Propa delay	gation time	Dissipation current		Transmis- sion speed		
		(V)	(V)	(°C)	voltage (V)	tPLH (ns) MAX.	tPHL (ns) MAX.	Icc (mA) MAX.	$\begin{array}{c} \text{distortion} \\ \Delta tw \\ \text{(ns)} \end{array}$	T (Mb/s) MAX.		
GP1FD320TP0F	Compact, thin type (t: 4.2 mm), high speed, optical mini-jack (low voltage type)	-0.5 to +7	-0.5 to Vcc + 0.5	-20 to +70	2.3 to 5.5	180	180	12	±11	25		

■ Fiber Optic Receivers (Square Connector)

(Ta = 25°C)

	Appea	arance		Absolute r	maxim	um ratings		Elec	tro-opti	cal charac	teristics	
Model No.	Mounting		Features		lol	Topr	Supply	Propa delay	gation time	Dissipation current	width	Transmis- sion speed
	hole	Shutter	, calaise	Vcc (V)	(mA)	(°C)	voltage (V)	tPLH (ns) MAX.	tPHL (ns) MAX.	Icc (mA) MAX.	distortion ∆tw (ns)	T (Mb/s) MAX.
GP1FMV31RK0F	No	Yes	Compact, low voltage drive	-0.5 to +7	10	-20 to +70	2.7 to 3.6	180	180	15	±20	15.5
GP1FMV51RK0F	No	Yes	Compact	-0.5 to +7	10	-20 to +70	4.75 to 5.25	180	180	25	±20	13.2
GP1FAV30RK0F	Yes	No	Low voltage drive, with protection cap	-0.5 to +7	10	-20 to +70	2.7 to 3.6	180	180	15	±20	15.5
GP1FAV50RK0F	Yes	No	With protection cap	-0.5 to +7	10	-20 to +70	4.75 to 5.25	180	180	25	±20	13.2
GP1FAV51RK0F	Yes	Yes		-0.5 to +7	10	-20 to +70	4.75 to 5.25	180	180	25	±20	13.2
GP1FAV31RK0F	Yes	Yes	Low voltage drive	-0.5 to +7	10	-20 to +70	2.7 to 3.6	180	180	15	±20	15.5

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■ High-Luminosity (AlGaInP) Surface Mount LEDs (Taped Models Only)

(I F = 20 mA, Tc = 25°C)

		Resin type			JE		ZVJV		JS		JJ		ZRJF	?
Outline dimensions (mm)	Colored diffusion	Colored transparency	Colorless transparency	Milky diffusion	Yellow-green	Luminous intensity (mcd) TYP.	Amber	Luminous intensity (mcd) TYP.	Sunset orange	Luminous intensity (mcd) TYP.	Orange	Luminous intensity (mcd) TYP.	Red	Luminous intensity (mcd) TYP.
1.6×0.8 (t = 0.35)			•		GM1JE35200AE*1	13	GM1JV35200AE*1	18.8	GM1JS35200AE*1	19	GM1JJ35200AE*1	19	GM1JR35200AE*1	13
$ \begin{array}{c} 1.6 \times 0.8 \\ (t = 0.55) \end{array} $			•		GM1JE55200AE	13	GM1JV55200AE*1	16.8	GM1JS55200AE	20.9	GM1JJ55200AE	19	GM1JR55200AE	15
3.2×2.8 (t = 1.9)			•		-	-	GM5ZV96270A	600	_	_	-	-	GM5ZR96270A	600

^{*1} GM1JV35200AE series, GM1JV55200AE series: IF = 5 mA

■ High-Luminosity (InGaN) Surface Mount LEDs (Taped Models Only)

 $(I F = 5 mA, Ta = 25^{\circ}C)$

		Resir	n type		D C		GC			
Outline		ncy	ncy	diffusion	Blue		Green			
dimensions (mm)	Colored diffusion	Colored transpare	Colorless transpare	Milky diffu	Blue	Luminous intensity (mcd) TYP.	Gleen	Luminous intensity (mcd) TYP.		
$1.6 \times 0.8 \ (t = 0.35)$				•	GM1BC35372AC	35	GM1GC35370AC	80		

■ Surface Mount LEDs (Taped Models Only)

 $(IF = 20 \text{ mA}, Ta = 25^{\circ}C)$

		esin t			EG		HY		HS		ΗD]
Outline dimensions (mm)	Colored diffusion		Coloriess transparency	Milly dilidaloi!	Yellow-green	Luminous intensity (mcd) TYP.	Yellow	Luminous intensity (mcd) TYP.	Sunset orange	Luminous intensity (mcd) TYP.	Red	Luminous intensity (mcd) TYP.
$1.6 \times 0.8 \ (t = 0.55)$		•	•		GM1EG55200A	19	GM1HY55200A	11.5	GM1HS55200A	11.4	GM1HD55200A	12.5



GM1EG55200A series GM1JV55200AE series GM1JV35200AE series GM1BC35372AC GM1GC35370AC

GM5ZV96270A series

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HIGH-LUMINOSITY WHITE SURFACE MOUNT LEDS / HIGH-LUMINOSITY SURFACE MOUNT LEDs (RGB 3-COLOR)

☆New product



■ High-Luminosity White Surface Mount LEDs (Taped Models Only)

 $(Ta = 25^{\circ}C^{*5})$

Outline	Color	E	3W		E	3N	ing color Luminous Color temperature		
dimensions	coordinates	V	/hite		High ren	dering color			
(mm)	(x, y) TYP.		Luminous intensity (mcd) TYP.	Color temperature (K) TYP.		Luminous intensity (mcd) TYP.	temperature		
2.8 × 1.2 (t = 0.8)	(0.30, 0.29)	GM4BW853A0A*1	1 900	_	-	_	_		
Side view type	(0.30, 0.29)	GM4BW853B0A*1	2 200	_	-	_	_		
	(0.20, 0.20)	GM4BW653A0A*1	1 900	_	-	_	_		
$3.85 \times 1.0 \text{ (t = 0.6)}$ Side view type	(0.30, 0.29)	GM4BW653B0A*1	2 200	_	-	_	_		
Gido iioii iypo	(0.29, 0.28)	-	-	_	GM4BN653C0A*1, 4	1 700	_		
	(0.31, 0.31)	GM5BW96382A*1	2 300	_	-	_	_		
	(0.34, 0.36)	GM5BW96385A*1	2 600	_	-	_	_		
	(0.29, 0.28)	GM5BW96387A*1	2 000	_	-	_	_		
$3.2 \times 2.8 \ (t = 1.9)$	(0.338, 0.365)	GM5BW97330A*2	6 400	5 300	-	_	_		
	(0.312, 0.311)	GM5BW97332A*2	5 800	6 700	-	_	_		
	(0.283, 0.262)	GM5BW97333A*2	5 100	11 500	-	_	_		
	(0.3398, 0.3472)	_	_	_	GM5BN97330A*2,4	6 000	5 200		
3.2 × 2.8 (t = 1.4)	(0.32, 0.33)	GM5BW94370A*3	5 200	_		_	_		

GM4BW853A0A series, GM4BW653A0A series, GM4BN653C0A, GM5BW96382A, GM5BW96385A, GM5BW96387A: IF = 20 mA

GM5BW96382A, GM5BW96385A, GM5BW96387A, GM5BW97330A series, GM5BW94370A, GM5BN97330A: Tc = 25°C



■ High-Luminosity Surface Mount LEDs (RGB 3-color) (Taped Models Only) $(Tc = 25^{\circ}C)$

Resin type WA Colored transparency Colorless transparency Outline dimensions Red + Green + Blue Milky diffusion Colored diffusion (mm) Luminous intensity (mcd) TYP. $1.6 \times 1.6 (t = 0.55)$ GM1WA55311A*1 20/70/23 ☆GM5WA94320A*2 3.2×2.8 (t = 1.4) (2 300) [Mixed color] GM4WA25300A*3 $5.0 \times 2.5 \ (t = 2.5)$ 2 200 [Mixed color]

^{*3} GM4WA25300A: IF = 21 mA (Red), IF = 25 mA (Green), IF = 7 mA (Blue)



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GM5BW97330A series, GM5BN97330A: IF = 20 mA/chip

^{*3} GM5BW94370A: IF = 25 mA/chip

GM4BN653C0A and GM5BN97330A are high-NTSC-ratio products.

GM1WA55311A: IF = 5 mA (Red, Green, Blue)

GM5WA94320A: IF = 20 mA (Red), IF = 20 mA (Green), IF = 7 mA (Blue)



ZENIGATA LEDS FOR LIGHTING



■ ZENIGATA LEDs for Lighting (ZENIGATA is a registered trademark or a trademark of Sharp Corporation) in Japan, the United States and/or other countries.

<4W class> $(Tc = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW5BMC27KG4	2 700			300	
	GW5BMC30KG4	3 000			310	
15.0×12.0 (t = 1.6)	GW5BMC40KG4	4 000	9.6	400	330	82
((= 1.0)	GW5BMC50KG4	5 000			340	
	GW5BMC65KG4	6 500			340	

<6W class> $(Tc = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW5BMF27K04	2 700			520	
	GW5BMF30K04	3 000			535	
15.0×12.0 (t = 1.6)	GW5BMF40K04	4 000	12.3	520	570	82
((= 1.0)	GW5BMF50K04	5 000			585	
	GW5BMF65K04	6 500			585	

<9W class> (Tc = 25°C)

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW5BMJ27K04	2 700			720	
	GW5BMJ30K04	3 000			740	
15.0×12.0 (t = 1.6)	GW5BMJ40K04	4 000	18.6	480	780	82
((= 1.0)	GW5BMJ50K04	5 000			800	
	GW5BMJ65K04	6 500			800	

<15W class> $(Tc = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW5DMA27M04	2 700			1 350	83
	GW5DMA30M04	3 000			1 400	03
	GW5DLA40M04	4 000			1 520	82
	GW5DLA50M04	5 000			1 550	
24.0 × 20.0	GW5DLA65M04	6 500	37	400	1 550	
(t = 1.8)	GW5DGA27M04	2 700	31	400	1 150	93
	GW5DGA30M04	3 000			1 170	93
	GW5DGA40M04	4 000			1 230	92
	GW5DGA50M04	5 000			1 250	90
	GW5DGA65M04	6 500			1 250	90

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ZENIGATA LEDS FOR LIGHTING

☆New product



<25W class>

 $(Tc = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GW5DMC27M04	2 700			2 300	83
	GW5DMC30M04	3 000			2 370	
	GW5DLC40M04	4 000			2 550	
	GW5DLC50M04	5 000			2 600	82
24.0 × 20.0	GW5DLC65M04	6 500	37	700	2 600	
(t = 1.8)	GW5DGC27M04	2 700	31	700	1 910	93
	GW5DGC30M04	3 000			1 950	93
	GW5DGC40M04	4 000			2 050	92
	GW5DGC50M04	5 000			2 080	90
	GW5DGC65M04	6 500			2 080	90

<50W class>

(Tc = 25°C)

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	☆GW5DME27MR5	2 700			4 300	83
	☆GW5DME30MR5	3 000			4 430	03
	☆GW5DLE40MR5	4 000			4 770	
	☆GW5DLE50M05	5 000			4 880	82
24.0×20.0	☆GW5DLE65M05	6 500	50	050	4 880	
(t = 1.8)	☆GW5DGE27MR5	2 700	50	950	3 590	00
	☆GW5DGE30MR5	3 000			3 670	93
	☆GW5DGE40MR5	4 000			3 850	92
	☆GW5DGE50M05	5 000			3 900	90
	☆GW5DGE65M05	6 500			3 900	90



GW5BMC27KG4 series



GW5BMF27K04 series



GW5BMJ27K04 series



GW5DMA27M04 series GW5DGA27M04 series



GW5DMC27M04 series GW5DGC27M04 series



GW5DME27MR5 series GW5DGE27MR5 series

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SURFACE MOUNT LEDs FOR LIGHTING / SURFACE MOUNT LEDs FOR LIGHTING (RGB 3-COLOR)



■ Surface Mount LEDs for Lighting (Taped Models Only)

(Tc = 25°C)

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.	Average color rendering index Ra TYP.
	GM2BB27QKAC	2 700			29.5	
	GM2BB30QKAC	3 000		400	31	
	GM2BB35QKAC	3 500			32	
	GM2BB40QKAC	4 000			33.5	
	GM2BB45QKAC	4 500		100	34.5	
	GM2BB50QKAC	5 000	2.95		35.5	
	GM2BB57QKAC	5 700			35	
2.8×2.8	GM2BB65QKAC	6 500			33.5	83
(t = 1.9)	GM2BB27QK0C	2 700	2.95		44	03
	GM2BB30QK0C	3 000			46	
	GM2BB35QK0C	3 500			48	
	GM2BB40QK0C	4 000		450	50	
	GM2BB45QK0C	4 500		150	51	
	GM2BB50QK0C	5 000			53	
	GM2BB57QK0C	5 700			52	
	GM2BB65QK0C	6 500			50	

 $(Tc = 25^{\circ}C)$

Outline dimensions (mm)	Model No.	Color temperature (K) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Luminous intensity (mcd) TYP.	Average color rendering index Ra TYP.
	GM5SAE27P0A	2 700			2 000	85
	GM5SAE30P0A	3 000			1 900	85
	GM5SAE35P0A	3 500	3.2	20	2 100	83
3.2×2.8	GM5SAE40P0A	4 000			2 100	83
(t = 1.9)	GM5SAE45P0A	4 500	3.2	20	2 200	83
	GM5SAE50P0A	5 000			2 200	83
	GM5SAE57P0A	5 700			2 200	80
	GM5SAE65P0A	6 500			2 200	80

■ Surface Mount LEDs for Lighting (RGB 3-color) (Taped Models Only)

 $(I F = 20 \text{ mA/chip}, Tc = 25^{\circ}C)$

Outline dimensions (mm)	dimensions Model No.		Luminous intensity (mcd) TYP.	
		Red	680	
3.2×2.8 (t = 1.4)	GM5WA94315A	Green	1 500	
(1-11)		Blue	450	



GM2BB27QKAC series GM2BB27QK0C series



GM5SAE27P0A series



GM5WA94315A

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LEDs FOR LCD BACKLIGHT

☆New product



■ LEDs for LCD Backlight

(Tc = 25°C)

Outline dimensions (mm)	Model No.	Color coordinates (x, y) TYP.	Forward voltage (V) TYP.	Forward current (mA) TYP.	Total luminous flux (lm) TYP.
2.8 × 2.8 (t = 1.9)	☆GM2BB0CH10A	(0.273, 0.244)	3.5	150	36.9
4.2 × 1.4 (t = 0.8)	☆GM5FM0CP10A	(0.260, 0.235)	3.2	130	36





GM2BB0CH10A

GM5FM0CP10A

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★Under development



■ Laser Diodes

♦Model Configurations

• For applications other than optical discs

		Pack	kage
Wavelength (nm)	Absolute maximum ratings (mW)*1		
		ø5.6 mm Metal type	ø3.3 mm Metal type
660 band	10	GH06510F2B	GH06510F4A
	15	GH07815D2K	_
785 band	15	GH3S215D2B	-
roo Danu	25	GH07825D2K	-
	25	GH3S225D2B	_

^{*1} The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use.

• For optical disc use*3

		Package			
Wavelength (nm)	Absolute maximum ratings (mW)*1				
		ø5.6 mm Metal type	ø3.3 mm Metal type	1.8 mm t Resin type	
	20	GH04020D2A	GH04020C4A	_	
405 band	320*2	GH04P32A2G	GH04P32A4G	-	
	430*2	GH04P43A2G	GH04P43A4G	-	
660 band	300*2	★GH06P30C1C	_	_	
660 band	350* ²	_	-	GH16P35A8C	
785 band	280*2	★GH07P28F1C	GH07P28F4C	_	
Dual-wavelength 660/785 band	350/400*2	-	-	GH33540A8C	

The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use.

♦ Specifications

• Laser diodes lineup for applications other than optical discs

 $(Tc = 25^{\circ}C)$

	Wave-	Absolute maximum ratings*1		Applications	Terminal
Model No.	length (nm)	CW (Continuous wave)	CW (Continuous wave)		connec- tions
GH06510F4A	660	10	ø3.3 mm CAN package, operating temperature: 70°C MAX., with built-in monitor PD	Bar code reader, laser displacement gauge, etc.	Α
GH06510F2B	band	10	ø5.6 mm CAN package, operating temperature: 75°C MAX., with built-in monitor PD	Bar code reader, laser displacement gauge, etc.	G
GH07815D2K		15	ø5.6 mm CAN package, operating temperature: 60°C MAX., with built-in monitor PD	Printer, copier, complex machine	- D
GH07825D2K	785	25	ø5.6 mm CAN package, operating temperature: 60°C MAX., with built-in monitor PD	Printer, copier, complex machine	
GH3S225D2B	band	25	ø5.6 mm CAN package, operating temperature: 60°C MAX., with built-in monitor PD	Printer, copier, complex machine	F
GH3S215D2B		15	ø5.6 mm CAN package, operating temperature: 60°C MAX., with built-in monitor PD	Printer, copier, complex machine	F

^{*1} The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use.

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Optical pulse power output MAX. (mW)

New models for optical disc use are introduced frequently, and it is possible the model you wish to order may no longer be in production. Sample sales may not be available, either. We ask for your understanding in this matter.



LASER DIODES

★Under development



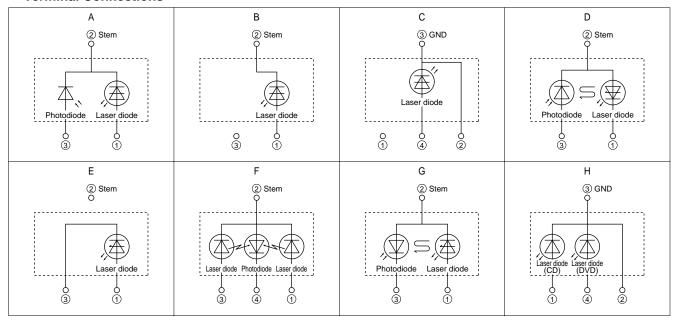
• Laser diodes lineup for optical disc use*2

(Tc = 25°C)

Model No.	Wavelength	Absolute ratin		- Features	Applications	Terminal
Model No.	(nm)	CW (Continuous wave)	Pulse	reatules	Applications	connec- tions
GH04020D2A		20	_	ø5.6 mm CAN package, operating temperature: 75°C MAX.	Blu-ray disc playback	Α
GH04020C4A		20	_	ø3.3 mm CAN package, operating temperature: 75°C MAX.	Blu-ray disc playback	Α
GH04P32A2G	405 band	160	320	ø5.6 mm CAN package, operating temperature: 80°C MAX. (pulse drive)	Blu-ray disc recording	Е
GH04P32A4G	405 band	160	320	ø3.3 mm CAN package, operating temperature: 80°C MAX. (pulse drive)	Blu-ray disc recording	Е
GH04P43A2G		160	320	ø5.6 mm CAN package, operating temperature: 80°C MAX. (pulse drive)	Blu-ray disc recording	Е
GH04P43A4G		160	320	ø3.3 mm CAN package, operating temperature: 80°C MAX. (pulse drive)	Blu-ray disc recording	Е
★GH06P30C1C	CCO band	100	250	ø5.6 mm CAN package, operating temperature: 75°C MAX. (pulse drive)	Double-layer DVD 8× to 16× recording	В
GH16P35A8C	660 band	125	350	1.8 mm frame package, operating temperature: 80°C MAX. (pulse drive)	Double-layer DVD 8× to 16× recording	С
★GH07P28F1C	705 hand	150	280	ø5.6 mm CAN package, operating temperature: 80°C MAX. (pulse drive)	CD-R/RW (MAX. 48× to 52× writing)	В
GH07P28F4C	785 band	150	280	ø3.3 mm CAN package, operating temperature: 80°C MAX. (pulse drive)	CD-R/RW (H/H, slim dual-purpose) (MAX. 48× to 52× writing)	В
01100540400	Dual- wavelength	125	350	1.8 mm frame package, operating temperature: 80°C MAX.	Double-layer DVD 8× to 16× recording	
GH33540A8C	660/785 band	200	400	(pulse drive)	CD-R/RW (H/H, slim dual-purpose) (MAX. 48× to 52× writing)	Н

^{*1} The absolute maximum ratings are the limits that are not to be exceeded under any condition whatsoever, whether in testing or in actual use. For recommended optical power output, consult the specification sheet or data sheet for each model.

• Terminal Connections



Notice
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Except where specially indicated, models listed on this page comply with the RoHS Directive*. For details, please contact SHARP.

*RoHS Directive: Prohibits use of lead, cadmium, hexavalent chromium, mercury and specific brominated flame retardants (PBBs and PBDEs), with certain exceptions.

Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device.

New models for optical disc use are introduced frequently, and it is possible the model you wish to order may no longer be in production. Sample sales may not be available, either. We ask for your understanding in this matter.

■ Europe: LNBs for Satellite Broadcast

♦ Features

- (1) Wide band type receiving all broadcasting channels (analog & digital) in Europe. [Universal LNB]
- (2) Originally developed feed-horn waveguide makes the wide-band, low-noise characteristics possible.
- (3) One of the industry's most compact and lightweight package
- (4) Low dissipation current design for energy saving [80 mA (TYP.): BS1K0EL150A]

♦ Specifications

Destination		Europe, Astra/Eutelsat Satellite etc.				
Receiving polarization		Horizontal/Vertical polarization				
Model No. <type></type>		BS1R8EL500A <4 output>	BS1R8EL400A <4 output>	BS1K0EL250A <2 output>	BS1K0EL150A <1 output>	
Input frequency (GHz)			10.7 to 11.7 [Low band],	11.7 to 12.75 [High band]	_	
Output frequency (MHz)			950 to 1 950 [Low band],	1 100 to 2 150 [High band]		
Local oscillation frequen	cy (GHz)		9.75 [Low band],	10.6 [High band]		
NF (dB)		0.7 ((TYP.)	0.4 (TYP.)	
Conversion gain (dB)			56 (TYP.)			
Phase noise		-55 dBc/Hz at 1 kHz (TYP.)				
Cross-polar discrimination	on (dB)	25 (TYP.)				
Supply voltage (V DC)	Vertical polarization	11.5 to 14.0 (0/22 kHz)				
(Polarization switching)	Horizontal polarization	16.0 to 19.0 (0/22 kHz)				
Dissipation current (mA)		210 (TYP.)/250 (MAX.)	310 (TYP.)/350 (MAX.)	190 (TYP.)/250 (MAX.)	80 (TYP.)/120 (MAX.)	
Waveguide		Feed-horn (F/D = 0.6)				
Output impedance (Ω)		75				
Output connector (F-type)		4-output (H/H, H/L, V/H, V/L)	4-output (H/V, High and low switching)	2-output (H/V, High and low switching)	1-output (H/V, High and low switching)	
Outline dimensions (W)	\times (D) \times (H) (mm)	133.0 × 103.6 × 60.0	133.0 × 103.6 × 60.0	135.0 × 90.0 × 58.0	103.0 × 60.0 × 60.0	
Weight (g)		Approx. 255	Approx. 256	Approx. 245	Approx. 90	



JAPAN/ASIA/AUSTRALIA: LNBs FOR CS DIGITAL SATELLITE BROADCAST / JAPAN: LNBs FOR BS/CS 110° SATELLITE BROADCAST



■ Japan/Asia/Australia: LNBs for CS Digital Satellite Broadcast

♦ Specifications

Destination		Japan, Asia, Australia, CS Satellite	
Receiving polarization		Horizontal/Vertical polarization	
Model No. <type></type>		BS1R8AR100A	
Input frequency (GHz)		11.70 to 12.75	
Output frequency (MHz)		1 000 to 2 050	
Local oscillation frequen	ncy (GHz)	10.7	
NF (dB)		0.7 (TYP.) / 0.9 (MAX.)	
Conversion gain (dB)		55 to 64	
Phase noise		-75 dBc/Hz at 1 kHz (TYP.)	
Cross-polar discrimination	on (dB)	25 (TYP.)	
Supply voltage (V DC)	Vertical polarization	11.5 to 14.0	
(Polarization switching)	Horizontal polarization	16.0 to 19.0	
Dissipation current (mA)		80 (TYP.)/120 (MAX.)	
Waveguide		Feed-horn (F/D = 0.6)	
Output impedance (Ω)		75	
Output connector (F-typ	e)	1-output (H/V switching)	
Outline dimensions (mm	1)	107.3 (W) × 60 (D) × 60 (H)	
Weight (g)		Approx. 110	



■ Japan: LNBs for BS/CS 110° Satellite Broadcast

♦ Features

- (1) Can receive 2 satellite broadcasts of 110° BS/CS digital [Employs wide-band (1 GHz) circular' linear polarization conversion technology (septum waveguide structure)]
- (2) Outstanding noise figure (NF) characteristics enabling compact design of antenna diameter. [NF: 0.45 dB (TYP.)/BS1F6JU300A]
- (3) Low dissipation current design for improved energy saving. [80 mA (TYP.)]

♦ Standard Specifications

Destination		Ja	pan BS/CS 110° Satel	lite
Receiving polarization		Right circular polarization		Right/Left circular polarization
Model No.		BS1F9JU300A	BS1F6JU300A	BS1F6JP100A
Input frequency (GHz)			11.71023 to 12.751	
Output frequency (MHz)			1 032.23 to 2 073	
Local oscillation frequen	cy (GHz)		10.678	
NF (dB)		0.45 (TYP.)	/ 0.6 (MAX.)	0.7 (TYP.) / 1.1 (MAX.)
Conversion gain (dB)		48 to 58		
Phase noise		-65 dBc/Hz at 1 kHz (TYP.)		
Cross-polar discrimination	on (dB)	25 (TYP.)/20 (MIN.)		
Supply voltage (V DC)	Right circular polarization	9.5 to 18.0		13.5 to 16.5
(Polarization switching)	Left circular polarization	_		9.5 to 12.0
Dissipation current (mA)		80 (TYP.)/110 (MAX.)		
Waveguide		Feed-horn (F/D = 0.5)		
Output impedance (Ω)		75		
Output connector (F-type)		1-00	utput	1-output (R/L switching)
Outline dimensions (mm)		96 (W) × 47 (D) × 71 (H)		96 (W) × 53.07 (D) × 71 (H)
Weight* (g)		Approx. 100 Approx.		Approx. 130

BS1F9JU300A * Outer cabinet is made upon request.

^{*} Not including outer cabinet





■ Digital DBS Front-End Units

♦ Features

- (1) Equipped with a direct conversion IC developed by Sharp. Reliability is improved by reducing power consumption and component counts.
- (2) Wide-band reception design also covering CS broadcast band. [Reception frequency: 950 to 2 150 MHz]
- (3) Wide product line-up of LINK integrated types for contributing to set development time reduction. [Compatible with DVB-S/DVB-S2/ISDB-S/ABS-S demodulation]
- (4) User support tools can be provided. [Sample/evaluation boards and software are available.]

◆ Standard Specifications <IQ output type>

Destination	Global (ISDB-S/	DVB-S2/ABS-S)	
Input type	1-input/1-loop through output	1-input	
Model No.	BS2S7HZ7903	BS2S7HZ6903	
Input frequency (MHz)	950 to	2 150	
Input signal level (dBm)	-65 to	o –25	
The 1st intermediate frequency (MHz)	Zero-IF (Direct conversion)		
Base band frequency bandwidth (MHz)	10 to 30, 2.0 MHz step (BB LPF)		
RF input local leak (dBm)	-68 and below		
Output type	1/1	Q	
Noise figure (dB)	8 (T	YP.)	
Tuning voltage (V DC)	Shared with a 3.3	3 V power source	
Supply voltage (V DC)	3.3		
LNB power supply	DC 25 V, 400 mA (MAX.)		
Input impedance (Ω)	75		
Outline dimensions (mm)	32.6 (W) × 28.0	0 (D) × 13.0 (H)	



◆ Standard Specifications <NIM type>

<u>•</u>			
Destination	Europe (DVB-S2)		
Input type	1-input, 1-loop through output	1-input	
Model No.	BS2F7VZ7702	BS2F7HZ1266	
Input frequency (MHz)	950 to	2 150	
Input signal level (dB m)	-65 to	o –25	
The 1st intermediate frequency (MHz)	Zero-IF (Direc	ct conversion)	
Base band frequency bandwidth (MHz)	10 to 30, 2.0 MHz step (BB LPF)		
RF input local leak (dB m)	-70 and below		
Output type	Transport strean	n (parallel/serial)	
Symbol rate (M baud)	45 (N	1AX.)	
Noise figure (dB)	8 (TYP.)	5 (TYP.)	
Tuning voltage (V DC)	Shared with a 3.3	3 V power source	
Supply voltage (V DC)	3.3, 1.2 3.3, 1.0		
LNB power supply	25 V DC, 400 mA (MAX.)		
Input impedance (Ω)	75		
Outline dimensions (mm)	57.5 (W) × 29.6 (D) × 13.2 (H) 56.0 (W) × 34.9 (D) × 10.0 (H)		

^{*} Contact SHARP for custom design product.



^{*} Contact SHARP for custom design product.



FRONT-END UNITS FOR ISDB-T/DVB-T/CTTB/CATV **AND DIGITAL SATELLITE**



■ Front-End Units for ISDB-T/DVB-T/CTTB/CATV and Digital Satellite

♦ Features

- (1) Low phase noise characteristics, high elimination of adjacent channel interference.
- (2) Compact, low power consumption.

♦ Standard Specifications

Destination	Japan (ISDB-T/S)			
Model No.	VA4M5	JC2116	VA4M6	JC2103
	Digital terrestrial	Digital satellite	Digital terrestrial	Digital satellite
Number of tuners	1	1	2	2
Input frequency (MHz)	93 to 767	950 to 2 150	93 to 767	950 to 2 150
Output type	Low-IF	I,Q	Low-IF	I, Q
Noise figure (dB)		6 (*	TYP.)	
Phase noise (dBc/Hz)	-90 (TYP.) at 10 kHz offset	-85 (TYP.) at 10 kHz offset	-90 (TYP.) at 10 kHz offset	-85 (TYP.) at 10 kHz offset
Supply voltage (V DC)	1.8, 3.3	3.3	1.8, 3.3	3.3
Power consumption (W)	0.5	0.6	1	1.1
Outline dimensions (mm)	50.0 (W) × 45.0 (D) × 5.8 (H)			







■ Front-End Units for ISDB-T/DVB-T/CTTB/CATV

♦ Features

- (1) Low phase noise characteristics, high elimination of adjacent channel interference.
- (2) Compact, low power consumption.
- (3) Other types are available with various chassis forms (vertical or horizontal type) and input connectors (F or DIN type), etc.

♦ Standard Specifications

Destination	Europe/As	ia (DVB-T2)	China (DTMB)	Brazil (ISDB-TB)	
Madal Na	Terrestrial	Terrestrial/Satellite	Terrestrial	Terrestrial	
Model No.	VA4M1EX6158	VA4S5DC5072	VA4N1CD1136	VA4N1BD1108	
Input frequency (MHz)	47 to 868	47 to 868 950 to 2 150	47 to 868 54 to 868		
Output type	TS DIF		D	DIF	
	_	CVBS/SIF	AIF		
Noise figure (dB)	Terrestrial: 6 (MAX.)	Terrestrial: 6 (MAX.) Satellite: 6 (TYP.)	Terrestrial: 6 (MAX.)		
Phase noise (dBc/Hz)	Terrestrial: -90	Terrestrial: –90 Satellite: –85	Terrestrial: -90		
Power consumption (W)	1.1	Terrestrial: 1.0 Satellite: 0.5	Terrestrial: 1.26 Terrestrial: 1.16		
Supply voltage (V DC)	3.3, 1.8, 1.2	3.3, 1.8	3.3		
Outline dimensions (mm)	47 (W) × 30 (D) × 13 (H)	32 (W) × 40 (D) × 6.7 (H)	32 (W) × 36 (D) × 6.7 (H) 34 (W) × 37 (D) × 6.7		



FRONT-END UNITS FOR DIGITAL TERRESTRIAL AND ANALOG TERRESTRIAL BROADCASTING



■ Front-End Units for Digital Terrestrial and Analog Terrestrial Broadcasting

♦ Features

Contributing to the development of thinner LCD TVs and similar products by combining compatibility with digital and analog terrestrial broadcasts into a single unit.

♦ Standard Specifications

Destination		Brazil*1	China
Model No.		VA4A1BC5038	VA1P1CD8402
Input frequency (MHz)		47 to 866	47 to 870
Analog intermediate	Video	45.75	38.0
frequency (MHz)	Audio	41.25	D/K: 31.5, I: 32.0, B/G: 32.5, M/N: 33.5
Digital intermediate frequency (MHz) 44		44	36
Digital IF bandwidth (MHz)	Digital IF bandwidth (MHz) 6		8
Phase noise (dBc/Hz)		-90 (TYP.) at 10 kHz offset	-85 (TYP.) at 10 kHz offset
Supply voltage (V DC)		1.8, 3.3	5.0
Noise figure (dB)	Noise figure (dB) 6 (TYP.)		
Channel selection system		PLL (I ² C	C-bus)*2
Outline dimensions (W) \times (D)	× (H) (mm)	40 × 36.6 × 5	70.0 × 37.0 × 10.0

Transport stream output front-end units with built-in OFDM demodulation IC

^{*2} I2C-bus is a trademark of Philips Corporation.



♦ Features

Universal specifications compatible with various broadcasting systems all over the world

Digital: DVB-T/T2, DVB-C, ATSC, ISDB-T, DTMB Analog: NTSC-M/N, PAL-B/G/I/DK, SECAM-L, L'

♦ Standard Specifications

Destination		Japan	Global	
Model No.		VA4D1JA2160	VA4M1DA5167	
Input frequency (MHz)		93 to 767	47 to 868	
Digital terrestrial		D	IF	
Output type	Analog terrestrial	_	AIF	
Noise figure (dB)		6 (MAX.)	4 (TYP.)	
Phase noise (dBc/Hz)		-90 (TYP.)		
Supply voltage (V)		1.8, 3.3	3.3	
Device concumention (M)	Digital terrestrial	0.5	T.B.D.	
Power consumption (W)	Analog terrestrial	_	T.B.D.	
Outline dimensions (W) × (I	O) × (H) (mm)	32.0×2	2.0 × 6.7	
Outline dimensions (W) × (I	, , , , ,	32.0 × 2	2.0 × 6.7	

VA4D1JA2160

(For connector shape or facing side, analog output format, etc.)

^{*} Contact SHARP for custom design product.





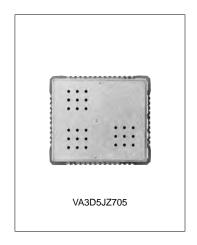
■ Full-Seg Tuner Module for Diversity Reception

♦ Features

Compact package, enabling 4-diversity reception $(35.0 \times 31.0 \times 2.95 \text{ mm})$

♦ Standard Specifications

Destination		Japan	
Model No.		VA3D5JZ705	
Туре		Built-in diversity demodulator for four signal reception	
Input frequency (MHz)	470 to 770	
IF frequency (MHz)		4	
Output type		Transport stream	
Input sensitivity	During diversity reception	-88 (TYP.) (64QAM, CR = 3/4)	
(dBm)	During single reception	-82 (TYP.) (64QAM, CR = 3/4)	
Supply voltage (V)		Vcc1: 1.2, Vcc2: 3.3 (IO: 3.3)	
Power consumption (\	N)	1.24 (TYP.)	
Operating temperatur	e (°C)	-40 to 85	
Control interface		I ² C-bus*1	
Outline dimensions (W) × (D) × (H) (mm)		35.0 × 31.0 × 2.95	



Diversity demodulator for two signal reception is also available.

■ MPEG Module

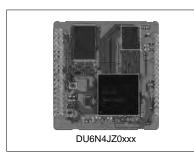
♦ Features

- (1) An OFDM demodulator, MPEG decoder and video encoder circuit are combined into a single package for reception of ISDB-T.
- (2) Comes with built-in standard reception software, with a simple EPG included, based on the ARIB standard.

Compatible with Ministry of Internal Affairs and Communications specifications for a "simple tuner."

Compatible also with full HD output.

(3) Optional One-seg broadcasting compatibility is available for diversity-reception and integrated-RF types.



♦ Standard Specifications

Туре	For digital terrestrial	For digital terrestrial/BS/CS	For digital terrestrial Compatible with diversity reception	For digital terrestrial only Integrated RF	
Model No.	DU6N4JZxxxx	DU6U4JZxxxx	DU6U4JZxxxx	DU6F4JZxxxx	
Circuit configuration	[RI	F (separate body) +] OFDM + MF	EG	RF + OFDM + MPEG	
CATV (pass-through)	(0	_	0	
Video output		Componen	t (Full HD)*		
Audio output		Analog st	ereo (L/R)		
B-CAS		Built-in conf	rol software		
EPG		Built-in si	mple EPG		
ES (Engineering service)		(
Firm ware upgrades		(
Supply voltage (V)		3.3/1	8/1.0		
Power consumption (W)	1.1 (TYP.) 1.5 (TYP.)				
Outline dimensions (mm)	58 (W) × 60 (D) × 7 (H) 60 (W) × 70 (D) × 7 (H)			78 (W) × 55.5 (D) × 7 (H)	
Recommended front-end	VA4D1JA2160	VA1N5JF8627	VA3D5JZ705	-	

^{*} Switchable between S-Video (Y/C) and component (SD or HD).

^{*1} I2C-bus is a trademark of Philips Corporation.

MPEG MODULE WITH VIDEO RECORDING FUNCTION / **ONE-SEG TUNER MODULE**



■ MPEG Module with Video Recording Function

♦ Features

- (1) Comes with built-in USB interface for recording. Capable of recording a counter program if a double tuner is installed on the device as well.
- (2) Fully compliant with ARIB standard. Compatible with interactive data broadcasting.



♦ Standard Specifications

Time	For digital terrestrial/BS/CS					
Type	Double type	Single type				
Model No.	DU6R4JZxxxx					
CATV (pass-through)	(
Video output / Audio output	Component (Full HD)*	* / Analog stereo (L/R)				
B-CAS	Built-in control software					
EPG	Built-in EPG					
ES (Engineering service))				
Firm ware upgrades)				
Supply voltage (V)	5/3.3/1.8/1.2/1.05					
Power consumption (W)	2.9					
Outline dimensions (mm)	65 (W) × 80 (D) × 7 (H) 65 (W) × 70 (D) × 7 (H)					
Recommended front-end	VA4M6JC2103 VA4M5JC2116					

^{*} Switchable between S-Video (Y/C) and component (SD or HD).

■ One-Seg Tuner Module

♦ Features

(1) High sensitivity: -100 dBm (13 seg, QPSK CR: 2/3)

(2) Compact and thin design: $5.4 \times 5.4 \times 1.0$ mm

41 mW (with software power control) (3) Low power consumption:

(4) Output interface: TS serial output



♦ Standard Specifications

Destination	Japan
Model No.	VA3A5JZ967
Input frequency (MHz)	470 to 770 (UHF: 13 to 62)
Input signal level (dBm)	-100 (13 seg, QPSK CR: 2/3)
Outline dimensions (mm)	5.4 (W) × 5.4 (D) × 1.0 (H)
Supply voltage (V DC)	1.2 (RF) 1.2 (OFDM Core) 1.62 to 3.6 (I/O)
Power consumption (mW)	41 (TYP.)
Operating temperature (degree C)	-20 to 65
Control I/F	I2C-bus*1

^{*1} I²C-bus is a trademark of Philips Corporation.



■ Embedded Wireless LAN-Bluetooth Combo Module

♦ Features

- (1) A two-in-one module compliant with the latest Bluetooth standard (v2.1) Wireless LAN: 11b/g, Bluetooth: v2.1+EDR* (3 Mbps)
- (2) Compatible with IEEE802.15.2 standard compliant wireless LAN and Bluetooth coexistence functions.
- (3) Compact and thin design $9.0 \times 9.0 \times 1.25$ mm





♦ Standard Specifications

Model No.	DC2K1DZ172					
Wireless communication standard	WLAN (IEEE802.11b/g) Bluetooth v2.1+EDR					
Outline dimensions (mm)	9.0 (W) × 9.0 (D) × 1.25 (H) (LTCC)					
Frequency (MHz)	2 400 to 2 483.5 2 402 to 2 480					
Data rate (Mbps)	1/2/5.5/11 & 6/9/12/18/24/36/48/54	1/2/3				
Number of channels	13	79				
Transmission output (dBm)	11g: +14/11b: +18	Class 2				
Receiving sensitivity (dBm)	TYP.: -84 (11 Mbps, PER 8%) TYP.: -71 (54 Mbps, PER 10%)	TYP:: -70 (1 Mbps, BER 0.1%) TYP:: -70 (2 Mbps, BER 0.01%) TYP:: -70 (3 Mbps, BER 0.01%)				
Security	WEP TKIP AES	by driver software				
Interface	SPI/SDIO PCM (64 kbps), SPI/					

Consult separately regarding driver software.



INFRARED DATA COMMUNICATION DEVICE LINEUP



■ Infrared Data Communication Device Lineup

Communication system	Transmission speed	Transmission distance	Features	Operating supply voltage	Model No.
IrDA data	FIR 4 Mb/s (Receiver only)	250 cm		3.0 to 3.6 V	GP2W4020XPMF
(IrDA 1.x)		150 cm		3.0 to 3.6 V	GP2W4010YP0F
	FIR 4 Mb/s (Integrated receiver				
	and transmitter type)	100/20 cm	LP/MP/HP mode switching function LP/HP mode switching function,	2.7 to 5.5 V	GP2W1001YP0F▲
		35/21 cm	remote control transmission function, thin (height: 1.5 mm)	2.6 to 3.6 V	GP2W3152YP0F
			LP/HP mode switching function, remote control transmission function, top view type (height: 1.75 mm)	2.6 to 3.6 V	GP2W3176XP0F
			LP/HP mode switching and remote control transmission functions	2.6 to 3.6 V	GP2W3120YP0F
		21 cm	LP/HP mode switching function	2.6 to 3.6 V	GP2W1320YP0F
		70/21 cm	LP/MP/HP mode switching and remote control transmission functions	2.6 to 3.3 V	GP2W3106YP0F
	SIR 115.2 kb/s (Integrated receiver and transmitter type)	100 cm	Compact, low dissipation current	2.4 to 5.5 V	GP2W0004YP0F▲/ GP2W0004XP0F▲
	SIR LP 115.2 kb/s (Integrated receiver and transmitter type)	21 cm	Built-in LED constant current circuit, 3-state output	2.0 to 3.6 V 1.7 to 2.5 V	GP2W0110VY GP2W0112VY

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.

■ Infrared Data Communication Devices

♦FIR Compliant Devices (Receiver Only)

Model No.	Communication system	Transmission speed	Description	Maximum reception distance*1 (cm)	Supply voltage (V DC)	Outline dimensions (mm)
GP2W4020XPMF	Uni-directional communication (receiving only)	4 Mb/s	IrSS™-compliant, receiving-only type	250	3 to 3.6	20.96 × 6.68 × 7.1
GP2W4010YP0F	Uni-directional communication (receiving only)	9.6 k to 4 Mb/s	IrSS™-compliant, receiving-only type	150	3 to 3.6	10 × 3.93 × 4.53

^{*1} Radiant intensity at transmitting side: 100 mW/sr





INFRARED DATA COMMUNICATION DEVICES

GP2W4020XPMF

GP2W4010YP0F

♦FIR Compliant Devices (Integrated Receiver and Transmitter Type)

Model No.	Communication system	Transmission speed	Description	Transmission distance (cm)	Supply voltage (V DC)	Outline dimensions (mm)
GP2W3152YP0F	Bi-directional (half-duplex) communication	9.6 k to 4 Mb/s	With remote control transmission function, LP/HP mode switching function	21/35	2.6 to 3.6	7.88 × 2.76 × 1.5
GP2W3176XP0F	Bi-directional (half-duplex) communication	9.6 k to 4 Mb/s	With remote control transmission function, top-view, LP/HP mode switching function	21/35	2.7 to 3.6	8.72 × 2.53 × 1.75
GP2W3120YP0F	Bi-directional (half-duplex) communication	9.6 k to 4 Mb/s	With remote control transmission function, LP/HP mode switching function	21/35	2.6 to 3.6	7.16 × 2.73 × 1.82
GP2W1001YP0F▲	Bi-directional (half-duplex) communication	9.6 k to 4 Mb/s	LP/MP/HP mode switching function	20/100	2.7 to 5.5	10.01 × 4.38 × 3.53
GP2W1320YP0F	Bi-directional (half-duplex) communication	9.6 k to 4 Mb/s	Compact, thin, low dissipation current (Icc: TYP. 0.45 mA)	21	2.6 to 3.6	7.16 × 2.73 × 1.82
GP2W3106YP0F	Bi-directional (half-duplex) communication	9.6 k to 4 Mb/s	With remote control transmission function, LP/MP/HP mode switching function	21/70	2.6 to 3.3	7.9 × 2.85 × 2.5

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.













GP2W3152YP0F

GP2W3176XP0F

GP2W3120YP0F

GP2W3106YP0F

GP2W1001YP0F▲

GP2W1320YP0F

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INFRARED DATA COMMUNICATION DEVICES



♦SIR Compliant Devices (Integrated Receiver and Transmitter Type)

Model No.	Communication system	Transmission speed	Description	Transmission distance (cm)	Supply voltage (V DC)	Outline dimensions (mm)
GP2W0004YP0F▲	Bi-directional (half-duplex) communication	9.6 k to 115.2 kb/s	Low dissipation current (Icc: 130 µA MAX.)	100	2.4 to 5.5	9.21 × 3.76 × 2.71
GP2W0004XP0F▲	Bi-directional (half-duplex) communication	9.6 k to 115.2 kb/s	Low dissipation current (Icc: 130 µA MAX.), top-view	100	2.4 to 5.5	9.21 × 3.35 × 3.8

The model marked with ▲ may not be available in the near future. Contact with SHARP for details before use.



♦SIR LP Compliant Devices (Integrated Receiver and Transmitter Type)

Model No.	Communication system	Transmission speed	Description	Transmission distance (cm)	Supply voltage (V DC)	Outline dimensions (mm)
GP2W0110VY	Bi-directional (half-duplex) communication	2.4 k to 115.2 kb/s	Low dissipation current (Icc: 120 µA MAX.)	21	2.0 to 3.6	6.8 × 2.35 × 2.1
GP2W0112VY	Bi-directional (half-duplex) communication	2.4 k to 115.2 kb/s	Low dissipation current (Icc: 120 µA MAX.)	21	1.7 to 2.5	6.8 × 2.35 × 2.1



Notice
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(PBBs and PBDEs), with certain exceptions.

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IR DETECTING UNIT FOR REMOTE CONTROL LINEUP (CLASSIFIED BY FORM)



■ IR Detecting Unit for Remote Control Lineup (Classified by Form)

	Paci	kage			Model No.	
Туре	Form	Detection position*5 (from PCB)	Features	Operating voltage: 3 to 5 V	Operating voltage: 5 V	Operating voltage: 3 to 5 V
IR detecting unit for remote control	Compact, thin typ SMD (4.5 × 5.0 ×					GP1USC3xXP series
	Compact type SMD (6.8 × 2.1 ×	(2.35 t mm)				GP1UF31 series
	Lead L bend with shield case (holder)	16.0 mm* ¹	Compact size	GP1LIE28YK0\/E corios	GP1UM28XK0VF series	GP1UE28xXKC4 series
	(Holder)	10.0 111111	· '	GFTUEZOXNUVF Selles	GF TOWIZONNOVE SELIES	GF TUEZOXANU4 SETIES
			Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	GP1UE28RK0VF series	GP1UM28RK0VF series	GP1UE28xRKC4 series
		12.0 mm* ²	Compact size	GP1UE27XK0VF series	GP1UM27XK0VF series	GP1UE27xXKC4 series
			Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	GP1UE27RK0VF series	GP1UM27RK0VF series	GP1UE27xRKC4 series
		6.8 mm*3	Compact size	GP1UE26XK0VF series	GP1UM26XK0VF series	GP1UE26xXKC4 series
			Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	GP1UE26RK0VF series	GP1UM26RK0VF series	GP1UE26xRKC4 series
	Lead straight with shield case (holder)	19.0 mm	Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	GP1UE29QK0VF series	GP1UM29QK0VF series	GP1UE29xQKC4 series
		9.6 mm	Compact size	GP1UE28YK0VF series	GP1UM28YK0VF series	GP1UE28xYKC4 series
			Compact size, Strengthened resistance to electromagnetic induction noise (Mesh type)	GP1UE28QK0VF series	GP1UM28QK0VF series	GP1UE28xQKC4 series
	Holderless	Lead straight 6.0 mm		GP1UX31QS series	GP1UX51QS series	GP1UXC4xQS series
		Lead L bend*4 5.3 mm		GP1UX31RK series	GP1UX51RK series	GP1UXC4xRK series

- *1 Mesh type (strengthened resistance to electromagnetic induction noise): 16.4 mm
- *5 Lead straight: Distance from lens center to mounting board upper surface No mesh lead L bend: Distance from tip of lens to mounting board upper surface Mesh-type lead L bend: Distance from tip of mesh to mounting board upper surface

























GP1UE29xQKC4 GP1UX31QS, (GP1UX31QS, C

GP1UXC4xQS (GP1UX31QS, GP1UX51QS)

GP1UF31xXP0F (GP1UF31xYP0F)

GP1USC3xXP



IR DETECTING UNITS FOR REMOTE CONTROL



■ IR Detecting Units for Remote Control

(Ta = 25°C)

Series No. Voc (V) Topr (°C) Vol (V) Port (°C) Voc (W)	
Surface-mount type, Reflow soldering compatible GP1USC3xXP O to 6.0 GP1USC3xXP O to	Termin layou
Compatible GP1USC3xXP 0 to 6.0 -30 to +85 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.4.5 x 1.3 With shield case (holder), 3 to 5 V drive (New type) GP1UE28xXKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 16.0 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.4 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.4 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.4 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.4 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.4 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.4 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.0 x 12.5 (9.1 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.0 x 12.5 (9.1 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.0 x 12.5 (9.1 GP1UE28xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 x 9.0 x 12.5 (9.1 GP1UE29xYKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 16.4 GP1UE29xYKC4 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 x 9.6 x 12.0 GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6	_
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With shield case (holder), 3 to 5 V drive (New type) GP1UE28xXKC4	
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With shield case (holder), 3 to 5 V drive, Strengthened resistance to electromagnetic induction noise (New type) GP1UE28xRKC4 GP1UE28xRKC4 GP1UE28xRKC4 GP1UE28xRKC4 GP1UE28xRKC4 GP1UE28xRKC4 GP1UE29xQKC4	
With shield case (holder), 3 to 5 V drive, Strengthened resistance to electromagnetic induction noise (New type) GP1UE28xRKC4 O to 6.0 -10 to +70 2.7 to 5.5 O.6 Vcc-0.5 O.45 *3 5.6 × 9.6 × 12.4 GP1UE28xRKC4 O to 6.0 -10 to +70 2.7 to 5.5 O.6 Vcc-0.5 O.45 *3 5.6 × 9.6 × 16.4 GP1UE28xQKC4 O to 6.0 -10 to +70 2.7 to 5.5 O.6 Vcc-0.5 O.45 *3 5.6 × 9.0 × 12.5(9.1) GP1UE29xQKC4 O to 6.0 -10 to +70 2.7 to 5.5 O.6 Vcc-0.5 O.45 *3 5.6 × 9.0 × 12.5(9.1) GP1UE29xQKC4 O to 6.0 -10 to +70 2.7 to 5.5 O.6 Vcc-0.5 O.45 *3 5.6 × 9.6 × 16.4 SVC-0.5 O.45 *3 S.6 × 9.6 × 16.4 SVC-0.5 O.45 *3 S.6 × 9.6 × 12.4 GP1UE29xQKC4 O to 6.0 -10 to +70 O to 6.0 -10 to +70 O to 6.0 -10 to +70 O to 6.0 O to 6.0	2
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Strengthened resistance to electromagnetic induction noise (New type) GP1UE28xRKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 × 9.6 × 16.4 GP1UE28xQKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 × 9.0 × 12.5(9.00) GP1UE29xQKC4 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 Vcc-0.5 0.45 *3 5.6 × 16.2 × 21.9(1 GP1UM26XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 With shield case (holder), GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0	
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GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0 (0.65) Vcc-0.5 (0.65) Vcc-0.	2
With shield case (holder), GP1UM27XK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0	*2
With shield case (holder),	
E V drive	
GP1UM28YK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 8.6 × 12.5(9.00)	2
GP1UM26RK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 7.2	Cente Vcc
With shield case (holder), GP1UM27RK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.4	
5 V drive, Strengthened resistance to GP1UM28RK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.6 × 16.4	
electromagnetic induction noise GP1UM28QK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 9.0 × 12.5(9.0 × 12.5)	2
GP1UM29QK0VF 0 to 6.0 -10 to +70 4.5 to 5.5 0.6 (0.65) Vcc-0.5 0.45 *3 5.6 × 16.2 × 21.9(1	*2
GP1UE26XK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 9.6 × 6.8	
With shield case (holder), GP1UE27XK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.0	
3 to 5 V drive GP1UE28XK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 9.6 × 16.0	
GP1UE28YK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 8.6 × 12.5(9.0 cm)	2
GP1UE26RK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 9.6 × 7.2	
With shield case (holder), 3 to 5 V drive. GP1UE27RK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 9.6 × 12.4	
Strengthened resistance to $ GP1UE28RK0VF 0$ to 6.0 $ -10$ to +70 $ 2.7$ to 5.5 $ 0.4 Vcc-0.5 0.45 *3 5.6 \times 9.6 \times 16.4$	
electromagnetic induction noise GP1UE28QK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 9.0 × 12.5(9.0 × 12.5)	2
GP1UE29QK0VF 0 to 6.0 -10 to +70 2.7 to 5.5 0.4 Vcc-0.5 0.45 *3 5.6 × 16.2 × 21.9(1	*2
Holderless, 3 to 5 V drive, Strengthened resistance to GP1UXC4xQS 0 to 6.0 -10 to +70 2.7 to 5.5 0.6 V cc -0.5 0.45 *3 $5.5 \times 5.3 \times 7.5$	
electromagnetic induction noise (New type) GP1UXC4xRK 0 to 6.0 -10 to $+70$ 2.7 to 5.5 0.6 $Vcc-0.5$ 0.45 *3 $5.5 \times 5.3 \times 7.5$	
Holderless, 5 V drive, Strengthened resistance to $\frac{\text{GP1UX51QS}}{\text{CP1DX51QS}}$ 0 to 6.0 $\frac{-10 \text{ to } +70}{\text{CP1DX51QS}}$ 0.6 $\frac{-10 \text{ to } +70}{\text{CP1DX51QS}}$ 0.6 $\frac{-10 \text{ to } +70}{\text{CP1DX51QS}}$ 0.6 $\frac{-10 \text{ to } +70}{\text{CP1DX51QS}}$ 0.7 5.5 \times 5.5 \times 5.3 \times 7.5	Cente
electromagnetic induction noise GP1UX51RK 0 to 6.0 -10 to $+70$ 4.5 to 5.5 0.6 $Vcc-0.5$ 0.45 *3 $5.5 \times 5.3 \times 7.5$	GND
Holderless, 3 to 5 V drive, Strengthened resistance to GP1UX31QS	
electromagnetic induction noise $ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	_

^{*} A voltage regulator circuit is built-in but may be affected by the usage environment. Install with an externally mounted C and R as a power supply filter.
*1 When no signal is input (during input light).

When no signal is input (during input light).
 Figures in parentheses indicate the distance to the light detection center.
 fo = 32.75/36/36.7/38/40 kHz
 fo = 36/36.7/38/40 kHz
 GP1UF31xXP0F: Top view taped package, GP1UF31xYP0F: Side view taped package

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■ Advanced Flex Printed Circuit Boards < Multilayer FPC specifications>

The advanced flex printed circuit board is a multilayered wiring board comprising of flexible printed circuits (FPC) laminated into a multilayer configuration. The PWBs and FPCs are connected to each other via copper-plated through holes. It is ideal for compact, lightweight equipment design.

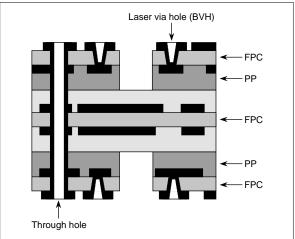
♦ Features

- (1) For selecting optimal specifications to suit specific applications, special specifications such as for mobile phones are also available.
 - Minimum thickness in multi-layer part: 0.19 mm (4-layer), 0.33 mm (6-layer)
 - Minimum pattern width/pitch: 0.06/0.07 mm
 - Flexibility of single/double sided FPC part (dedicated for hinge): More than 200 000 times 180-degree bending of radius 3 mm
- (2) Capable of board-to-board connection without connectors, which enables space-saving and 3-dimensional equipment assembly.
- (3) Through hole plating connection of multi-layer (3 to 8) part to flexible part significantly improves reliability.
- (4) Blind Via Hole (BVH) forming with laser via drilling of small diameter.
- (5) Sheet design provides excellent mountability, equivalent to that of PWB.

♦ Outline Specifications

Туре		Folding type/Flying tail type		
Min. base thickness (mm)		0.19 (4-layer), 0.33 (6-layer), 0.40 (8-layer)		
Min. line width/spacing (mm)		0.05/0.05		
Min. throug diameter (r		ø0.25		
Min. via	Through hole (mm)	Outer layer: ø0.5, Inner layer: ø0.5		
hole land	Blind via hole (mm)	ø0.09		
diameter	Inner via hole (mm)	ø0.30		
Solder resist		Multi layer: Liquid photo solder resist, FPC: Film cover ray		
Surface finish		Heat-resistant preflux, Ni-Au plating (Ni-Au plating for flying tail)		

■ Construction of Advanced Flex Board (example of 6-layer BVH)





ADVANCED FLEX PRINTED CIRCUIT BOARDS

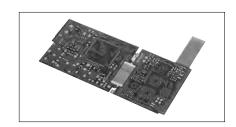


■ Advanced Flex Printed Circuit Boards <Flex-rigid specifications>

With rigid materials used for the build-up multilayer, this board can handle finer mounting patterns and achieve connectorless betweenboard connections using an inner layer flexible printed circuit (FPC). This facilitates greater equipment design flexibility and ultracompact designs.

♦ Features

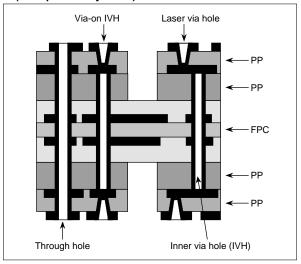
- (1) Multiple build-up layers are connected internally with an FPC, thereby improving connection reliability between multilayer boards and reducing both connection space and connector weight.
- (2) Enables narrow pitch (0.4 mm) CSP and bare chip mounting, and thus greater equipment compactness through ultra-high density mounting.
- (3) Enables via-on-IVH (inner-via-hole) configurations and stacked-via-hole configurations, and makes it possible to achieve ultra-high-density wiring designs. (Facilitates a diverse range of designs for greater compactness and thinness.)



♦ Outline Specifications

Туре		6- to 8-layer, flex-rigid	
		,	
FPC core layer configur	ation	2 to 6 layers (Polyimide)	
No. of build-up layers		1 to 2 layers for each side of core layer	
Min. board thickness (m	nm)	0.4 (6-layer), 0.53 (8-layer)	
Min. via hole diameter/	Conformal via hole (mm)	Hole: ø0.09 / Land: ø0.25	
Land hole diameter	Stacked via hole (mm)	Hole: ø0.09 / Land: ø0.25	
Min. inner via hole diam	eter (mm)	Hole: ø0.09 / Land: ø0.25	
Via-on IVH		Available	
Min. line width/spacing	(mm)	0.05/0.05	
CSP mountable pitch (r	nm)	0.4	
		•	

■ Construction of Advanced Flex Board (example of 6-layer IVH)



FLEXIBLE PRINTED CIRCUITS BOARDS





■ Flexible Printed Circuit Boards

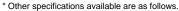
The flexible printed circuit board is designed for high space efficiency and product design flexibility, which are now aiming at more compact and higher density mounting. It also contributes to the reduction of assembly process and to the enhancement of the reliability.

♦ Features

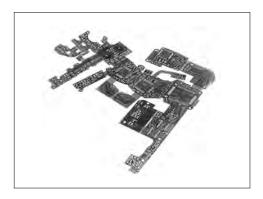
- (1) High density mounting circuit, SMT and other most suitable flexible PCB are
- (2) High precision type for COF with flip chip mounting and wire bonding capabilities and other connector mounting type are also available.

♦ Standard specifications

	i	İ	
Layers	Single side	Both-side through-hole	
Substrate materials	Polyimido film, non-	adhesive polyimido	
Design pattern width (mm)	0.04 (MIN.)	0.05 (MIN.)	
Design pattern spacing (mm)	0.04 (MIN.)	0.05 (MIN.)	
Through-hole / land diameter (mm)	_	ø0.1/ø0.3 (MIN.)	
Cover lay	Polyimido film, liquid soldering resist		
Safety standard	UL (9	4V-0)	



Bonding Ni-Au plating	
High density SMT	





■ DVD Pickup for Automotive Use <HPD-61>

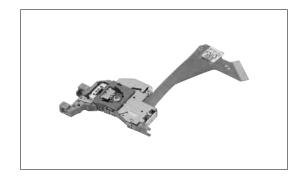
♦ Features

• Compact, thin (7.3 mm) pickup

• Playable disk: DVD-ROM, CD-ROM ● Operating temperature: -20 to +80°C

● Outline dimensions: W 30.2 × H 7.3 × D 48.7 (mm)

• Weight: Approx. 13.5 g





	GH04P32A2G87/88	GM1JR55200AE81	GM5BW94370A82
BS	GH04P32A4G87/88	GM1JS35200AE81	GM5BW96382A82
BS1F6JP100A90	GH04P43A2G87/88	GM1JS55200AE81	GM5BW96385A82
BS1F6JU300A90	GH04P43A4G87/88	GM1JV35200AE81	GM5BW96387A82
BS1F9JU300A90	GH06510F2B87	GM1JV55200AE81	GM5BW97330A82
BS1K0EL150A89	GH06510F4A87	GM1WA55311A82	GM5BW97332A82
BS1K0EL250A89	GH06P30C1C87/88		GM5BW97333A82
BS1R8AR100A90	GH07815D2K87	GM2	GM5FM0CP10A86
BS1R8EL400A 89	GH07825D2K87	GM2BB0CH10A86	GM5SAE27P0A85
BS1R8EL500A89	GH07P28F1C87/88	GM2BB27QK0C85	GM5SAE30P0A85
BS2F7HZ126691	GH07P28F4C87/88	GM2BB27QKAC85	GM5SAE35P0A85
BS2F7VZ770291	GH16P35A8C87/88	GM2BB30QK0C85	GM5SAE40P0A85
BS2S7HZ690391	GH33540A8C87/88	GM2BB30QKAC85	GM5SAE45P0A85
BS2S7HZ790391	GH3S215D2B87	GM2BB35QK0C85	GM5SAE50P0A85
	GH3S225D2B87	GM2BB35QKAC85	GM5SAE57P0A85
DC		GM2BB40QK0C85	GM5SAE65P0A85
DC2K1DZ17297	GL	GM2BB40QKAC85	GM5WA94315A85
	GL100MD1MP173	GM2BB45QK0C85	GM5WA94320A82
DU	GL100MN0MP73	GM2BB45QKAC85	GM5ZR96270A81
DU6F4JZxxxx95	GL100MN1MP73	GM2BB50QK0C85	GM5ZV96270A81
DU6N4JZxxxx95	GL4100E0000F73	GM2BB50QKAC85	
DU6R4JZxxxx96	GL4800E0000F73	GM2BB57QK0C85	GP1
DU6U4JZxxxx95	GL480E00000F73	GM2BB57QKAC85	GP1A054RDKLF64
		GM2BB65QK0C85	GP1A057RBKLF64
GA	GM1	GM2BB65QKAC85	GP1A057SGKLF 64
GA1A1S100WP67	GM1BC35372AC81		GP1A058SCK0F64
GA1A1S202WP67	GM1EG55200A81	GM4	GP1A073LCS62
GA1A1S203WP67	GM1GC35370AC81	GM4BN653C0A82	GP1A101C2KSF64
GA1A1S204WP67	GM1HD55200A81	GM4BW653A0A82	GP1A173LCS2F62
GA1A2S100LY67	GM1HS55200A81	GM4BW653B0A82	GP1A173LCSVF62
GA1A2S100SS67	GM1HY55200A81	GM4BW853A0A82	GP1A204HCS064
GA220T2L2IZ69	GM1JE35200AE81	GM4BW853B0A82	GP1A273LCS1F62
			00/450/10/10/5
	GM1JE55200AE81	GM4WA25300A82	GP1A50HRJ00F61
GH	GM1JE55200AE	GM4WA25300A82	GP1A50HRJ00F61
GH GH04020C4A87/88		GM4WA25300A82	



GP1A53HRJ00F	61	GP1S195HCPSF	58	GP1UF31xXP0F	102	GP2S700HCP	62
GP1A57HRJ00F	61	GP1S195HCZSF	58	GP1UF31xYP0F	102	GP2TC2J0000F	78
GP1A58HRJ00F	61	GP1S196HCPSF	58	GP1UM26RK0VF	102	GP2W0004XP0F	100
GP1A73AJ000F	62	GP1S196HCZ0F	58	GP1UM26XK0VF	102	GP2W0004YP0F	100
GP1A75EJ000F	62	GP1S196HCZSF	58	GP1UM27RK0VF	102	GP2W0110VY	100
GP1A98HCPSF	60	GP1S273LCS1F	59	GP1UM27XK0VF	102	GP2W0112VY	100
GP1A98HCZ0F	60	GP1S296HCPSF	58	GP1UM28QK0VF	102	GP2W1001YP0F	99
GP1FAV30RK0F	80	GP1S396HCP0F	58	GP1UM28RK0VF	102	GP2W1320YP0F	99
GP1FAV30TK0F	80	GP1S396HCPSF	58	GP1UM28XK0VF	102	GP2W3106YP0F	99
GP1FAV31RK0F	80	GP1S50J0000F	59	GP1UM28YK0VF	102	GP2W3120YP0F	99
GP1FAV31TK0F	80	GP1S51VJ000F	59	GP1UM29QK0VF	102	GP2W3152YP0F	99
GP1FAV50RK0F	80	GP1S52VJ000F	59	GP1USC3xXP	102	GP2W3176XP0F	99
GP1FAV50TK0F	80	GP1S53VJ000F	59	GP1UX31QS	102	GP2W4010YP0F	99
GP1FAV51RK0F	80	GP1S54J0000F	59	GP1UX31RK	102	GP2W4020XPMF	99
GP1FAV51TK0F	80	GP1S56TJ000F	59	GP1UX51QS	102	GP2Y0A02YK0F	76
GP1FAV55TK0F	80	GP1S58VJ000F	59	GP1UX51RK	102	GP2Y0A21YK0F	76
GP1FD320TP0F	80	GP1S59J0000F	59	GP1UXC4xQS	102	GP2Y0A41SK0F	76
GP1FMV31RK0F	80	GP1S74PJ000F	59	GP1UXC4xRK	102	GP2Y0A51SK0F	76
GP1FMV31TK0F	80	GP1UE26RK0VF	102			GP2Y0A60SZ0F	76
GP1FMV31TK0F		GP1UE26RK0VF		GP2		GP2Y0A60SZ0F	
	80		102	GP2 GP2A200LCS0F	63		76
GP1FMV51RK0F	80	GP1UE26XK0VF	102			GP2Y0A60SZLF	76 76
GP1FMV51RK0F	80 80	GP1UE26XK0VF	102 102 102	GP2A200LCS0F	65	GP2Y0A60SZLF	76 76 77
GP1FMV51RK0F	80 80 80 80 80	GP1UE26XK0VF	102 102 102 102	GP2A220LCS0F	65	GP2Y0A60SZLFGP2Y0A710K0FGP2Y0AH01K0F	76 76 77
GP1FMV51RK0F GP1FMV51TK0F GP1FSB31TK0F GP1FSV31TK0F	80 80 80 80 80 80 80	GP1UE26XK0VF	102 102 102 102	GP2A200LCS0F	65 63	GP2Y0A60SZLF GP2Y0A710K0F GP2Y0AH01K0F GP2Y0D02YK0F	76 76 77 75
GP1FMV51RK0F	80 80 80 80 80 80 80 80 80 80 80	GP1UE26XK0VF	102102102102102102102102102	GP2A200LCS0F	65 63 63	GP2Y0A60SZLF GP2Y0A710K0F GP2Y0AH01K0F GP2Y0D02YK0F GP2Y0D21YK0F	76 76 77 75 75
GP1FMV51RK0F	80 80 80 80 80 60	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102	GP2A200LCS0F	65 63 63 63	GP2Y0A60SZLF GP2Y0A710K0F GP2Y0AH01K0F GP2Y0D02YK0F GP2Y0D21YK0F GP2Y0D310K	76 75 75 75
GP1FMV51RK0F	80 80 80 80 60 60	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102	GP2A200LCS0F	65 63 63 63 63	GP2Y0A60SZLF	76 76 75 75 75 75
GP1FMV51RK0F	80 80 80 80 60 60	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102	GP2A220LCS0F	65 63 63 63 63 63	GP2Y0A60SZLF	76 76 77 75 75 75 75
GP1FMV51RK0F	80 80 80 80 80 60 60 60	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102 102	GP2A220LCS0F	65 63 63 63 63 63	GP2Y0A60SZLF	76 75 75 75 75 75 75
GP1FMV51RK0F	80 80 80 80 80 60 60 60 60	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102 102 102 102	GP2A220LCS0F	65 63 63 63 63 63 63 63	GP2Y0A60SZLF	76 75 75 75 75 75 75 75
GP1FMV51RK0F	80 80 80 80 80 80 60 60 60 60 60 58 58	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102	GP2A220LCS0F	65 63 63 63 63 63 63 63 63	GP2Y0A60SZLF GP2Y0A710K0F GP2Y0AH01K0F GP2Y0D02YK0F GP2Y0D21YK0F GP2Y0D310K GP2Y0D340K GP2Y0D413K0F GP2Y0D805Z0F GP2Y0D810Z0F GP2Y0D810Z1F	76 75 75 75 75 75 75 75 75
GP1FMV51RK0F	80 80 80 80 80 80 80 60 60 60 60 60 58 58 58	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102	GP2A220LCS0F	65 63 63 63 63 63 63 63 63	GP2Y0A60SZLF	76 75 75 75 75 75 75 75 75 75 75
GP1FMV51RK0F	80 80 80 80 60 60 60 60 58 58	GP1UE26XK0VF	102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102 102	GP2A220LCS0F	65 63 63 63 63 63 63 63 66 66	GP2Y0A60SZLF	76 75 75 75 75 75 75 75 75 75 75 77
GP1FMV51RK0F	80 80 80 80 60 60 60 60 58 58	GP1UE26XK0VF	102 102	GP2A2200LCS0F	65 63 63 63 63 63 63 63 66 65 66	GP2Y0A60SZLF	76 75 75 75 75 75 75 75 75 77 77



GP2Y3A003K0F	77	GW5DLA50M04	83	IR3T46U6	31	LQ070Y3LG4A	6
GP2Y40010K0F	78	GW5DLA65M04	83	IR3T48Y6	31	LQ070Y3LW01	6
GP2Y5D91S00F	75	GW5DLC40M04	84			LQ084S3LG03	6
		GW5DLC50M04	84	IRM		LQ084V3DG02	6
GW		GW5DLC65M04	84	IRM053U7	30		
GW5BMC27KG4	83	GW5DLE40MR5	84	IRM065U7	30	LQ1	
GW5BMC30KG4	83	GW5DLE50M05	84	IRM067U6	30	LQ104V1DG81	6
GW5BMC40KG4	83	GW5DLE65M05	84	IRM068U7	30	LQ104V1LG81	6
GW5BMC50KG4	83	GW5DMA27M04	83			LQ121S1LG81	6
GW5BMC65KG4	83	GW5DMA30M04	83	IS		LQ121S1LG84	6
GW5BMF27K04	83	GW5DMC27M04	84	IS471FE	68	LQ150X1LG91	6
GW5BMF30K04	83	GW5DMC30M04	84	IS485E	68	LQ190E1LW52	6
GW5BMF40K04	83	GW5DME27MR5	84	IS486E	68	LQ190E1LX51	6
GW5BMF50K04	83	GW5DME30MR5	84	IS489E	68		
GW5BMF65K04	83					LQ2	
GW5BMJ27K04	83	HPD		LH		LQ231U1LW32	6
GW5BMJ30K04	83	HPD-61	106	LH163Y	17		
GW5BMJ40K04	83			LH16DD	17	LQ3	
GW5BMJ50K04	83	IR2		LH16DE	17	LQ315D1LG91	7
GW5BMJ65K04	83	IR2D071	29	LH16DH	17		
GW5DGA27M04	83	IR2D20U	29	LH16DK	17	LR0	
GW5DGA30M04	83	IR2E49M	28			LR0G934	19
GW5DGA40M04	83	IR2E49U	28	LK		LR0G938	19
GW5DGA50M04	83	IR2E56U6	28	LK600D3LB14	7	LR0GC023	31
GW5DGA65M04	83	IR2E58U	28	LK601R3LA19	7	LR0GC05	31
GW5DGC27M04	84	IR2E63Yx	28	LK816D3LA19	7		
GW5DGC30M04	84	IR2E65U	29			LR3	
GW5DGC40M04	84	IR2E67M	29	LQ0		LR35501	19/20
GW5DGC50M04	84	IR2E68Yx	28	LQ035Q3DG03	6	LR35503	19/20
GW5DGC65M04	84			LQ043T3DG01	6	LR366851	12
GW5DGE27MR5	84	IR3		LQ043T3DG02	6	LR36B03A	12/15/16
GW5DGE30MR5	84	IR3M58M	18	LQ043T3DW03	6	LR36B14	12/14
GW5DGE40MR5	84	IR3M58U	18	LQ057Q3DC03	6	LR36B15	12
GW5DGE50M05	84	IR3M59U	12/27	LQ057V3LG11	6	LR38627	12/15
GW5DGE65M05	84	IR3M63U	12/13/27	LQ070Y3DG3A	6	LR38653	12/13
GW5DLA40M04	83	IR3M85N4	30	LQ070Y3DG3B	6	LR38654	12/13



LR38690A12/16	PC3SD12NTZAF51		PQ070VK02FZH22
LR388D118/21	PC3SD12NTZBF51	PC7	PQ070XF01SZH22
LR388D8 18/21	PC3SD21NTZAF52	PC713V0NSZXF47	PQ070XHA2ZPH24
LR388G918/21	PC3SD21NTZBF52	PC714V0NSZXF47	PQ070XNA1ZPH23
LR388H017	PC3SD21NTZCF52	PC715V0NSZXF47	PQ070XNA2ZPH23
LR388H317	PC3SD21NTZDF52	PC724V0NSZXF47	PQ070XNAHZPH23
LR388J4 18/21	PC3SD23YTZCF52	PC725V0NSZXF47	PQ070XNB1ZPH23
	PC3SF11YVZAF51		
PC1	PC3SF11YVZBF51	PC8	PQ1
PC1231xNSZ0X 46	PC3SF13YVZBF51	PC81510NSZ0X46	PQ150RWA2SZH22
PC123XNNSZ0F 46	PC3SF21YVZAF52	PC815XNNSZ0F46	PQ1AS1D0130
PC1S3021NTZF52	PC3SF21YVZBF52	PC8171xNSZ0X46	PQ1AS1D01A30
PC1S3052NTZF52	PC3SH11YFZAX51	PC817XNNSZ0F46	PQ1AS2D0130
PC1S3063NTZF52	PC3SH13YFZAX51	PC851XNNSZ0F46	PQ1CG2032FZH26
	PC3SH21YFZBX52	PC852XNNSZ0F46	PQ1CG2032RZH26
PC2	PC3ST11NSZAX51	PC853XNNSZ0F46	PQ1CG21H2FZH26
PC2SD11NTZAF51	PC3ST21NSZBX52		PQ1CG21H2RZH26
		PC9	PQ1CG3032FZH26
D00	DC4		
PC3	PC4	PC900V0NSZXF49	PQ1CG3032RZH26
PC352NJ0000F44	PC400J00000F48	PC925LxNSZ0F49	PQ1CG3032RZH
PC352NJ0000F44	PC400J00000F48	PC925LxNSZ0F49	PQ1CG38M2FZH26
PC352NJ0000F	PC400J00000F48 PC410L0NIP0F48	PC925LxNSZ0F49 PC928J00000F49	PQ1CG38M2FZH
PC352NJ0000F	PC410L0NIP0F	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F 48 PC410L0NIP0F 48 PC410S0NIP0F 48 PC451J00000F 44 PC452J00000F 44 PC456L0NIP0F 48 PC457S0NIP0F 48 PC4D10SNIP0F 48	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F 48 PC410L0NIP0F 48 PC410S0NIP0F 48 PC451J00000F 44 PC452J00000F 44 PC456L0NIP0F 48 PC457S0NIP0F 48 PC4D10SNIP0F 48 PC4D11NTZBF 51	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F 48 PC410L0NIP0F 48 PC410S0NIP0F 48 PC451J00000F 44 PC452J00000F 44 PC456L0NIP0F 48 PC457L0NIP0F 48 PC457S0NIP0F 48 PC4D10SNIP0F 48 PC4SD11NTZBF 51 PC4SD11NTZCF 51	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F 48 PC410L0NIP0F 48 PC410S0NIP0F 48 PC451J00000F 44 PC452J00000F 44 PC456L0NIP0F 48 PC457L0NIP0F 48 PC457S0NIP0F 48 PC4D10SNIP0F 48 PC4SD11NTZBF 51 PC4SD21NTZCF 52	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F 48 PC410L0NIP0F 48 PC410S0NIP0F 48 PC451J00000F 44 PC452J00000F 44 PC456L0NIP0F 48 PC457L0NIP0F 48 PC457S0NIP0F 48 PC4D10SNIP0F 48 PC4SD11NTZBF 51 PC4SD21NTZCF 52 PC4SD21NTZDF 52	PC925LxNSZ0F	PQ1CG38M2FZH
PC352NJ0000F	PC400J00000F 48 PC410L0NIP0F 48 PC410S0NIP0F 48 PC451J00000F 44 PC452J00000F 44 PC456L0NIP0F 48 PC457L0NIP0F 48 PC457S0NIP0F 48 PC4D10SNIP0F 48 PC4SD11NTZBF 51 PC4SD21NTZCF 52 PC4SD21NTZDF 52 PC4SF11YVZAF 51	PC925LxNSZ0F	PQ1CG38M2FZH



		PR26MF21NSZF	54		RJ63YC100	8/5
PQ2		PR29MF11NSZF	54	QM	RJ63YC200	8/9
PQ200WN3MZPH	23	PR29MF12NSZF	54	QM2A1UA00330	RJ64PC800	8/9
PQ200WNA1ZPH	23	PR29MF21NSZF	54	QM2A1UA00430	RJ64SC100	8/9
		PR31MA11NTZF	54		RJ64SC200	8/9
PQ3		PR32MA11NTZF	54	RJ	RJ6CBA100	8/9
PQ30RV11J00H	22	PR33MF51NSZF	54	RJ2311DB0PB11/13/14/15/16	RJ6CBA200	8/9
PQ30RV21J00H	22	PR36MF12NSZF	54	RJ2315DB0PB11/13/14/15/16		
PQ30RV31J00H	22	PR36MF21NSZF	54	RJ2321DB0PB11/13/14/15/16	S1	
		PR36MF22NSZF	54	RJ2325DB0PB11/13/14/15/16	S101S05F	55
PQ5		PR36MF51NSZF	54	RJ2331AA0PB11	S101S06F	55
PQ5CM03P	26	PR39MF12NSZF	54	RJ2341AA0PB11	S101S16F	55
		PR39MF21NSZF	54	RJ2351CA0PB11/13/14/15/16	S102S01F	55
PQ6		PR39MF22NSZF	54	RJ2355CA0PB11/13/14/15/16	S102S02F	55
PQ6CB11X1CP	28	PR39MF51NSZF	54	RJ2361CA0PB11/13/14/15/16	S102S11F	55
PQ6CU12X2APQ	25	PR3BMF21NSZF	54	RJ2365CA0PB11/13/14/15/16	S102S12F	55
		PR3BMF51NSKF	54	RJ23E3BA0LT10/11	S102T01F	55
PQ7				RJ23W3EA0KT10/11	S102T02F	55
PQ7L2020BP	28	PT		RJ23W3HA0LT10/11	S108T01F	55
PQ7L3010QPF	28	PT100MC0MP	71	RJ23Y3BC0LT10/11	S108T02F	55
		PT100MF0MP	71	RJ23Y3EA0LT10/11	S112S01F	55
PQx		PT100MF1MP	71	RJ23Y3HA0LT10/11	S116S01F	55
PQxxxDNA1ZPH series	23	PT4800E0000F	71	RJ23Z3BA0LT10/11	S116S02F	55
PQxxxENA1ZPH series	23	PT4800FE000F	71	RJ2411CA0PB11/13		
PQxxxENAHZPH series	23	PT480E00000F	71	RJ2411EA0PB11/13/14/15/16	S2	
PQxxxENB1ZPH series	23	PT480FE0000F	71	RJ2411EB0PB11/13/14/15/16	S201S06F	56
PQxxxGN01ZPH series	23	PT4810E0000F	71	RJ2411FA0PB11/13/14/15/16	S202S01F	55
PQxxxGN1HZPH series	23	PT4810FJE00F	71	RJ2421EB0PB11/13/14/15/16	S202S02F	56
PQxxxRDA1SZH series	22	PT481E00000F	71	RJ2421FA0PB11/13/14/15/16	S202S11F	56
PQxxxRDA2SZH series	22	PT481FE0000F	71	RJ2451CA0PB11/13/14/15/16	S202S12F	56
		PT483F1E000F	71	RJ2455CA0PB11/13/14/15/16	S202S15F	56
PR		PT4850FE000F	71	RJ2461CA0PB11/13/14/15/16	S202T01F	55
PR22MA11NTZF	54	PT491FE0000F	71	RJ2465CA0PB11/13/14/15/16	S202T02F	55
PR23MF11NSZF	54	PT493FE0000F	71	RJ3331AA0PB11	S208T01F	55
PR26MF11NSZF	54			RJ3341AA0PB11	S208T02F	55
PR26MF12NS7F	54			R.163VC200 8/9	S212S01F	55



S216S01F	55
S216S02F	56
S2S3000F	51
S2S4000F	52
S2S5A00F	51

VA

VA1N5JF8627	95
VA1P1CD8402	94
VA3A5JZ967	96
VA3D5JZ705	95
VA4A1BC5038	94
VA4D1JA2160	94/95
VA4M1DA5167	94
VA4M1EX6158	93
VA4M5JC2116	92/96
VA4M6JC2103	92/96
VA4N1BD1108	93
VA4N1CD1136	93
VA4S5DC5072	93

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Mie Plant	EC99J2051	January 28, 1997	Development, design and manufacture of LCDs
Kameyama Plant	EC04J0284	October 12, 2004	Production and development of Large LCD TVs
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*2 The Group name has been changed from Liquid Crystal Display Group as of April 1, 2011 (The above information is current as of June 2011.)





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